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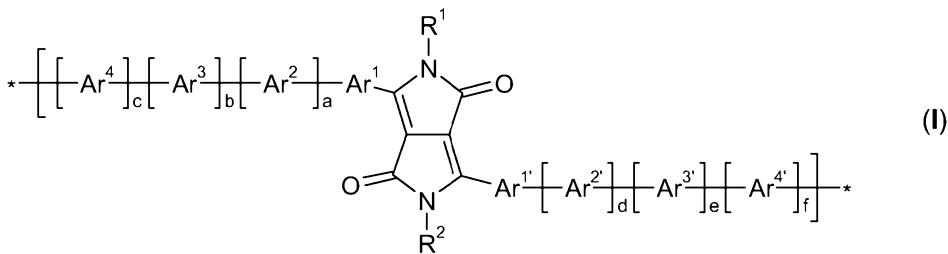
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(54) Title: DIKETOPYRROLOPYRROLE POLYMERS AS ORGANIC SEMICONDUCTORS



(I)

(57) **Abstract:** The present invention relates to polymers comprising a repeating unit of the formula (I) and their use as organic semiconductor in organic devices, especially a diode, an organic field effect transistor and/or a solar cell, or a device containing a diode and/or an organic field effect transistor, and/or a solar cell. The polymers according to the invention have excellent solubility in organic solvents and excellent film-forming properties. In addition, high efficiency of energy conversion, excellent field-effect mobility, good on/off current ratios and/or excellent stability can be observed, when the polymers according to the invention are used in semiconductor devices or organic photovoltaic (PV) devices (solar cells).

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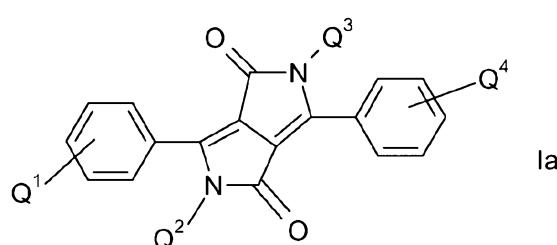
Diketopyrrolopyrrole Polymers as Organic Semiconductors

The present invention relates to polymers comprising a repeating unit of the formula (I) and their use as organic semiconductor in organic devices, especially a diode, an organic field effect transistor and/or a solar cell, or a device containing a diode and/or an organic field effect transistor, and/or a solar cell. The polymers according to the invention have excellent solubility in organic solvents and excellent film-forming properties. In addition, high efficiency of energy conversion, excellent field-effect mobility, good on/off current ratios and/or excellent stability can be observed, when the polymers according to the invention are used in semiconductor devices or organic photovoltaic (PV) devices (solar cells).

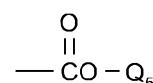
M. Smet et al., Tetrahedron Lett. 42 (2001) 6527-6530 describe the preparation of rod-like diketopyrrolopyrrole oligomers by a stepwise sequence of Suzuki couplings using brominated 1,4-dioxo-3,6-diphenylpyrrolo[3,4-c]pyrrole (DPP) derivatives and 1,4-dibromo-2,5-di-n-hexylbenzene as the monomers.

M. Horn et. al, Eur. Polymer J. 38 (2002) 2197-2205 describe the synthesis and characterisation of thermomesogenic polysiloxanes with 2,5-dihydropyrrolo[3,4-c]pyrrole units in the main chain.

EP-A-787,730 describes a polyacrylate and a polyurethane obtained by the polymerization of a DPP of formula Ia



wherein Q₁ and Q₄ independently of each other stand for a polymerizable reactive group, and Q₂ and Q₃ independently of each other stand for hydrogen, C₁₂-C₂₄alkyl, C₆-C₂₄alkyl which is interrupted one or more times by O or S, or are a group of the formula



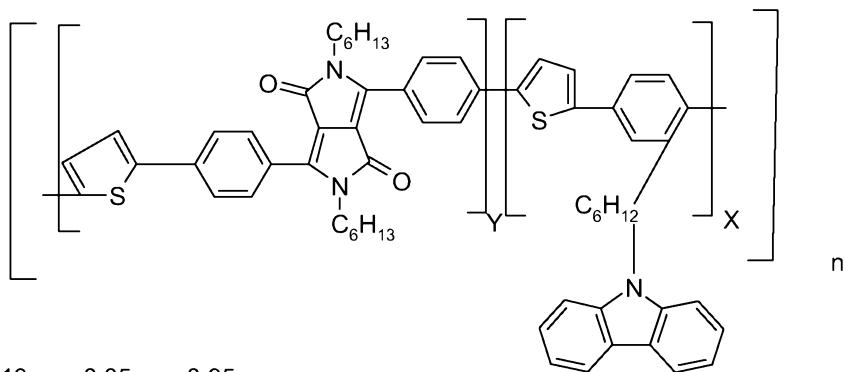
in which Q₅ is C₄-C₁₈alkyl or C₅-C₁₀cycloalkyl.

Though it is mentioned that compounds Ia can be used for the preparation of photo- and electroconductive polymers, no corresponding examples are given. Further, no teaching is given of how to prepare EL devices comprising DPP-based polymers and of how to select the appropriate DPP-monomers resp. DPP-polymers.

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Macromol. Chem. Phys. 200 (1999) 106-112 describes fluorescent DPP-polymers obtainable by the copolymerization of bifunctional monomeric DPP-derivatives, wherein the functional groups are attached to the N-atoms of the DPP-molecule, with diisocyanates or di-ols or di-acids.

10 J. Am. Chem. Soc. 117 (1995) 12426-12435 relates to the exploration of the palladium catalysed Stille coupling reaction for the synthesis of functional polymers. In Scheme 7 the synthesis of the following polymers is presented:



Polymer 13: $y = 0,05$, $x = 0,95$

Polymer 14: $y = 0$, $x = 1$

No teaching is given whether the described polymers can be used in EL devices.

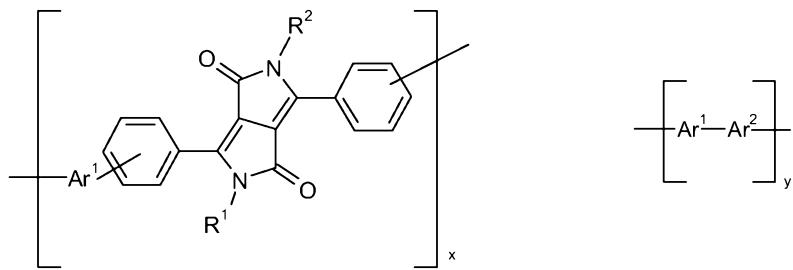
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J. Am. Chem. Soc. 115 (1993) 11735-11743 describes DPP-polymers demonstrating photorefractivity, i.e. exhibiting photoconductivity and second order non-linear-optical activity. In this device, photoconductive properties are determined by irradiating the device with a laser beam and then measuring the current resulting from this irradiation, no measurements 20 were carried out with regard to electroluminescence.

Further, no teaching is given of how to select other DPP-polymers.

In Appl. Phys. Lett. 64 (1994) 2489-2491 further studies, i.e. two-beam coupling experiments, 25 using polymers disclosed in J. Am. Chem. Soc. 115 (1993) 11735-11743 are performed to study photorefractivity. The two-beam coupling experiments demonstrated asymmetric energy exchange under zero field, i.e. photorefractivity of the polymers disclosed in J. Am. Chem. Soc. 115 (1993) 11735-11743.

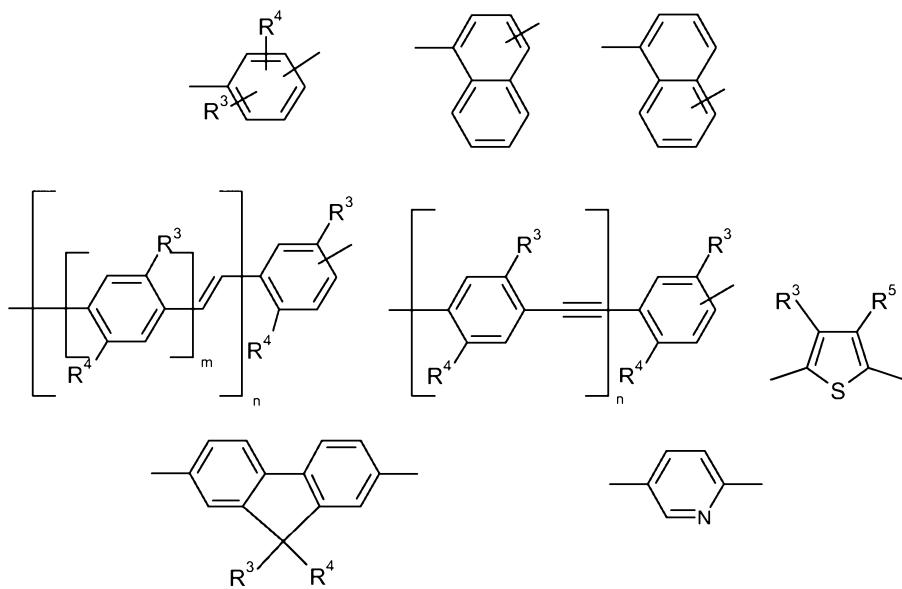
US-B-6451459 (cf. B. Tieke et al., *Synth. Met.* 130 (2002) 115-119; *Macromol. Rapid Commun.* 21 (4) (2000) 182-189) describes diketopyrrolopyrrole based polymers and copolymers comprising the following units



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wherein x is chosen in the range of from 0.005 to 1, preferably from 0.01 to 1, and y from 0.995 to 0, preferably 0.99 to 0, and wherein $x + y = 1$, and wherein Ar¹ and Ar² independently from each other stand for

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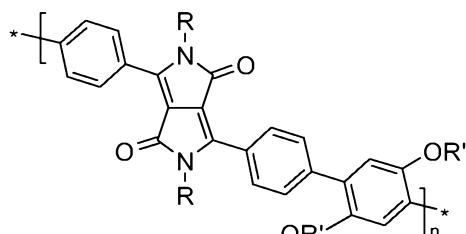
and m, n being numbers from 1 to 10, and

R¹ and R² independently from each other stand for H, C₁-C₁₈alkyl, -C(O)O-C₁-C₁₈alkyl, perfluoro-C₁-C₁₂alkyl, unsubstituted C₆-C₁₂aryl or one to three times with C₁-C₁₂alkyl, C₁-C₁₂alkoxy, or halogen substituted C₆-C₁₂aryl, C₁-C₁₂alkyl-C₆-C₁₂aryl, or C₆-C₁₂aryl-C₁-C₁₂alkyl,

15 R³ and R⁴ preferably stand for hydrogen, C₁-C₁₂alkyl, C₁-C₁₂alkoxy, unsubstituted C₆-C₁₂aryl or one to three times with C₁-C₁₂alkyl, C₁-C₁₂alkoxy, or halogen substituted C₆-C₁₂aryl or perfluoro-C₁-C₁₂alkyl, and

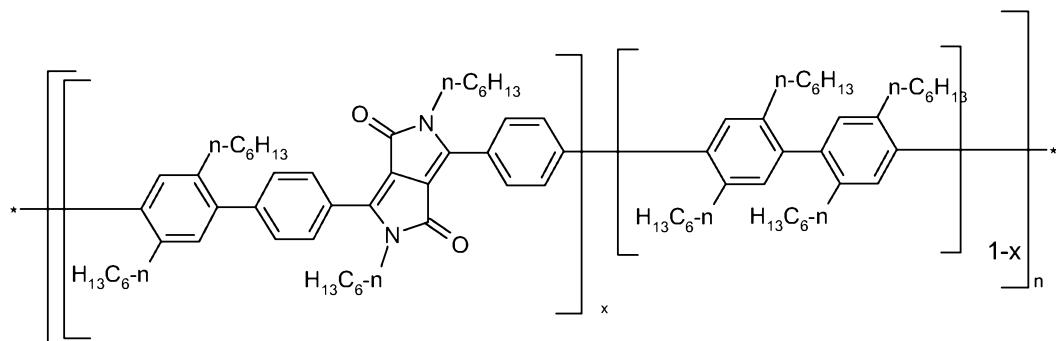
R⁵ preferably stands for C₁-C₁₂alkyl, C₁-C₁₂alkoxy, unsubstituted C₆-C₁₂aryl or one to three

20 times with C₁-C₁₂alkyl, C₁-C₁₂alkoxy, or halogen substituted C₆-C₁₂aryl, or perfluoro-C₁-C₁₂alkyl, and their use in EL devices. The following polymer



is explicitly disclosed in Tieke et al., *Synth. Met.* 130

(2002) 115-119. The following polymers



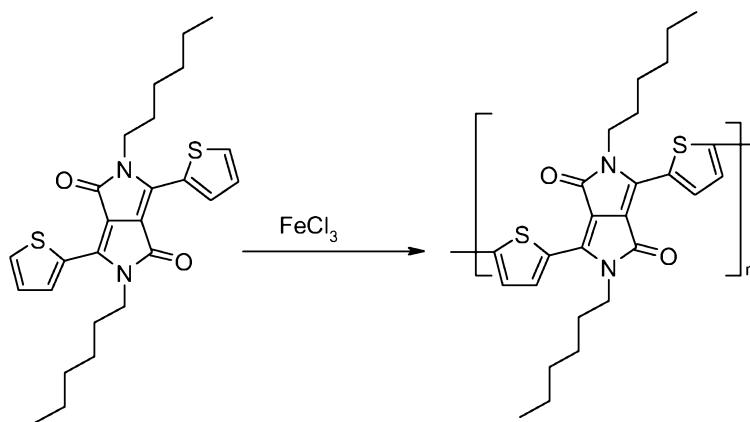
are

explicitly disclosed in *Macromol. Rapid Commun.* 21 (4) (2000) 182-189.

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WO05/049695 discloses diketopyrrolopyrrole (DPP) based polymers and their use in PLEDs, organic integrated circuits (O-ICs), organic field effect transistors (OFETs), organic thin film transistors (OTFTs), organic solar cells (O-SCs), or organic laser diodes, but fails to disclose the specific DPP based polymers of formula I. In Example 12 the preparation of the following

10 polymer is described:

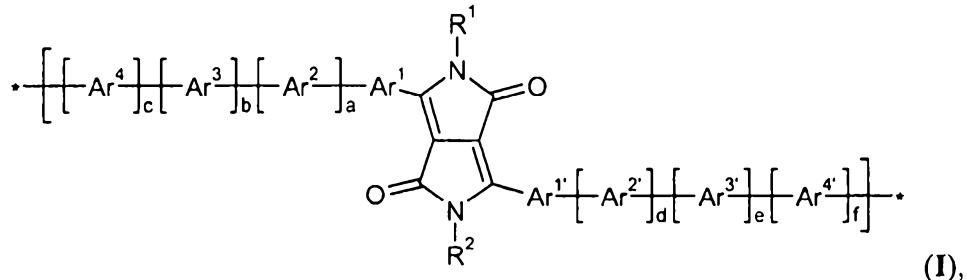


The object of the present invention is to provide novel polymers which show excellent performance when used, for example, in semiconductor devices, photodiodes or organic

photovoltaic (PV) devices (solar cells), such as high efficiency of energy conversion, excellent field-effect mobility, good on/off current ratios and/or excellent stability.

According to a first aspect of the invention there is provided a polymer comprising

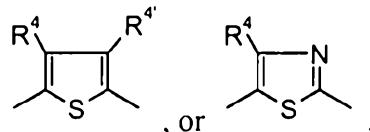
5 (repeating) unit(s) of the formula



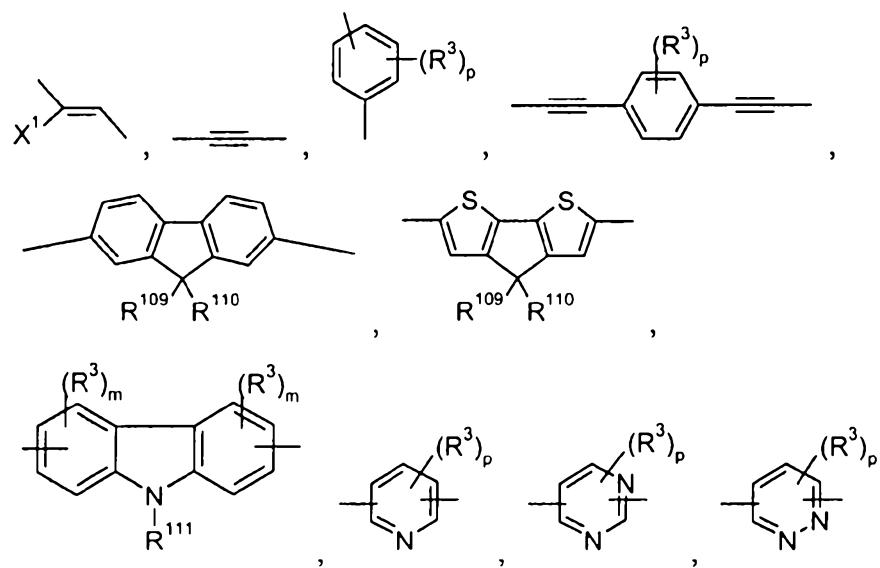
wherein

a, b, c, d, e and f are 0, 1, 2, or 3;

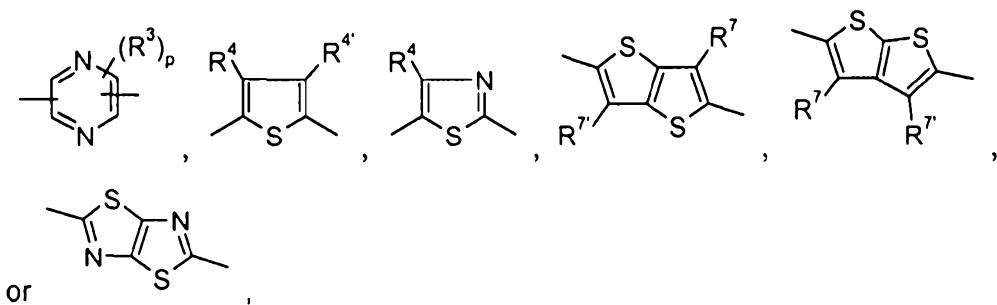
Ar¹ and Ar^{1'} are independently of each other a group of formula



Ar^2 , Ar^2' , Ar^3 , Ar^3' , Ar^4 and Ar^4' are independently of each other a group of formula



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p stands for 0, 1, 2, 3 or 4, if possible,

R¹ and R² may be the same or different and are selected from hydrogen, a C₁-C₂₅alkyl group, an alkenyl group, an alkynyl group, which may optionally be substituted by E and/or interrupted by D, an allyl group, which can be substituted one to three times with C₁-C₄alkyl; a cycloalkyl group, which can be substituted one to three times with C₁-C₈alkyl, C₁-C₈thioalkoxy, or C₁-C₈alkoxy, or a cycloalkyl group, which can be condensed one or two times by phenyl,

which can be substituted one to three times with C₁-C₄-alkyl, halogen, nitro or cyano; a cycloalkenyl group, a ketone or aldehyde group, an ester group, a carbamoyl group, a silyl group, a siloxanyl group, Ar¹⁰ or -CR⁵R⁶-(CH₂)₉-Ar¹⁰, wherein

R⁵ and R⁶ independently from each other stand for hydrogen, fluorine, cyano or C₁-C₄alkyl, which can be substituted by fluorine, chlorine or bromine, or phenyl, which can be substituted one to three times with C₁-C₄alkyl,

Ar¹⁰ stands for aryl or heteroaryl, which may optionally be substituted by G, in particular phenyl or 1- or 2-naphthyl which can be substituted one to three times with C₁-C₈alkyl, C₁-C₈thioalkoxy, and/or C₁-C₈alkoxy, and g stands for 0, 1, 2, 3 or 4,

R³ may be the same or different within one group and is selected from C₁-C₂₅alkyl, which may optionally be substituted by E and/or interrupted by D, C₆-C₂₄aryl, which may optionally be substituted by G, C₂-C₂₀heteroaryl, which may optionally be substituted by G, C₁-C₁₈alkoxy, which may optionally be

substituted by E and/or interrupted by D, C₇-C₂₅aralkyl, wherein ar (=aryl) of aralkyl may optionally be substituted by G, or -CO-R²⁸, or two or more groups R³ which are in the neighbourhood to each other, form a ring;

R⁴, R^{4'}, R⁷ and R^{7'} independently from each other stand for hydrogen, C₁-C₂₅alkyl, which may optionally be substituted by E and/or interrupted by D, C₆-C₂₄aryl, which may optionally be substituted by G, C₂-C₂₀heteroaryl, which may optionally be substituted by G, C₁-C₁₈alkoxy, which may optionally be

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substituted by E and/or interrupted by D, C₇-C₂₅aralkyl, wherein ar (=aryl) of aralkyl may optionally be substituted by G, or -CO-R²⁸; or R⁴ and R^{4'} form a ring; D is -CO-; -COO-; -S-; -SO-; -SO₂-; -O-; -NR²⁵-; -CR²³=CR²⁴-; or -C≡C-; and E is -OR²⁹; -SR²⁹; -NR²⁵R²⁶; -COR²⁸; -COOR²⁷; -CONR²⁵R²⁶; -CN; or halogen; G is E, C₁-C₁₈alkyl, which may be interrupted by D, or C₁-C₁₈alkoxy which is substituted by E and/or interrupted by D, wherein

5 R²³, R²⁴, R²⁵ and R²⁶ are independently of each other H; C₆-C₁₈aryl; C₆-C₁₈aryl which is substituted by C₁-C₁₈alkyl, or C₁-C₁₈alkoxy; C₁-C₁₈alkyl; or C₁-C₁₈alkyl which is interrupted by -O-;

10 R²⁷ and R²⁸ are independently of each other H; C₆-C₁₈aryl; C₆-C₁₈aryl which is substituted by C₁-C₁₈alkyl, or C₁-C₁₈alkoxy; C₁-C₁₈alkyl; or C₁-C₁₈alkyl which is interrupted by -O-,

15 R²⁹ is H; C₆-C₁₈aryl; C₆-C₁₈aryl, which is substituted by C₁-C₁₈alkyl, or C₁-C₁₈alkoxy; C₁-C₁₈alkyl; or C₁-C₁₈alkyl which is interrupted by -O-,

20 R¹⁰⁹ and R¹¹⁰ are independently of each other H, C₁-C₁₈alkyl, C₁-C₁₈alkyl which is substituted by E and/or interrupted by D, C₆-C₂₄aryl, C₆-C₂₄aryl which is substituted by G, C₂-C₂₀heteroaryl, C₂-C₂₀heteroaryl which is substituted by G, C₂-C₁₈alkenyl, C₂-C₁₈alkynyl, C₁-C₁₈alkoxy, C₁-C₁₈alkoxy which is substituted by E and/or interrupted by D, or C₇-C₂₅aralkyl, or

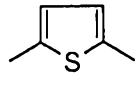
25 R¹⁰⁹ and R¹¹⁰ together form a group of formula =CR¹⁰⁰R¹⁰¹, wherein R¹⁰⁰ and R¹⁰¹ are independently of each other H, C₁-C₁₈alkyl, C₁-C₁₈alkyl which is substituted by E and/or interrupted by D, C₆-C₂₄aryl, C₆-C₂₄aryl which is substituted by G, or C₂-C₂₀heteroaryl, or C₂-C₂₀heteroaryl which is substituted by G, or

30 R¹⁰⁹ and R¹¹⁰ together form a five or six membered ring, which optionally can be substituted by C₁-C₁₈alkyl, C₁-C₁₈alkyl which is substituted by E and/or interrupted by D, C₆-C₂₄aryl, C₆-C₂₄aryl which is substituted by G, C₂-C₂₀heteroaryl, C₂-C₂₀heteroaryl which is substituted by G, C₂-C₁₈alkenyl, C₂-C₁₈alkynyl, C₁-C₁₈alkoxy, C₁-C₁₈alkoxy which is substituted by E and/or interrupted by D, C₇-C₂₅aralkyl, or -C(=O)-R¹⁸,

35 R¹¹¹ is H, a C₁-C₂₅alkyl group, a C₄-C₁₈cycloalkyl group, a C₁-C₂₅alkoxy group, in which one or more carbon atoms which are not in neighbourhood to each other could be replaced by -O-, -S-, or -C(=O)-O-, and/or wherein one or more hydrogen atoms can be replaced by F, a C₆-C₂₄aryl group, or a C₆-C₂₄aryloxy group, wherein one or more carbon atoms can be replaced by O, S, or N, and/or which can be substituted by one or more non-aromatic groups R¹¹¹;

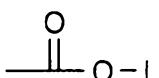
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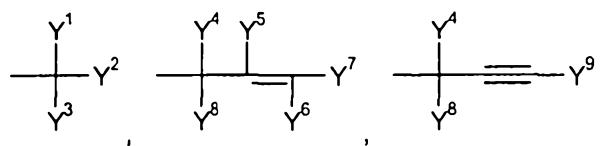
m can be the same or different at each occurrence and is 0, 1, 2, or 3, especially 0, 1, or 2, very especially 0 or 1;
 X¹ is a hydrogen atom, or a cyano group,

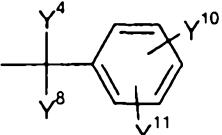
5 with the proviso that, if Ar¹ and Ar^{1'} are a group of formula  , a and d are not 0.

The polymers, wherein R¹ and/or R² are hydrogen can be obtained by using a protecting group which can be removed after polymerization (see, for example, EP-A-0 648 770, EP-A-0 648 817, EP-A-0 742 255, EP-A-0 761 772, WO98/32802, 10 WO98/45757, WO98/58027, WO99/01511, WO00/17275, WO00/39221, WO00/63297 and EP-A-1 086 984). Conversion of the pigment precursor into its pigmentary form is carried out by means of fragmentation under known conditions, for example thermally, optionally in the presence of an additional catalyst, for example the catalysts described in WO00/36210.

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An example of such a protecting group is group of formula  , wherein L is any desired group suitable for imparting solubility.

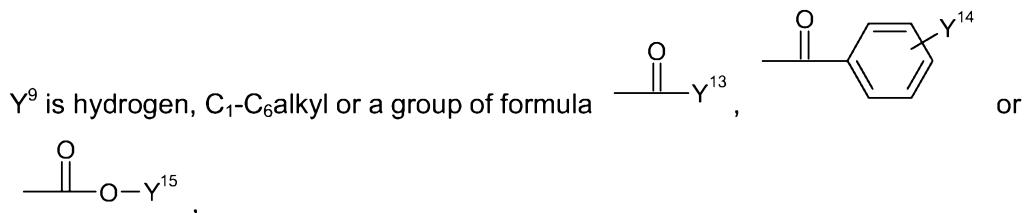
L is preferably a group of formula  ,

 , or $-\text{Q}-\text{X}-\text{L}'^{(L^2)m'}$, wherein Y¹, Y² and Y³ are independently of

20 each other C₁-C₆alkyl,

Y⁴ and Y⁸ are independently of each other C₁-C₆alkyl, C₁-C₆alkyl interrupted by oxygen, sulfur or N(Y¹²)₂, or unsubstituted or C₁-C₆alkyl-, C₁-C₆alkoxy-, halo-, cyano- or nitro-substituted phenyl or biphenyl,

Y⁵, Y⁶ and Y⁷ are independently of each other hydrogen or C₁-C₆alkyl,



Y^{10} and Y^{11} are each independently of the other hydrogen, $\text{C}_1\text{-C}_6\text{alkyl}$, $\text{C}_1\text{-C}_6\text{alkoxy}$, halogen, cyano, nitro, $\text{N}(\text{Y}^{12})_2$, or unsubstituted or halo-, cyano-, nitro-, $\text{C}_1\text{-C}_6\text{alkyl-}$ or $\text{C}_1\text{-C}_6\text{alkoxy-}$

5 substituted phenyl,

Y^{12} and Y^{13} are $\text{C}_1\text{-C}_6\text{alkyl}$, Y^{14} is hydrogen or $\text{C}_1\text{-C}_6\text{alkyl}$, and Y^{15} is hydrogen, $\text{C}_1\text{-C}_6\text{alkyl}$, or unsubstituted or $\text{C}_1\text{-C}_6\text{alkyl-}$ substituted phenyl,

Q is $\text{p},\text{q-C}_2\text{-C}_6\text{alkylene}$ unsubstituted or mono- or poly-substituted by $\text{C}_1\text{-C}_6\text{alkoxy}$,

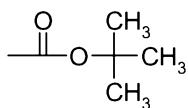
$\text{C}_1\text{-C}_6\text{alkylthio}$ or $\text{C}_2\text{-C}_{12}\text{dialkylamino}$, wherein p and q are different position numbers,

10 X is a hetero atom selected from the group consisting of nitrogen, oxygen and sulfur, m being the number 0 when X is oxygen or sulfur and m being the number 1 when X is nitrogen, and L^1 and L^2 are independently of each other unsubstituted or mono- or poly- $\text{C}_1\text{-C}_{12}\text{alkoxy-}$, $-\text{C}_1\text{-C}_{12}\text{alkylthio-}$, $-\text{C}_2\text{-C}_{24}\text{dialkylamino-}$, $-\text{C}_6\text{-C}_{12}\text{aryloxy-}$, $-\text{C}_6\text{-C}_{12}\text{arylthio-}$, $-\text{C}_7\text{-C}_{24}\text{alkylarylamino-}$ or $-\text{C}_{12}\text{-C}_{24}\text{diarylamino-}$ substituted $\text{C}_1\text{-C}_6\text{alkyl}$ or $[-(\text{p}',\text{q}'\text{-C}_2\text{-C}_6\text{alkylene-}\text{Z-})_n\text{-C}_1\text{-C}_6\text{alkyl}]$, n' being a number from 1 to 1000, p' and q' being different position numbers, each Z independently of any others being a hetero atom oxygen, sulfur or $\text{C}_1\text{-C}_{12}\text{alkyl-}$ substituted nitrogen, and it being possible for $\text{C}_2\text{-C}_6\text{alkylene}$ in the repeating

15 $[-\text{C}_2\text{-C}_6\text{alkylene-}\text{Z-}]$ units to be the same or different,

and L_1 and L_2 may be saturated or unsaturated from one to ten times, may be uninterrupted

20 or interrupted at any location by from 1 to 10 groups selected from the group consisting of $-(\text{C}=\text{O})$ - and $-\text{C}_6\text{H}_4$ -, and may carry no further substituents or from 1 to 10 further substituents selected from the group consisting of halogen, cyano and nitro. Most preferred L is a group



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25 The polymers of the present invention can be used as charge-transport, semiconducting, el. conducting, photoconducting, light emitting material, surface-modifying material, electrode materials in batteries, alignment layers, or in OFETs, ICs, TFTs, displays, RFITD tags, electro- or photoluminescent devices, backlights of displays, photovoltaic or sensor devices, charge injection layers, Schottky diodes, memory devices (e.g. FeFET), planarising layers, 30 antistatics, conductive substrates or patterns, photoconductors, or electrophotographic applications (recording).

The polymers of the present invention can comprise one, or more (different) repeating units of formula I, such as, for example, repeating units of formula **Ia** and **Id**.

The repeating unit of formula I can have an asymmetric structure, but has preferably a

5 symmetric structure: a = d; b = e; c = f; Ar¹ = Ar¹; Ar² = Ar²; Ar³ = Ar³; Ar⁴ = Ar⁴.

R¹ and R² may be the same or different and are preferably selected from hydrogen, a C₁-C₂₅alkyl group, which can optionally be interrupted by one or more oxygen atoms, a C₁-C₂₅perfluoroalkyl group, an allyl group, which can be substituted one to three times with C₁-

10 C₄alkyl; a cycloalkyl group, which can be substituted one to three times with C₁-C₈alkyl, C₁-C₈thioalkoxy, or C₁-C₈alkoxy, or a cycloalkyl group, which can be condensed one or two times by phenyl, which can be substituted one to three times with C₁-C₄-alkyl, halogen, nitro or cyano, an alkenyl group, a cycloalkenyl group, an alkynyl group, a haloalkyl group, a haloalkenyl group, a haloalkynyl group, a ketone or aldehyde group, an ester group, a

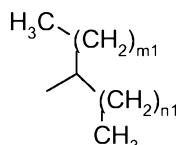
15 carbamoyl group, a ketone group, a silyl group, a siloxanyl group, Ar¹⁰ or -CR⁵R⁶-(CH₂)_g-Ar¹⁰, wherein

R⁵ and R⁶ independently from each other stand for hydrogen, fluorine, cyano or C₁-C₄alkyl, which can be substituted by fluorine, chlorine or bromine, or phenyl, which can be substituted one to three times with C₁-C₄alkyl,

20 R¹ and R² are more preferably selected from C₁-C₂₅alkyl, which can optionally be interrupted by one or more oxygen atoms, C₅-C₁₂-cycloalkyl, especially cyclohexyl, which can be substituted one to three times with C₁-C₈alkyl and/or C₁-C₈alkoxy, or C₅-C₁₂cycloalkyl, especially cyclohexyl, which can be condensed one or two times by phenyl, which can be substituted one to three times with C₁-C₄alkyl, halogen, nitro or cyano, phenyl or 1- or 2-naphthyl which can be substituted one to three times with C₁-C₈alkyl and/or C₁-C₈alkoxy, or -CR⁵R⁶-(CH₂)_g-Ar¹⁰ wherein R³ and R⁴ stand for hydrogen, Ar¹⁰ stands for phenyl or 1- or 2-naphthyl, which can be substituted one to three times with C₁-C₈alkyl and/or C₁-C₈alkoxy, and g stands for 0 or 1. An alkyl group which is interrupted one or more times by -O- is

25 understood to be a straight-chain or branched C₂-C₂₅alkyl radical, which may be interrupted one or more times by -O-, for example one, two or three times by -O-, resulting in structural units such as, for example, -(CH₂)₂OCH₃, -(CH₂CH₂O)₂CH₂CH₃, -CH₂-O-CH₃, -CH₂CH₂-O-CH₂CH₃, -CH₂CH₂CH₂-O-CH(CH₃)₂, -[CH₂CH₂O]_{Y1}-CH₃ wherein Y1 = 1-10, -CH₂-CH(CH₃)-O-CH₂-CH₂CH₃ and -CH₂-CH(CH₃)-O-CH₂-CH₃.

Most preferred R¹ and R² are a C₁-C₂₅alkyl group, especially a C₄-C₂₅alkyl group, such as n-butyl, sec.-butyl, isobutyl, tert.-butyl, n-pentyl, 2-pentyl, 3-pentyl, 2,2-dimethylpropyl, n-hexyl, n-heptyl, n-octyl, 1,1,3,3-tetramethylbutyl and 2-ethylhexyl, n-nonyl, n-decyl, n-undecyl, n-dodecyl, tridecyl, tetradecyl, pentadecyl, hexadecyl, 2-hexyldecyl, heptadecyl, 5 octadecyl, eicosyl, heneicosyl, docosyl, tetracosyl or pentacosyl, wherein advantageous



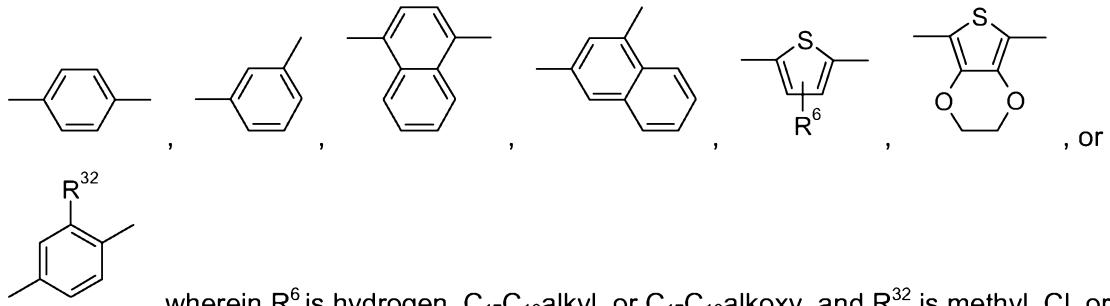
groups can be represented by formula , wherein m1 = n1 + 4 and m1 + n1 ≤ 22.

Chiral side chains, such as R¹ and R², can either be homochiral, or racemic, which can

10 influence the morphology of the polymers.

The present invention does not comprise polymers of formula I, wherein R¹ and R² are independently of each other a C₁-C₂₅alkyl group, especially a C₄-C₁₂alkyl group, which can be interrupted by one or more oxygen atoms,

15 Ar¹ and Ar^{1'} are a group of formula

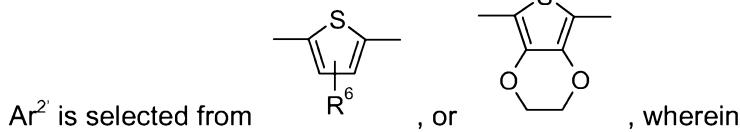


, wherein R⁶ is hydrogen, C₁-C₁₈alkyl, or C₁-C₁₈alkoxy, and R³² is methyl, Cl, or

OMe,

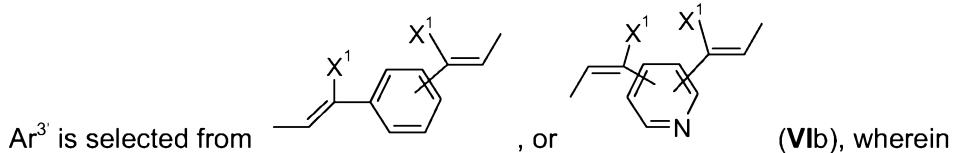
a = b = c = f = 0; d = e = 1;

20



Ar^{2'} is selected from , or , wherein

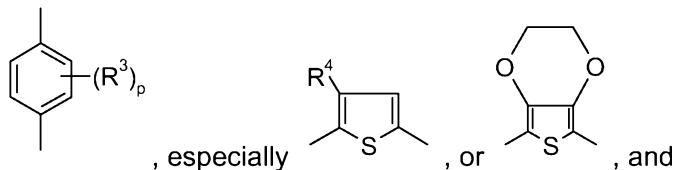
R⁶ is hydrogen, C₁-C₁₈alkyl, or C₁-C₁₈alkoxy, and



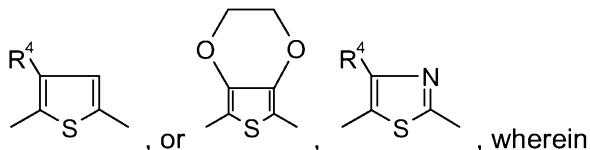
Ar^{3'} is selected from , or (VIIb), wherein

X^1 is a hydrogen atom, or a cyano group.

Ar^1 and $Ar^{1'}$ can be different, but are preferably the same and are a group of formula



5 Ar^2 , $Ar^{2'}$, Ar^3 , $Ar^{3'}$, Ar^4 and $Ar^{4'}$ are independently of each other a group of formula



p stands for 0, 1, or 2, R^3 may be the same or different within one group and is selected from C_1-C_{25} alkyl, which may optionally be substituted by E and/or interrupted by D, or C_1-C_{18} alkoxy, which may optionally be substituted by E and/or interrupted by D; R^4 is C_6-C_{25} alkyl, which may optionally be substituted by E and/or interrupted by D, C_6-C_{14} aryl, such as phenyl, naphthyl, or biphenyl, which may optionally be substituted by G, C_1-C_{25} alkoxy, which may optionally be substituted by E and/or interrupted by D, or C_7-C_{15} aralkyl, wherein ar may optionally be substituted by G,

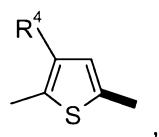
10 D is $-CO-$, $-COO-$, $-S-$, $-SO-$, $-SO_2-$, $-O-$, $-NR^{25}-$, wherein R^{25} is C_1-C_{12} alkyl, such as methyl, ethyl, n-propyl, iso-propyl, n-butyl, isobutyl, or sec-butyl;

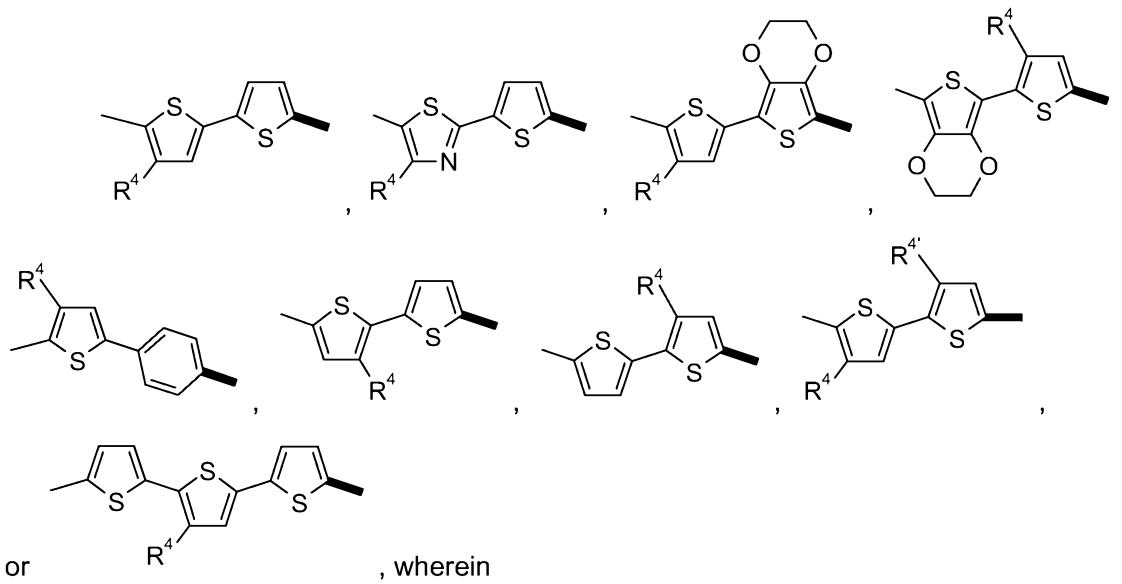
15 E is $-OR^{29}$, $-SR^{29}$, $-NR^{25}R^{25}$, $-COR^{28}$, $-COOR^{27}$, $-CONR^{25}R^{25}$; or $-CN$; wherein R^{25} , R^{27} , R^{28} and R^{29} are independently of each other C_1-C_{12} alkyl, such as methyl, ethyl, n-propyl, iso-propyl, n-butyl, isobutyl, sec-butyl, hexyl, octyl, or 2-ethyl-hexyl, or C_6-C_{14} aryl, such as phenyl, naphthyl, or biphenyl,

20 G has the same preferences as E, or is C_1-C_{18} alkyl, especially C_1-C_{12} alkyl, such as methyl, ethyl, n-propyl, iso-propyl, n-butyl, isobutyl, sec-butyl, hexyl, octyl, or 2-ethyl-hexyl.

The units and may be

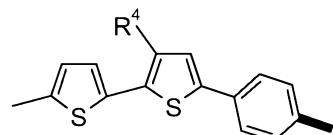
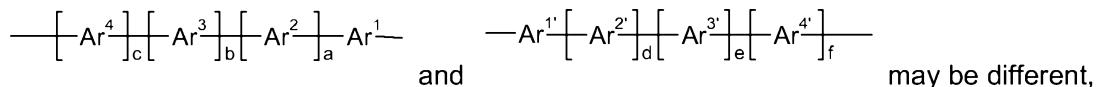
25 different, but are preferably the same and are a group of formula





— indicates the bond to the diketopyrrolopyrrole skeleton, and R^4 is as defined above and R^4' has the meaning of R^4 .

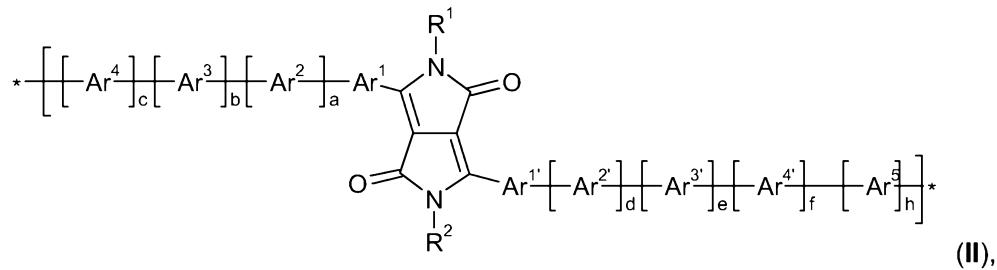
In another preferred embodiment of the present invention the units



but are preferably the same and are a group of formula

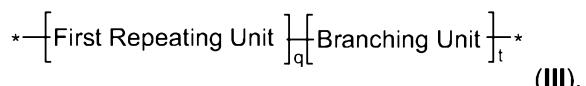
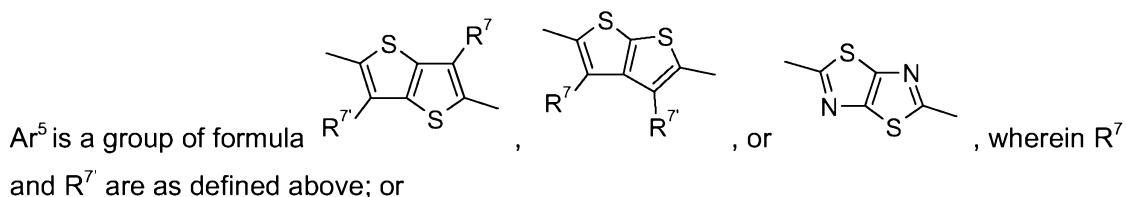
10 wherein R^4 is $\text{C}_6\text{-C}_{25}\text{alkyl}$, which may optionally be interrupted by one or more oxygen atoms.

In another preferred embodiment of the present invention the polymer comprises repeating units of the formula



wherein a, b, c, d, e, f, R^1 , R^2 , Ar^1 , Ar^1' , Ar^2 , Ar^2' , Ar^3 , Ar^3' , Ar^4 and Ar^4' are as defined above, h is 1, and

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the polymer has the structure of formula

wherein the First "Repeating Unit" is a repeating unit of formula I,

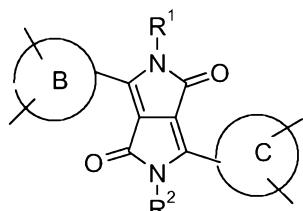
5 the "Branching Unit" is a unit having more than two linkage sites, and
 q and t are integers, wherein q/t is the ratio of the repeating unit of formula I to the
 "Branching Unit".

The repeating unit of formula II has advantageously a symmetric structure: a = d; b = e; c = f;

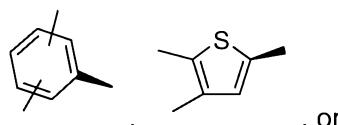
10 Ar¹ = Ar^{1'}; Ar² = Ar^{2'}; Ar³ = Ar^{3'}; Ar⁴ = Ar^{4'}.

The "Branching Unit" is a unit having more than two linkage sites. Examples of branching units are, for example, described in Dendrimers and Other Dendritic Polymers, D. A. Tomalia, J. M. J. Fréchet (Eds), John Wiley & Sons, Ltd. 2002; Star and Hyperbranched Polymers, M. K. Mishra and S. Kobayashi (Eds), Marcel Dekker 2000.

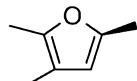
Examples of especially suitable "Branching" Units are shown below:



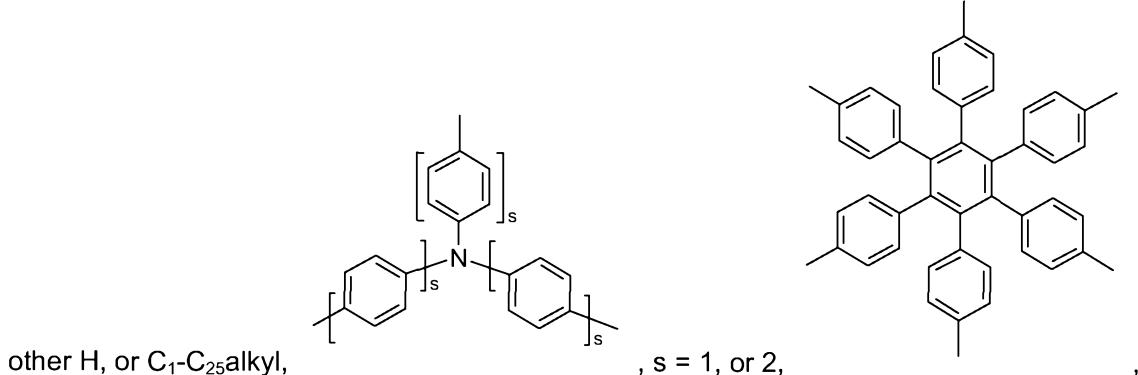
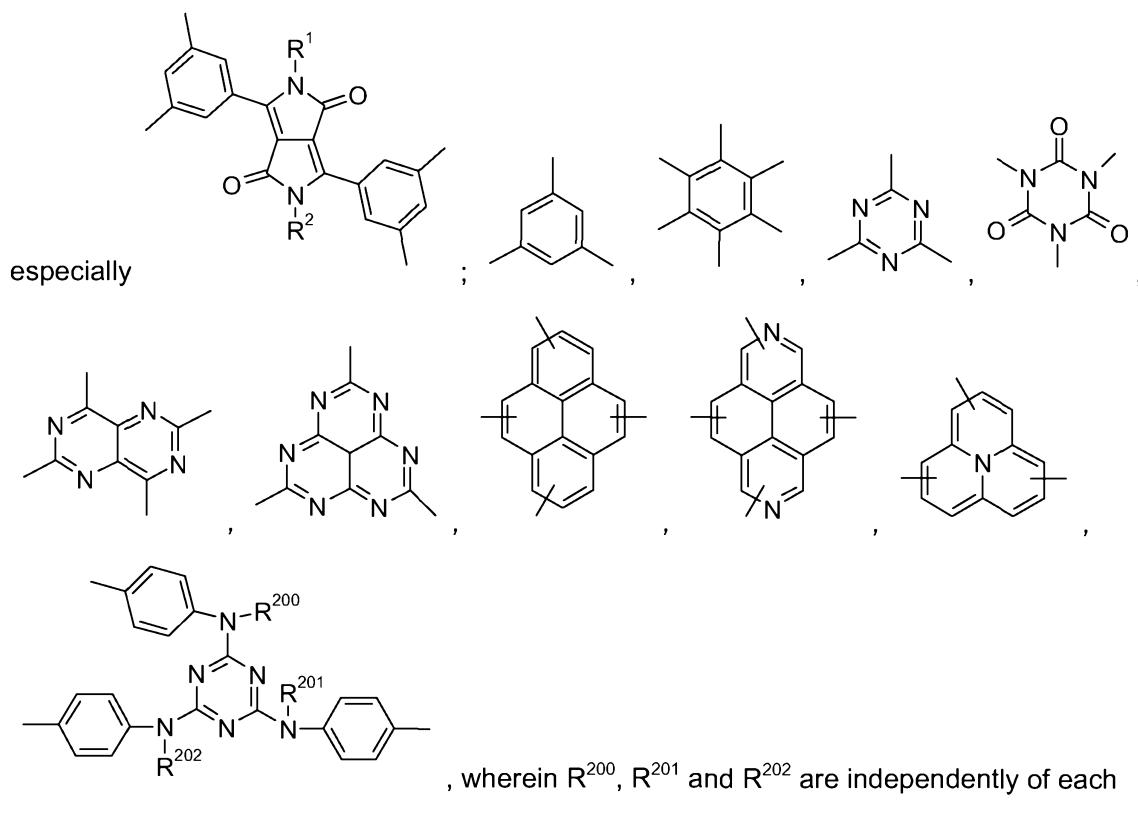
, wherein B and C are independently of each other an optionally



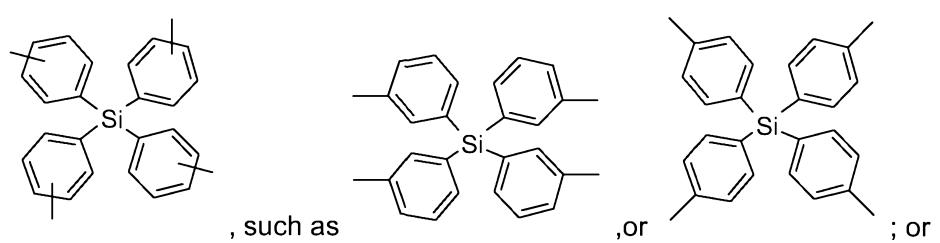
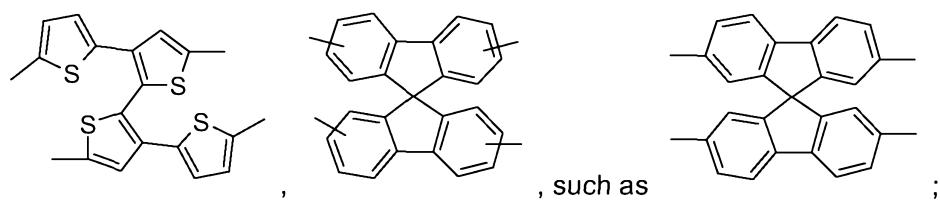
condensed aromatic, or heteroaromatic ring, such as



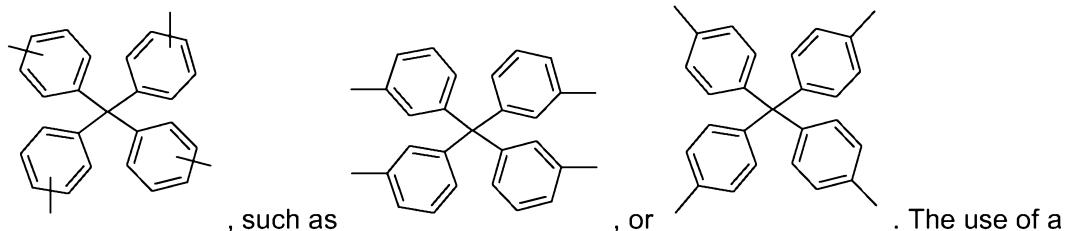
20  is the bonding to the DPP backbone,



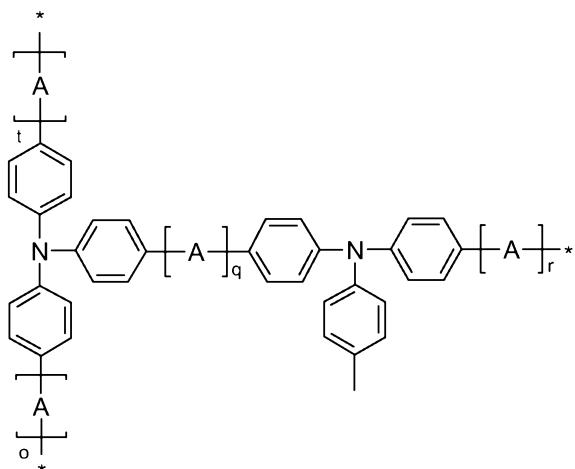
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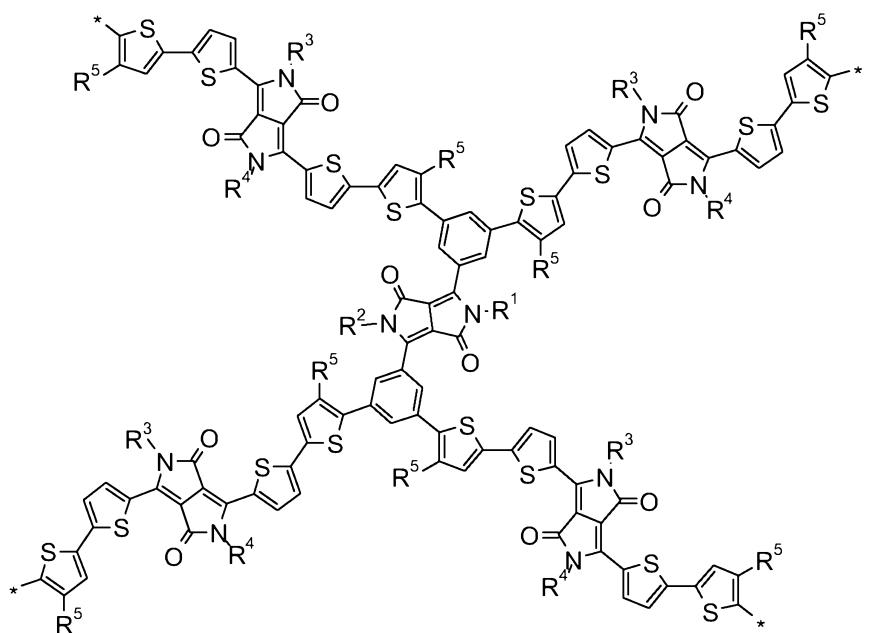
16



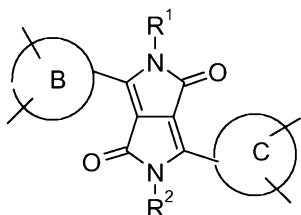
multi-functional unit ("Branching Unit") results in branched polymeric materials, as illustrated below (for exemplary purposes only) for two multi-functional units:



5 t are 0 to 500), or



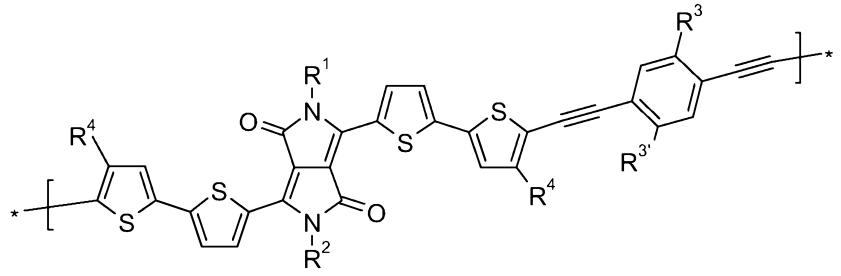
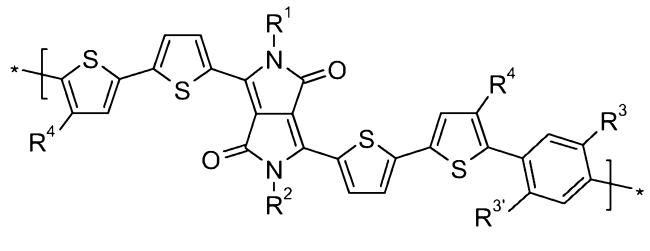
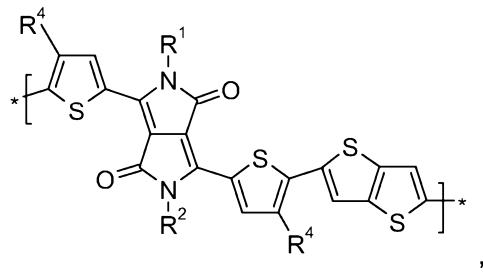
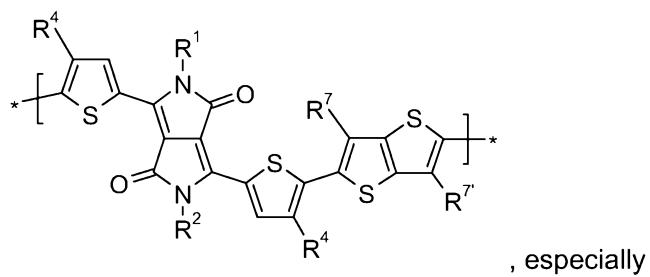
17

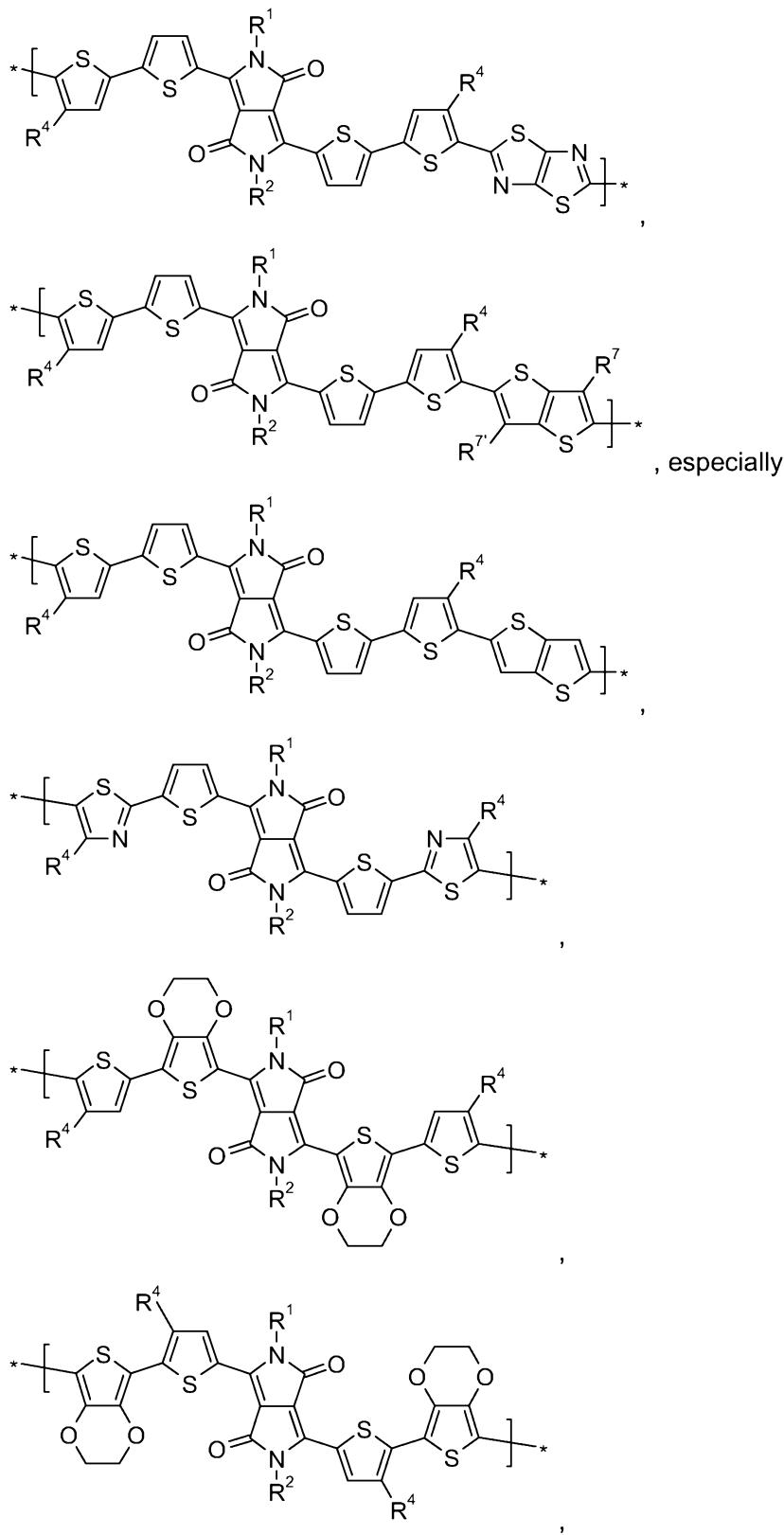


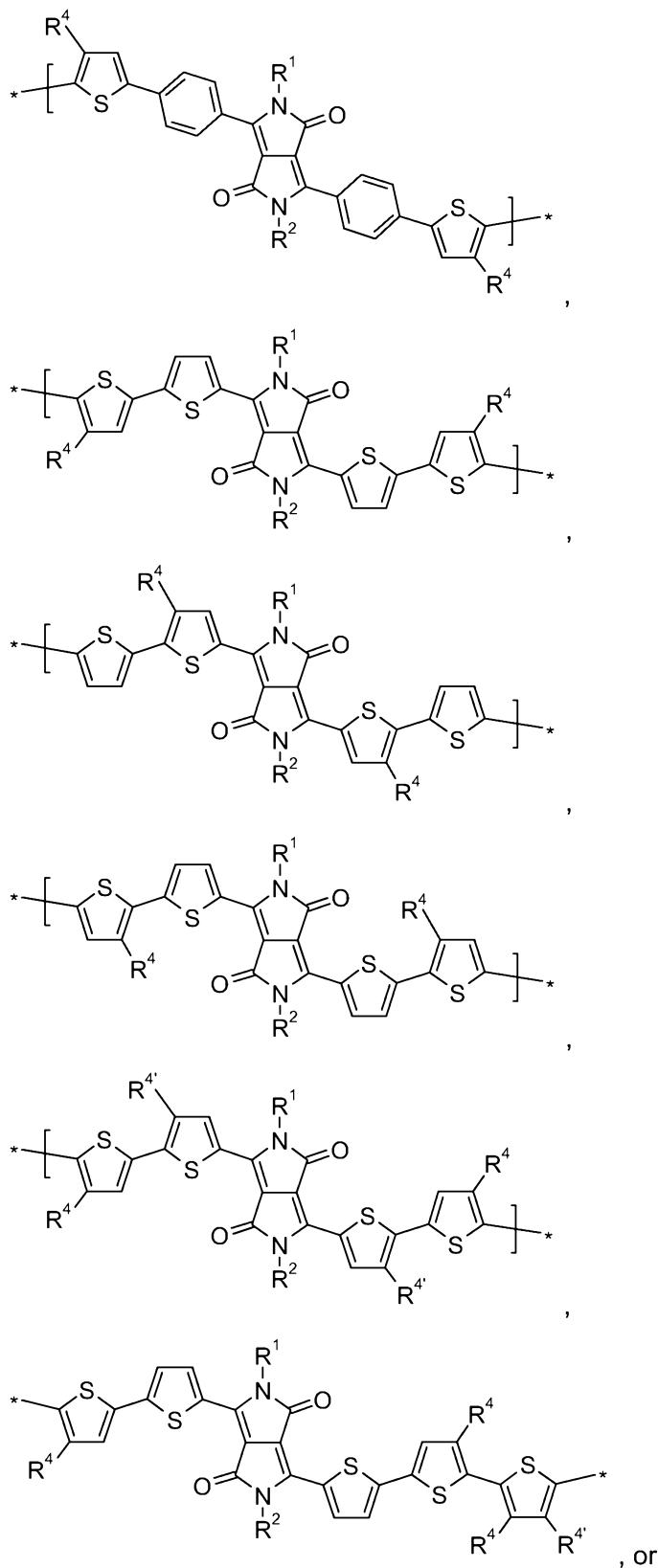
The “Branching Unit” of formula 17 and polymers derived therefrom are new and form further aspects of the present invention.

In another preferred embodiment of the present invention the polymers comprise repeating

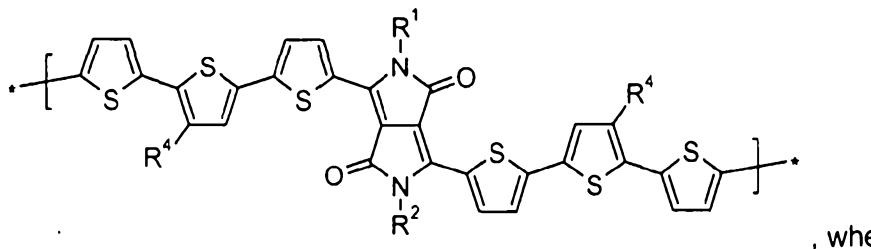
5 units of the formula







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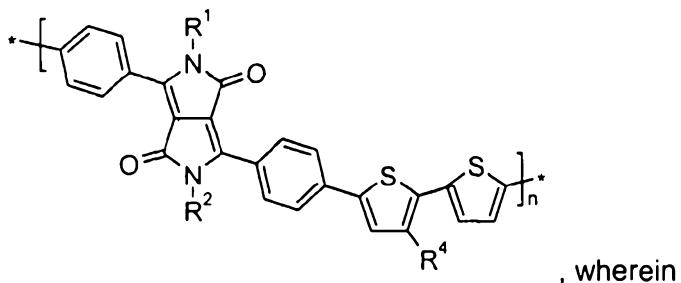
, wherein

R¹ and R² are independently from each other C₁-C₂₅alkyl, and

R³ and R^{3'} are independently from each other C₆-C₂₅alkyl, which may optionally be interrupted by one or more oxygen atoms,

5 R⁴ and R^{4'} are independently from each other C₆-C₂₅alkyl, which may optionally be interrupted by one or more oxygen atoms, and
 R⁷ and R^{7'} are independently from each other C₆-C₂₅alkyl, which may optionally be interrupted by one or more oxygen atoms.

10 In another preferred embodiment of the present invention the polymer is a polymer of the formula



, wherein

R¹ and R² are independently from each other H, or C₁-C₂₅alkyl, and

R⁴ is C₆-C₂₅alkyl, which may optionally be interrupted by one or more oxygen atoms.

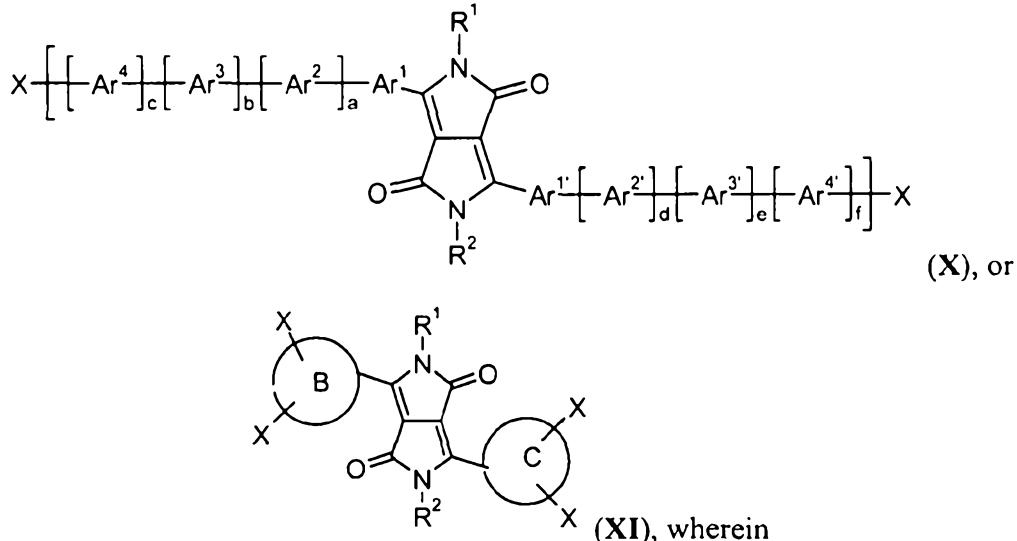
15 In one embodiment, the polymers according to the invention consist only of one or more type of repeating units of formula I. In a preferred embodiment, the polymers according to the invention consist of precisely one type of repeating unit of formula I (homopolymers).

20 According to a further aspect of the invention there is provided a semiconductor device, comprising a polymer of the formula I especially a diode, a photodiode, an organic field effect transistor and/or a solar cell, or a device containing a diode and/or a photodiode and/or an organic field effect transistor, and/or a solar cell.

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According to a further aspect of the present invention there is provided a process for the preparation of an organic semiconductor device, which process comprises applying a solution and/or dispersion of a polymer of the formula I in an organic solvent to a suitable substrate and removing the solvent.

According to a further aspect of the present invention there is provided a monomer of the formula

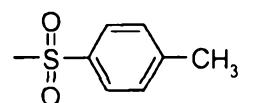


10

B and C are independently of each other an optionally condensed aromatic, or heteroaromatic ring,

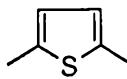
a, b, c, d, e, f, R¹, R², Ar¹, Ar¹', Ar², Ar²', Ar³, Ar³', Ar⁴ and Ar⁴' are as defined in claim 1 and X is ZnX¹², -SnR²⁰⁷R²⁰⁸R²⁰⁹, wherein R²⁰⁷, R²⁰⁸ and R²⁰⁹ are identical or different and are H or C₁-C₆alkyl, wherein two radicals optionally form a common ring and these radicals are optionally branched or unbranched and X¹² is a halogen atom, very

especially I, or Br; or -OS(O)₂CF₃, -OS(O)₂-aryl, especially



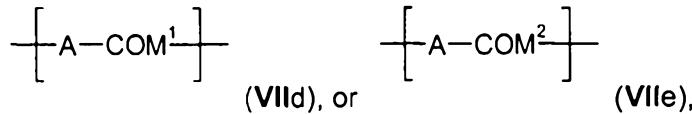
OS(O)₂CH₃, -B(OH)₂, -B(OY¹)₂, -BF₄Na, or -BF₄K, wherein Y¹ is independently in each occurrence a C₁-C₁₀alkyl group and Y² is independently in each occurrence a C₂-C₁₀alkylene group, such as -CY³Y⁴-CY⁵Y⁶-, or -CY⁷Y⁸-CY⁹Y¹⁰-CY¹¹Y¹²-, wherein Y³, Y⁴, Y⁵, Y⁶, Y⁷, Y⁸, Y⁹, Y¹⁰, Y¹¹ and Y¹² are independently of each other hydrogen, or a C₁-C₁₀alkyl group, especially -C(CH₃)₂C(CH₃)₂-, or -C(CH₃)₂CH₂C(CH₃)₂-

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with the proviso that, if Ar^1 and Ar^1 are a group of formula  , a and d are not 0.

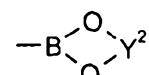
5 According to a further aspect of the present invention there is provided a use of the polymer of formula I as charge-transport, semiconducting, el. conducting, photoconducting, light emitting material, surface-modifying material, electrode materials in batteries, alignment layers, or in OFETs, ICs, TFTs, displays, RFID tags, electro- or photoluminescent devices, backlights of displays, photovoltaic or 10 sensor devices, charge injection layers, Schottky diodes, memory devices (e.g. FeFET), planarising layers, antistatics, conductive substrates or patterns, photoconductors, or electrophotographic applications (recording).

15 According to a further aspect of the present invention there is provided a process for preparing polymers of formula



which process comprises reacting a dihalogenide, such as a dibromide or dichloride, especially a dibromide corresponding to formula $\text{Br}-\text{A}-\text{Br}$ with an equimolar

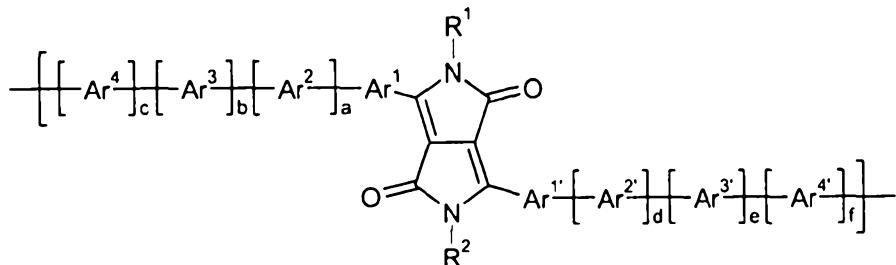
20 amount of a diboronic acid or diboronate corresponding to formula $x^{11} \left[\text{COM}^1 \right] x^{11}$, or $x^{11} \left[\text{COM}^2 \right] x^{11}$ under the catalytic action of Pd and triphenylphosphine, wherein A, COM^1 and COM^2 are as defined in claim 3,



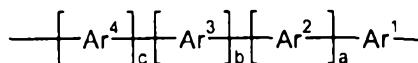
25 X^{11} is independently in each occurrence $-\text{B}(\text{OH})_2$, $-\text{B}(\text{OY}^1)_2$ or $-\text{B}(\text{OY}^2)_2$, wherein Y^1 is independently in each occurrence a $\text{C}_1\text{-C}_{10}$ alkyl group and Y^2 is independently in each occurrence a $\text{C}_2\text{-C}_{10}$ alkylene group, such as $-\text{CY}^3\text{Y}^4-\text{CY}^5\text{Y}^6-$, or $-\text{CY}^7\text{Y}^8-\text{CY}^9\text{Y}^{10}-\text{CY}^{11}\text{Y}^{12}-$, wherein Y^3 , Y^4 , Y^5 , Y^6 , Y^7 , Y^8 , Y^9 , Y^{10} , Y^{11} and Y^{12} are independently of each other hydrogen, or a $\text{C}_1\text{-C}_{10}$ alkyl group, especially $-\text{C}(\text{CH}_3)_2\text{C}(\text{CH}_3)_2-$, or $-\text{C}(\text{CH}_3)_2\text{CH}_2\text{C}(\text{CH}_3)_2-$.

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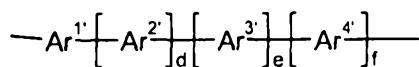
According to a further aspect of the present invention there is provided a monomer of formula X-A-X, wherein A is a group of formula



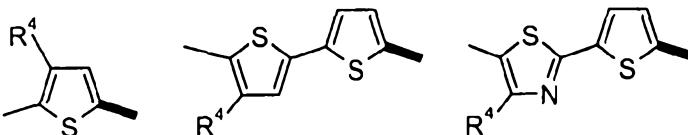
and X is



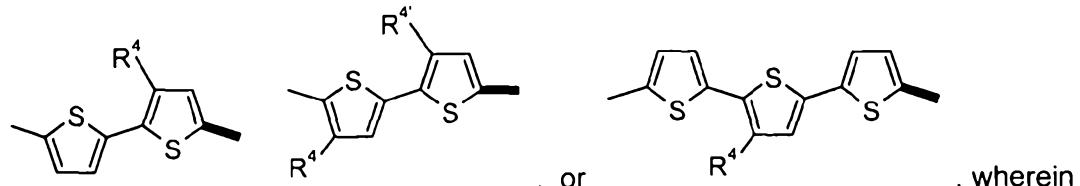
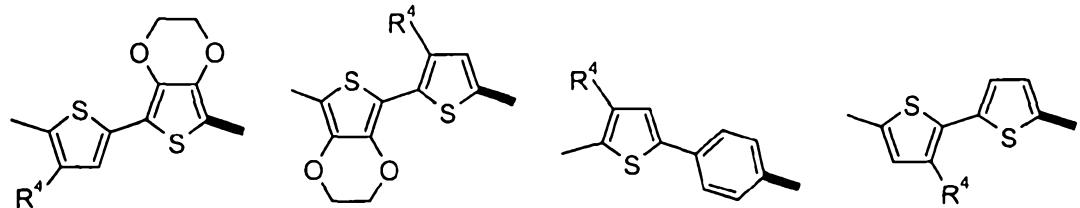
5 halogen, especially Br, wherein



may be different, but are preferably the same and



are a group of formula



10 — indicates the bond to the diketopyrrolopyrrole skeleton, R⁴ has the meaning of R⁴, and R¹ and R² and R⁴ are as defined previously.

According to a further aspect of the present invention there is provided a method of making a device, comprising incorporating the polymer of formula I into the device.

15 According to the present invention the term "polymer" comprises polymers as well as oligomers, wherein a polymer is a molecule of high relative molecular mass, the structure of which essentially comprises the repetition of units derived, actually or

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conceptually, from molecules of low relative molecular mass and an oligomer is a molecule of intermediate molecular mass, the structure of which essentially comprises a small plurality of units derived, actually or conceptually, from molecules 5 of lower relative molecular mass. A molecule is regarded as having a high relative molecular mass if it has properties which do not vary significantly with the removal of one or a few of the units. A molecule is regarded as

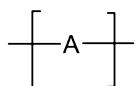
having an intermediate molecular mass if it has properties which do vary significantly with the removal of one or a few of the units.

According to the present invention a homopolymer is a polymer derived from one species of
 5 (real, implicit, or hypothetical) monomer. Many polymers are made by the mutual reaction of complementary monomers. These monomers can readily be visualized as reacting to give an "implicit monomer", the homopolymerisation of which would give the actual product, which can be regarded as a homopolymer. Some polymers are obtained by chemical modification of other polymers, such that the structure of the macromolecules that constitute the resulting
 10 polymer can be thought of having been formed by the homopolymerisation of a hypothetical monomer.

Accordingly a copolymer is a polymer derived from more than one species of monomer, e.g. bipolymer, terpolymer, quaterpolymer, etc.

15 The oligomers of this invention have a weight average molecular weight of < 2,000 Daltons. The polymers of this invention preferably have a weight average molecular weight of 2,000 Daltons or greater, especially 2,000 to 2,000,000 Daltons, more preferably 10,000 to 1,000,000 and most preferably 10,000 to 750,000 Daltons. Molecular weights are determined
 20 according to gel permeation chromatography using polystyrene standards.

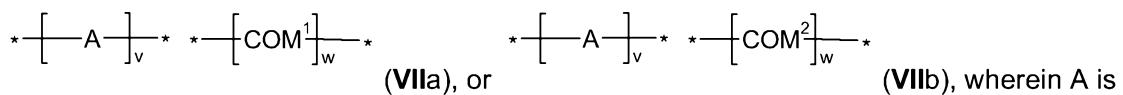
In a preferred embodiment the polymers of the present invention are homopolymers, comprising repeating units of the formula **I**, which can be represented by the formula



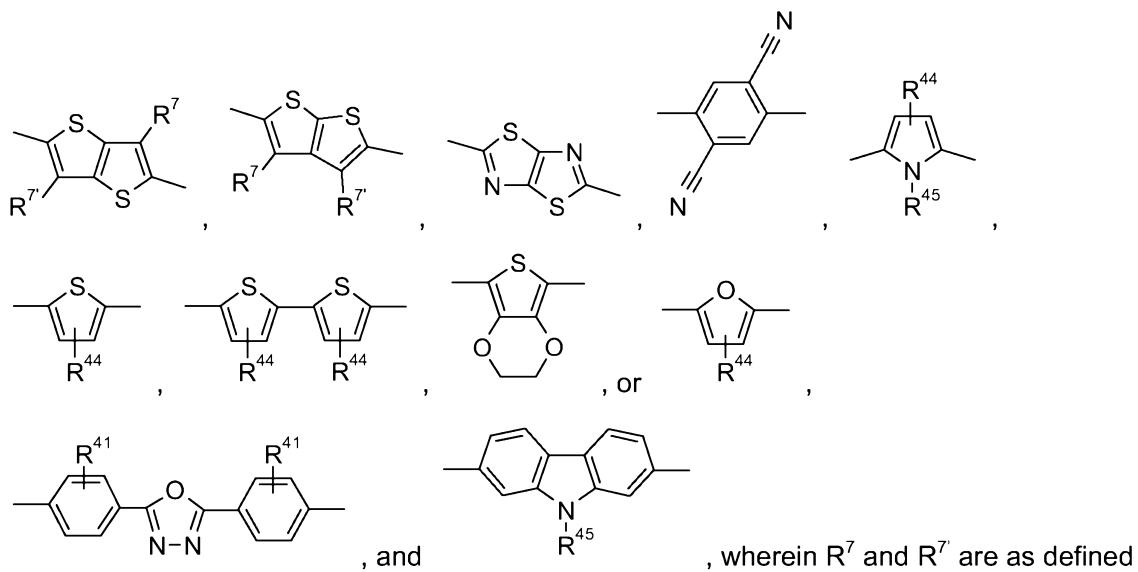
(**VII**), wherein A is a repeating unit of formula **I**. In said aspect the polymer

25 comprises preferably one of the repeating units of formula **Ia** to **II**, wherein repeating units of the formula **Ie**, **Id**, **Ih** and **II** are especially preferred.

Copolymers of formula **VII**, involving repeating units of formula **I** and **COM**¹ or **COM**² (v = 0.995 to 0.005, w = 0.005 to 0.995), can also be obtained by coupling reactions, such as
 30 nickel coupling reactions:

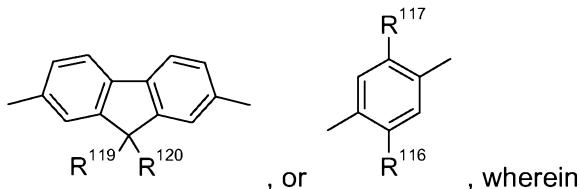


as defined above and **-COM**¹- is selected from repeating units of formula:



above,

5 R^{44} and R^{41} are hydrogen, C_1 - C_{18} alkyl, or C_1 - C_{18} alkoxy, and
 R^{45} is H, C_1 - C_{18} alkyl, or C_1 - C_{18} alkyl which is substituted by E and/or interrupted by D,
especially C_1 - C_{18} alkyl which is interrupted by $-O-$, wherein D and E are as defined above,



and -COM^2- is a group of formula

R^{116} and R^{117} are independently of each other H, C₁-C₁₈alkyl, which can optionally be

10 interrupted by O, or C₁-C₁₈alkoxy, which can optionally be interrupted by O,

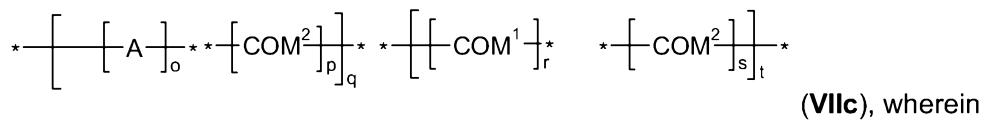
R^{119} and R^{120} are independently of each other H, C_1 - C_{18} alkyl, which can optionally be interrupted by O, or

R^{119} and R^{120} together form a group of formula $=CR^{100}R^{101}$, wherein

R^{100} and R^{101} are independently of each other H, C₁-C₁₈alkyl, or

15 R^{119} and R^{120} together form a five or six membered ring, which optionally can be substituted by C_1-C_{18} alkyl.

In said embodiment the polymer is a polymer of formula



20 A, COM¹ and COM² are as defined above,
o is 1,
p is 0, or 1,

q is 0.005 to 1,

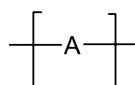
r is 0, or 1,

s is 0, or 1, wherein e is not 1, if d is 0,

t is 0.995 to 0, wherein the sum of c and f is 1.

5

Homopolymers of formula **VII** are, for example, obtained by nickel coupling reactions, especially the Yamamoto reaction:



(**VII**), wherein A is a repeating unit of formula **I**.

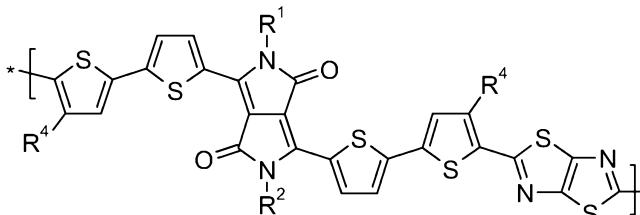
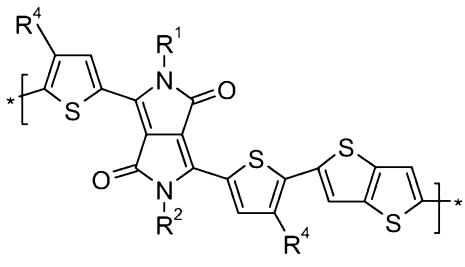
10 Polymerization processes involving only dihalo-functional reactants may be carried out using nickel coupling reactions. One such coupling reaction was described by Colon et al. in J. Pol. Sci., Part A, Polymer Chemistry Edition 28 (1990) 367, and by Colon et al. in J. Org. Chem. 51 (1986) 2627. The reaction is typically conducted in a polar aprotic solvent (e.g., dimethylacetamide) with a catalytic amount of nickel salt, a substantial amount of 15 triphenylphosphine and a large excess of zinc dust. A variant of this process is described by Ioyda et al. in Bull. Chem. Soc. Jpn, 63 (1990) 80 wherein an organo-soluble iodide was used as an accelerator.

20 Another nickel-coupling reaction was disclosed by Yamamoto in Progress in Polymer Science 17 (1992) 1153 wherein a mixture of dihaloaromatic compounds were treated with an excess amount of nickel (1,5-cyclooctadiene) complex in an inert solvent. All nickel-coupling reactions when applied to reactant mixtures of two or more aromatic dihalides yield essentially random copolymers. Such polymerization reactions may be terminated by the addition of small amounts of water to the polymerization reaction mixture, which will replace 25 the terminal halogen groups with hydrogen groups. Alternatively, a monofunctional aryl halide may be used as a chain-terminator in such reactions, which will result in the formation of a terminal aryl group.

30 Nickel-coupling polymerizations yield essentially homopolymers or random copolymers comprising DPP group-containing units and units derived from other co-monomers.

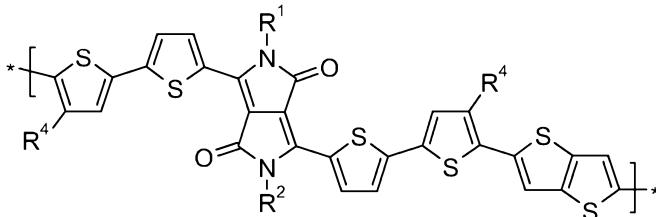
Homopolymers of formula **VIIId**, or **VIIe** can be obtained, for example, by the Suzuki reaction:

$\left[\text{A}-\text{COM}^1 \right]$ (VII^d), or $\left[\text{A}-\text{COM}^2 \right]$ (VII^e), wherein A, COM¹ and COM² are as defined above. Examples of preferred homopolymers of formula VII^d, or VII^e are shown below:

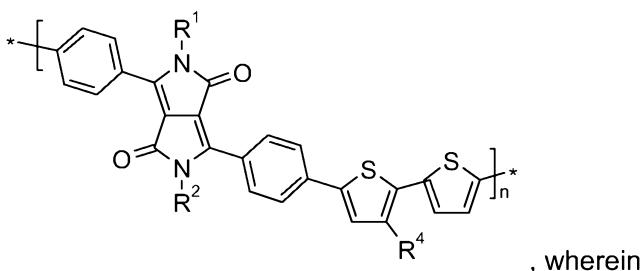


5

, and



Another example of a homopolymer of formula VII^d is the polymer of the formula



, wherein

R¹ and R² are independently from each other H, or C₁-C₂₅alkyl, and

10 R⁴ is C₆-C₂₅alkyl, which may optionally be interrupted by one or more oxygen atoms.

The condensation reaction of an aromatic boronate and a halogenide, especially a bromide, commonly referred to as the "Suzuki reaction", is tolerant of the presence of a variety of organic functional groups as reported by N. Miyaura and A. Suzuki in Chemical Reviews,

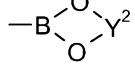
15 Vol. 95, pp. 457-2483 (1995). Preferred catalysts are 2-dicyclohexylphosphino-2',6'-di-alkoxybiphenyl/palladium(II)acetates. An especially preferred catalyst is 2-

dicyclohexylphosphino-2',6'-di-methoxybiphenyl (sPhos)/palladium(II)acetate. This reaction can be applied to preparing high molecular weight polymers and copolymers.

To prepare polymers corresponding to formula **VIIId**, or **VIIe** a dihalogenide, such as a

5 dibromide or dichloride, especially a dibromide corresponding to formula $\text{Br}-\text{A}-\text{Br}$ is reacted with an equimolar amount of a diboronic acid or boronate corresponding to formula



$-\text{B}(\text{OH})_2$, $-\text{B}(\text{OY}^1)_2$ or  , wherein Y^1 is independently in each occurrence a

10 $\text{C}_1\text{-C}_{10}$ alkyl group and Y^2 is independently in each occurrence a $\text{C}_2\text{-C}_{10}$ alkylene group, such as

$-\text{CY}^3\text{Y}^4\text{-CY}^5\text{Y}^6-$, or $-\text{CY}^7\text{Y}^8\text{-CY}^9\text{Y}^{10}\text{-CY}^{11}\text{Y}^{12}-$, wherein $\text{Y}^3, \text{Y}^4, \text{Y}^5, \text{Y}^6, \text{Y}^7, \text{Y}^8, \text{Y}^9, \text{Y}^{10}, \text{Y}^{11}$

and Y^{12} are independently of each other hydrogen, or a $\text{C}_1\text{-C}_{10}$ alkyl group, especially

$-\text{C}(\text{CH}_3)_2\text{C}(\text{CH}_3)_2-$, or $-\text{C}(\text{CH}_3)_2\text{CH}_2\text{C}(\text{CH}_3)_2-$, under the catalytic action of Pd and

triphenylphosphine. The reaction is typically conducted at about 70 °C to 180 °C in an

aromatic hydrocarbon solvent such as toluene. Other solvents such as dimethylformamide

15 and tetrahydrofuran can also be used alone, or in mixtures with an aromatic hydrocarbon. An aqueous base, preferably sodium carbonate or bicarbonate, is used as the HBr scavenger.

Depending on the reactivities of the reactants, a polymerization reaction may take 2 to 100 hours. Organic bases, such as, for example, tetraalkylammonium hydroxide, and phase

transfer catalysts, such as, for example TBAB, can promote the activity of the boron (see, for

20 example, Leadbeater & Marco; Angew. Chem. Int. Ed. Eng. 42 (2003) 1407 and references cited therein). Other variations of reaction conditions are given by T. I. Wallen and B. M.

Novak in J. Org. Chem. 59 (1994) 5034-5037; and M. Remmers, M. Schulze, and G. Wegner

in Macromol. Rapid Commun. 17 (1996) 239-252.

25 If desired, a monofunctional aryl halide or aryl boronate may be used as a chain-terminator in such reactions, which will result in the formation of a terminal aryl group.

It is possible to control the sequencing of the monomeric units in the resulting copolymer by controlling the order and composition of monomer feeds in the Suzuki reaction.

30 The polymers of the present invention can also be synthesized by the Stille coupling (see, for example, Babudri et al, J. Mater. Chem., 2004, 14, 11-34; J. K. Stille, Angew. Chemie Int. Ed. Engl. 1986, 25, 508). To prepare polymers corresponding to formula **VIIId**, or **VIIe** a

dihalogenide, such as a dibromide or dichloride, especially a dibromide corresponding to

formula $\text{Br}-\text{A}-\text{Br}$ is reacted with a compound of formula $\text{X}^{11}-[\text{COM}^1]-\text{X}^{11}$, or

$\text{X}^{11}-[\text{COM}^2]-\text{X}^{11}$

, wherein X^{11} is a group $-\text{SnR}^{207}\text{R}^{208}\text{R}^{209}$, in an inert solvent at a temperature in range from 0°C to 200°C in the presence of a palladium-containing catalyst. It must be

5 ensured here that the totality of all monomers used has a highly balanced ratio of organotin functions to halogen functions. In addition, it may prove advantageous to remove any excess reactive groups at the end of the reaction by end-capping with monofunctional reagents. In order to carry out the process, the tin compounds and the halogen compounds are preferably introduced into one or more inert organic solvents and stirred at a temperature of from 0 to
10 200°C, preferably from 30 to 170°C for a period of from 1 hour to 200 hours, preferably from 5 hours to 150 hours. The crude product can be purified by methods known to the person skilled in the art and appropriate for the respective polymer, for example repeated re-precipitation or even by dialysis.

15 Suitable organic solvents for the process described are, for example, ethers, for example diethyl ether, dimethoxyethane, diethylene glycol dimethyl ether, tetrahydrofuran, dioxane, dioxolane, diisopropyl ether and tert-butyl methyl ether, hydrocarbons, for example hexane, isohexane, heptane, cyclohexane, benzene, toluene and xylene, alcohols, for example methanol, ethanol, 1-propanol, 2-propanol, ethylene glycol, 1-butanol, 2-butanol and tert-
20 butanol, ketones, for example acetone, ethyl methyl ketone and isobutyl methyl ketone, amides, for example dimethylformamide (DMF), dimethylacetamide and N-methylpyrrolidone, nitriles, for example acetonitrile, propionitrile and butyronitrile, and mixtures thereof.

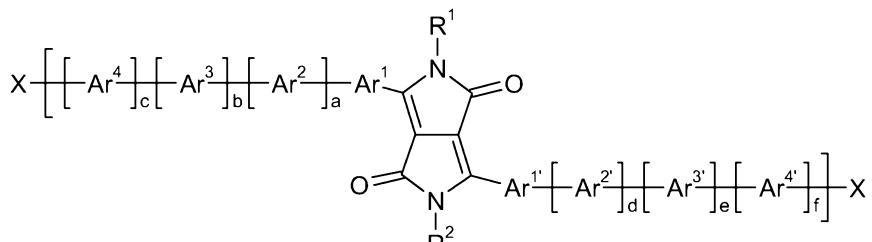
25 The palladium and phosphine components should be selected analogously to the description for the Suzuki variant.

Alternatively, the polymers of the present invention can also be synthesized by the Negishi reaction using zinc reagents $(\text{A}-\text{ZnX}^{12})_2$, wherein X^{12} is halogen) and halides or triflates $(\text{COM}^1-\text{X}^{11})_2$, wherein X^{11} is halogen or triflate). Reference is, for example, made to E.
30 Negishi et al., *Heterocycles* 18 (1982) 117-22.

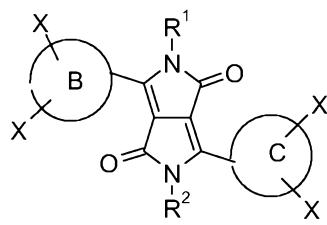
In addition, halogen derivatives of the DPPs can be polymerized oxidatively (for example using FeCl_3 , see, *inter alia*, P. Kovacic et al., *Chem. Ber.* 87 (1987) 357 to 379; M. Wenda et

al., *Macromolecules* 25 (1992) 5125) or electrochemically (see, *inter alia*, N. Saito et al., *Polym. Bull.* 30 (1993) 285).

The monomers of the formula



(X), and



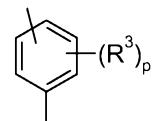
(XI), are new and form a further aspect of the present invention,

Wherein B and C are independently of each other an optionally condensed aromatic, or heteroaromatic ring,

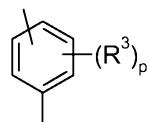
a, b, c, d, e, f, Ar¹, Ar^{1'}, Ar², Ar^{2'}, Ar³, Ar^{3'}, Ar⁴ and Ar^{4'} are as defined in claim 1 and X is

10 ZnX¹², -SnR²⁰⁷R²⁰⁸R²⁰⁹, wherein R²⁰⁷, R²⁰⁸ and R²⁰⁹ are identical or different and are H or C₁-C₆alkyl, wherein two radicals optionally form a common ring and these radicals are optionally branched or unbranched and X¹² is a halogen atom, very especially I, or Br; or -OS(O)₂CF₃, -

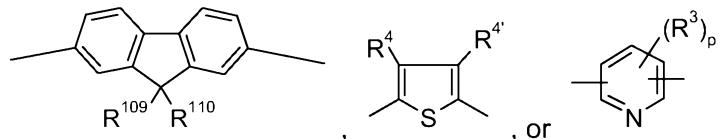
OS(O)₂-aryl, especially , -OS(O)₂CH₃, -B(OH)₂, -B(OY¹)₂, , -BF₄Na, or -BF₄K, wherein Y¹ is independently in each occurrence a C₁-C₁₀alkyl group and Y² is independently in each occurrence a C₂-C₁₀alkylene group, such as -CY³Y⁴-CY⁵Y⁶-, or -CY⁷Y⁸-CY⁹Y¹⁰- CY¹¹Y¹²-, wherein Y³, Y⁴, Y⁵, Y⁶, Y⁷, Y⁸, Y⁹, Y¹⁰, Y¹¹ and Y¹² are independently of each other hydrogen, or a C₁-C₁₀alkyl group, especially -C(CH₃)₂C(CH₃)₂- or -C(CH₃)₂CH₂C(CH₃)₂-



with the proviso that, if Ar^1 and $\text{Ar}^{1'}$ are a group of formula

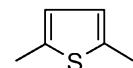


and Ar^2 and $\text{Ar}^{2'}$ are different from a group of formula



with the further proviso that, if Ar^1 and $\text{Ar}^{1'}$ are a group of formula

5 not 0.



A further aspect of the invention relates to both the oxidised and reduced form of the polymers and materials according to this invention. Either loss or gain of electrons results in formation of a highly delocalised ionic form, which is of high conductivity. This can occur on 10 exposure to common dopants. Suitable dopants and methods of doping are known to those skilled in the art, e. g., from EP0528662, US5,198,153, or WO 96/21659.

The doping process typically implies treatment of the semiconductor material with an 15 oxidising or reducing agent in a redox reaction to form delocalised ionic centres in the material, with the corresponding counterions derived from the applied dopants. Suitable doping methods comprise for example exposure to a doping vapor in the atmospheric pressure or at a reduced pressure, electrochemical doping in a solution containing a dopant, bringing a dopant into contact with the semiconductor material to be thermally diffused, and ion-implantation of the dopant into the semiconductor material.

20

When electrons are used as carriers, suitable dopants are for example halogens (e. g., I_2 , Cl_2 , Br_2 , ICl , ICl_3 , IBr and IF), Lewis acids (e.g., PF_5 , AsF_5 , SbF_5 , BF_3 , BCl_3 , SbCl_5 , BBr_3 and S_0_3), protonic acids, organic acids, or amino acids (e. g., HF , HCl , HNO_3 , H_2SO_4 , HClO_4 , FSO_3H and CISO_3H), transition metal compounds (e.g., FeCl_3 , FeOCl , $\text{Fe}(\text{ClO}_4)_3$, $\text{Fe}(4-$ 25 $\text{CH}_3\text{C}_6\text{H}_4\text{SO}_3)_3$, TiCl_4 , ZrCl_4 , HfCl_4 , NbF_5 , NbCl_5 , TaCl_5 , MoF_5 , MoCl_5 , WF_5 , WCl_6 , UF_6 and LnCl_3 (wherein Ln is a lanthanoid), anions (e. g., Cl^- , Br^- , I^- , I^{3-} , HSO_4^- , SO_4^{2-} , NO_3^- , ClO_4^- , BF_4^- , PF_6^- , AsF_6^- , SbF_6^- , FeCl_4^- , $\text{Fe}(\text{CN})_6^{3-}$, anions of various sulfonic acids, such as aryl- SO_3^-).

When holes are used as carriers, examples of dopants are cations (e.g., H⁺, Li⁺, Na⁺, K⁺, Rb⁺ and Cs⁺), alkali metals (e.g., Li, Na, K, Rb, and Cs), alkaline-earth metals (e.g., Ca, Sr, and Ba), O₂, XeOF₄, (NO₂⁺)(SbF₆⁻), (NO₂⁺)(SbCl₆⁻), (NO₂⁺)(BF₄⁻), AgClO₄, H₂IrCl₆, La(NO₃)₃·6H₂O, FSO₂OOSO₂F, Eu, acetylcholine, R₄N⁺, (R is an alkyl group), R₄P⁺ (R is an alkyl group), 5 R₆As⁺ (R is an alkyl group), and R₃S⁺ (R is an alkyl group).

The conducting form of the compounds and materials of the present invention can be used as an organic "metal" in applications, for example, but not limited to, charge injection layers and ITO planarising layers in organic light emitting diode applications, films for flat panel 10 displays and touch screens, antistatic films, printed conductive substrates, patterns or tracts in electronic applications such as printed circuit boards and condensers.

Halogen is fluorine, chlorine, bromine and iodine.

15 C₁-C₂₅alkyl is typically linear or branched, where possible. Examples are methyl, ethyl, n-propyl, isopropyl, n-butyl, sec.-butyl, isobutyl, tert.-butyl, n-pentyl, 2-pentyl, 3-pentyl, 2,2-dimethylpropyl, 1,1,3,3-tetramethylpentyl, n-hexyl, 1-methylhexyl, 1,1,3,3,5,5-hexamethylhexyl, n-heptyl, isoheptyl, 1,1,3,3-tetramethylbutyl, 1-methylheptyl, 3-methylheptyl, n-octyl, 1,1,3,3-tetramethylbutyl and 2-ethylhexyl, n-nonyl, decyl, undecyl, dodecyl, 20 tridecyl, tetradecyl, pentadecyl, hexadecyl, heptadecyl, octadecyl, eicosyl, heneicosyl, docosyl, tetracosyl or pentacosyl. C₁-C₈alkyl is typically methyl, ethyl, n-propyl, isopropyl, n-butyl, sec.-butyl, isobutyl, tert.-butyl, n-pentyl, 2-pentyl, 3-pentyl, 2,2-dimethyl-propyl, n-hexyl, n-heptyl, n-octyl, 1,1,3,3-tetramethylbutyl and 2-ethylhexyl. C₁-C₄alkyl is typically methyl, ethyl, n-propyl, isopropyl, n-butyl, sec.-butyl, isobutyl, tert.-butyl.

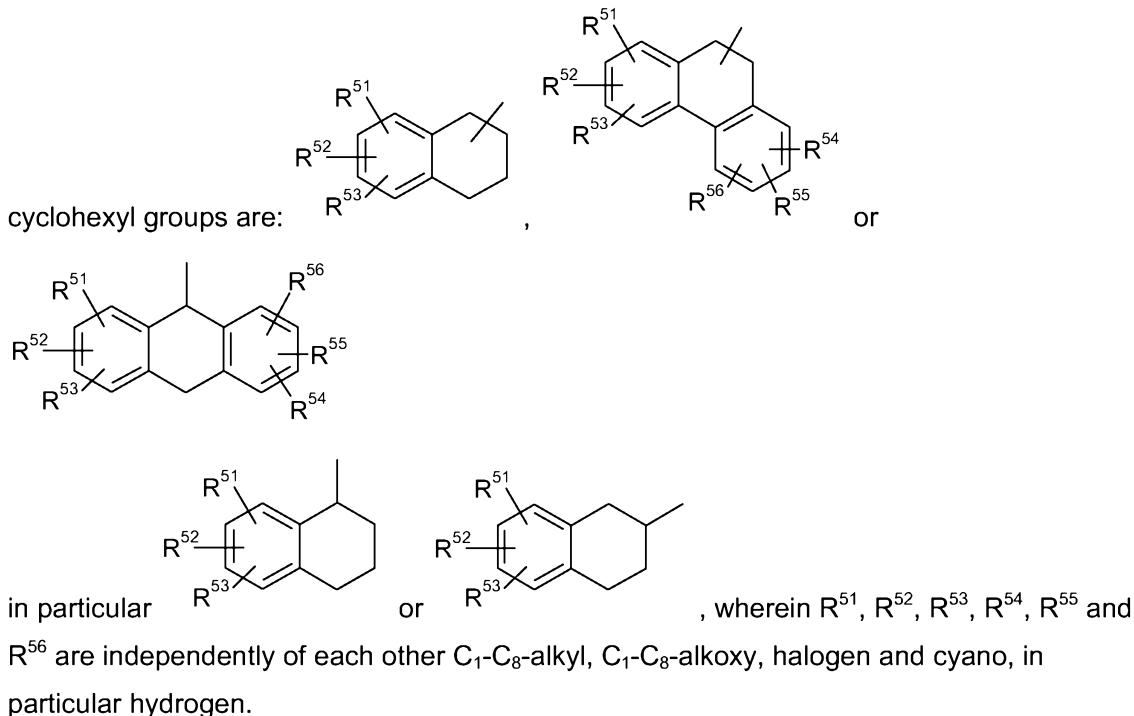
25 C₁-C₂₅alkoxy groups are straight-chain or branched alkoxy groups, e.g. methoxy, ethoxy, n-propoxy, isopropoxy, n-butoxy, sec-butoxy, tert-butoxy, amyloxy, isoamyloxy or tert-amyloxy, heptyloxy, octyloxy, isoctyloxy, nonyloxy, decyloxy, undecyloxy, dodecyloxy, tetradecyloxy, pentadecyloxy, hexadecyloxy, heptadecyloxy and octadecyloxy. Examples of C₁-C₈alkoxy 30 are methoxy, ethoxy, n-propoxy, isopropoxy, n-butoxy, sec.-butoxy, isobutoxy, tert.-butoxy, n-pentoxy, 2-pentoxy, 3-pentoxy, 2,2-dimethylpropoxy, n-hexoxy, n-heptoxy, n-octoxy, 1,1,3,3-tetramethylbutoxy and 2-ethylhexoxy, preferably C₁-C₄alkoxy such as typically methoxy, ethoxy, n-propoxy, isopropoxy, n-butoxy, sec.-butoxy, isobutoxy, tert.-butoxy. The term "alkylthio group" means the same groups as the alkoxy groups, except that the oxygen atom of the ether linkage is replaced by a sulfur atom.

C₂-C₂₅alkenyl groups are straight-chain or branched alkenyl groups, such as e.g. vinyl, allyl, methallyl, isopropenyl, 2-butenyl, 3-butenyl, isobut enyl, n-penta-2,4-dienyl, 3-methyl-but-2-enyl, n-oct-2-enyl, n-dodec-2-enyl, isododec enyl, n-dodec-2-enyl or n-octadec-4-enyl.

5 C₂₋₂₄alkynyl is straight-chain or branched and preferably C₂₋₈alkynyl, which may be unsubstituted or substituted, such as, for example, ethynyl, 1-propyn-3-yl, 1-butyn-4-yl, 1-pentyn-5-yl, 2-methyl-3-butyn-2-yl, 1,4-pentadiyn-3-yl, 1,3-pentadiyn-5-yl, 1-hexyn-6-yl, cis-3-methyl-2-penten-4-yn-1-yl, trans-3-methyl-2-penten-4-yn-1-yl, 1,3-hexadiyn-5-yl, 1-octyn-8-yl, 1-nony n-9-yl, 1-decyn-10-yl, or 1-tetracosyn-24-yl.

10 The terms "haloalkyl, haloalkenyl and haloalkynyl" mean groups given by partially or wholly substituting the above-mentioned alkyl group, alkenyl group and alkynyl group with halogen, such as trifluoromethyl etc. The "aldehyde group, ketone group, ester group, carbamoyl group and amino group" include those substituted by an alkyl group, a cycloalkyl group, an 15 aryl group, an aralkyl group or a heterocyclic group, wherein the alkyl group, the cycloalkyl group, the aryl group, the aralkyl group and the heterocyclic group may be unsubstituted or substituted. The term "silyl group" means a group of formula -SiR⁶²R⁶³R⁶⁴, wherein R⁶², R⁶³ and R⁶⁴ are independently of each other a C₁-C₈alkyl group, in particular a C₁-C₄ alkyl group, a C₆-C₂₄aryl group or a C₇-C₁₂aralkyl group, such as a trimethylsilyl group.

20 The term "cycloalkyl group" is typically C₅-C₁₂cycloalkyl, such as cyclopentyl, cyclohexyl, cycloheptyl, cyclooctyl, cyclononyl, cyclodecyl, cycloundecyl, cyclododecyl, preferably cyclopentyl, cyclohexyl, cycloheptyl, or cyclooctyl, which may be unsubstituted or substituted. The term "cycloalkenyl group" means an unsaturated alicyclic hydrocarbon group containing 25 one or more double bonds, such as cyclopentenyl, cyclopentadienyl, cyclohexenyl and the like, which may be unsubstituted or substituted. The cycloalkyl group, in particular a cyclohexyl group, can be condensed one or two times by phenyl which can be substituted one to three times with C₁-C₄-alkyl, halogen and cyano. Examples of such condensed



The term "aryl group" is typically C₆-C₂₄aryl, such as phenyl, indenyl, azulenyl, naphthyl, biphenyl, as-indacenyl, s-indacenyl, acenaphthyl, fluorenyl, phenanthryl, fluorantheny, triphenlenyl, chrysenyl, naphthacen, picenyl, perylenyl, pentaphenyl, hexacenyl, pyrenyl, or 10 anthracenyl, preferably phenyl, 1-naphthyl, 2-naphthyl, 4-biphenyl, 9-phenanthryl, 2- or 9-fluorenyl, 3- or 4-biphenyl, which may be unsubstituted or substituted. Examples of C₆-C₁₂aryl are phenyl, 1-naphthyl, 2-naphthyl, 3- or 4-biphenyl, 2- or 9-fluorenyl or 9-phenanthryl, which may be unsubstituted or substituted.

15 The term "aralkyl group" is typically C₇-C₂₄aralkyl, such as benzyl, 2-benzyl-2-propyl, β -phenyl-ethyl, α, α -dimethylbenzyl, ω -phenyl-butyl, ω, ω -dimethyl- ω -phenyl-butyl, ω -phenyl-dodecyl, ω -phenyl-octadecyl, ω -phenyl-eicosyl or ω -phenyl-docosyl, preferably C₇-C₁₈aralkyl such as benzyl, 2-benzyl-2-propyl, β -phenyl-ethyl, α, α -dimethylbenzyl, ω -phenyl-butyl, ω, ω -dimethyl- ω -phenyl-butyl, ω -phenyl-dodecyl or ω -phenyl-octadecyl, and particularly 20 preferred C₇-C₁₂aralkyl such as benzyl, 2-benzyl-2-propyl, β -phenyl-ethyl, α, α -dimethylbenzyl, ω -phenyl-butyl, or ω, ω -dimethyl- ω -phenyl-butyl, in which both the aliphatic hydrocarbon group and aromatic hydrocarbon group may be unsubstituted or substituted.

25 The term "aryl ether group" is typically a C₆₋₂₄aryloxy group, that is to say O-C₆₋₂₄aryl, such as, for example, phenoxy or 4-methoxyphenyl. The term "aryl thioether group" is typically a

C_{6-24} arylthio group, that is to say $S-C_{6-24}$ aryl, such as, for example, phenylthio or 4-methoxyphenylthio. The term “carbamoyl group” is typically a C_{1-18} carbamoyl radical, preferably C_{1-8} carbamoyl radical, which may be unsubstituted or substituted, such as, for example, carbamoyl, methylcarbamoyl, ethylcarbamoyl, n-butylcarbamoyl, tert-butylcarbamoyl, dimethylcarbamoyloxy, morpholinocarbamoyl or pyrrolidinocarbamoyl.

The terms “aryl” and “alkyl” in alkylamino groups, dialkylamino groups, alkylaryl amino groups, arylamino groups and diarylgroups are typically C_1-C_{25} alkyl and C_6-C_{24} aryl, respectively.

10

Alkylaryl refers to alkyl-substituted aryl radicals, especially C_7-C_{12} alkylaryl. Examples are toyl, such as 3-methyl-, or 4-methylphenyl, or xylyl, such as 3,4-dimethylphenyl, or 3,5-dimethylphenyl.

15

Heteroaryl is typically C_2-C_{26} heteroaryl, i.e. a ring with five to seven ring atoms or a condensed ring system, wherein nitrogen, oxygen or sulfur are the possible hetero atoms, and is typically an unsaturated heterocyclic group with five to 30 atoms having at least six conjugated π -electrons such as thienyl, benzo[b]thienyl, dibenzo[b,d]thienyl, thianthrenyl, furyl, furfuryl, 2H-pyranyl, benzofuranyl, isobenzofuranyl, dibenzofuranyl, phenoxythienyl, pyrrolyl, imidazolyl, pyrazolyl, pyridyl, bipyridyl, triazinyl, pyrimidinyl, pyrazinyl, pyridazinyl, indolizinyl, isoindolyl, indolyl, indazolyl, purinyl, quinolizinyl, chinolyl, isochinolyl, phthalazinyl, naphthyridinyl, chinoxalinyl, chinazolinyl, cinnolinyl, pteridinyl, carbazolyl, carbolinyl, benzotriazolyl, benzoxazolyl, phenanthridinyl, acridinyl, pyrimidinyl, phenanthrolinyl, phenazinyl, isothiazolyl, phenothiazinyl, isoxazolyl, furazanyl or phenoxazinyl, which can be unsubstituted or substituted.

Possible substituents of the above-mentioned groups are C_1-C_8 alkyl, a hydroxyl group, a mercapto group, C_1-C_8 alkoxy, C_1-C_8 alkylthio, halogen, halo- C_1-C_8 alkyl, a cyano group, an aldehyde group, a ketone group, a carboxyl group, an ester group, a carbamoyl group, an amino group, a nitro group or a silyl group.

As described above, the aforementioned groups may be substituted by E and/or, if desired, interrupted by D. Interruptions are of course possible only in the case of groups containing at least 2 carbon atoms connected to one another by single bonds; C_6-C_{18} aryl is not interrupted; interrupted arylalkyl or alkylaryl contains the unit D in the alkyl moiety. C_1-C_{18} alkyl substituted by one or more E and/or interrupted by one or more units D is, for example, $(CH_2CH_2O)_{1-9}R^x$,

where R^x is H or C_1 - C_{10} alkyl or C_2 - C_{10} alkanoyl (e.g. $CO-CH(C_2H_5)C_4H_9$), $CH_2-CH(OR^y)-CH_2-O-R^y$, where R^y is C_1 - C_{18} alkyl, C_5 - C_{12} cycloalkyl, phenyl, C_7 - C_{15} phenylalkyl, and R^y embraces the same definitions as R^y or is H;

C_1 - C_8 alkylene-COO- R^z , e.g. CH_2COOR_z , $CH(CH_3)COOR^z$, $C(CH_3)_2COOR^z$, where R^z is H,

5 C_1 - C_{18} alkyl, $(CH_2CH_2O)_{1-9}-R^x$, and R^x embraces the definitions indicated above;

$CH_2CH_2-O-CO-CH=CH_2$; $CH_2CH(OH)CH_2-O-CO-C(CH_3)=CH_2$.

The polymers of the invention can be used as the semiconductor layer in semiconductor devices. Accordingly, the present invention also relates to semiconductor devices,

10 comprising a polymer of the formula I. The semiconductor device is especially a diode, an organic field effect transistor and/or a solar cell, or a device containing a diode and/or an organic field effect transistor, and/or a solar cell. There are numerous types of semiconductor devices. Common to all is the presence of one or more semiconductor materials.

Semiconductor devices have been described, for example, by S. M. Sze in Physics of

15 Semiconductor Devices, 2nd edition, John Wiley and Sons, New York (1981). Such devices include rectifiers, transistors (of which there are many types, including p-n-p, n-p-n, and thin-film transistors), light emitting semiconductor devices (for example, organic light emitting diodes in display applications or backlight in e.g. liquid crystal displays), photoconductors, current limiters, solar cells, thermistors, p-n junctions, field-effect diodes, Schottky diodes, 20 and so forth. In each semiconductor device, the semiconductor material is combined with one or more metals and/or insulators to form the device. Semiconductor devices can be prepared or manufactured by known methods such as, for example, those described by Peter Van Zant in Microchip Fabrication, Fourth Edition, McGraw-Hill, New York (2000). In particular, organic electronic components can be manufactured as described by D.R.

25 Gamota et al. in Printed Organic and Molecular Electronics, Kluver Academic Publ., Boston, 2004.

A particularly useful type of transistor device, the thin-film transistor (TFT), generally includes a gate electrode, a gate dielectric on the gate electrode, a source electrode and a drain

30 electrode adjacent to the gate dielectric, and a semiconductor layer adjacent to the gate dielectric and adjacent to the source and drain electrodes (see, for example, S. M. Sze, Physics of Semiconductor Devices, 2^{sup.nd} edition, John Wiley and Sons, page 492, New York (1981)). These components can be assembled in a variety of configurations. More specifically, an organic thin-film transistor (OTFT) has an organic semiconductor layer.

Typically, a substrate supports the OTFT during manufacturing, testing, and/or use.

Optionally, the substrate can provide an electrical function for the OTFT. Useful substrate materials include organic and inorganic materials. For example, the substrate can comprise silicon materials inclusive of various appropriate forms of silicon, inorganic glasses, ceramic

5 foils, polymeric materials (for example, acrylics, polyester, epoxies, polyamides, polycarbonates, polyimides, polyketones, poly(oxy-1,4-phenyleneoxy-1,4-phenylenecarbonyl-1,4-phenylene) (sometimes referred to as poly(ether ether ketone) or PEEK), polynorbornenes, polyphenyleneoxides, poly(ethylene naphthalenedicarboxylate) (PEN), poly(ethylene terephthalate) (PET), poly(phenylene sulfide) (PPS)), filled polymeric
10 materials (for example, fiber-reinforced plastics (FRP)), and coated metallic foils.

The gate electrode can be any useful conductive material. For example, the gate electrode can comprise doped silicon, or a metal, such as aluminum, chromium, gold, silver, nickel, palladium, platinum, tantalum, and titanium. Conductive oxides, such as indium tin oxide, or

15 conducting inks/pastes comprised of carbon black/graphite or colloidal silver dispersions, optionally containing polymer binders can also be used. Conductive polymers also can be used, for example polyaniline or poly(3,4-ethylenedioxythiophene)/poly(styrene sulfonate) (PEDOT:PSS). In addition, alloys, combinations, and multilayers of these materials can be useful. In some OTFTs, the same material can provide the gate electrode function and also
20 provide the support function of the substrate. For example, doped silicon can function as the gate electrode and support the OTFT.

The gate dielectric is generally provided on the gate electrode. This gate dielectric electrically insulates the gate electrode from the balance of the OTFT device. Useful materials for the
25 gate dielectric can comprise, for example, an inorganic electrically insulating material.

The gate dielectric (insulator) can be a material, such as, an oxide, nitride, or it can be a material selected from the family of ferroelectric insulators (e.g. organic materials such as poly(vinylidene fluoride/trifluoroethylene or poly(m-xylylene adipamide)), or it can be an

30 organic polymeric insulator (e.g. poly(methacrylate)s, poly(acrylate)s, polyimides, benzocyclobutenes (BCBs), parylenes, polyvinylalcohol, polyvinylphenol (PVP), polystyrenes, polyester, polycarbonates) as for example described in J. Veres et al. Chem. Mat. 2004, 16, 4543 or A. Facchetti et al. Adv. Mat. 2005, 17, 1705. Specific examples of materials useful for the gate dielectric include strontiates, tantalates, titanates, zirconates,
35 aluminum oxides, silicon oxides, tantalum oxides, titanium oxides, silicon nitrides, barium titanate, barium strontium titanate, barium zirconate titanate, zinc selenide, and zinc

sulphide, including but not limited to $\text{PbZr}_x\text{Ti}_{1-x}\text{O}_3$ (PZT), $\text{Bi}_4\text{Ti}_3\text{O}_{12}$, BaMgF_4 , $\text{Ba}(\text{Zr}_{1-x}\text{Ti}_x)\text{O}_3$ (BZT). In addition, alloys, hybride materials (e.g. polysiloxanes or nanoparticle-filled polymers) combinations, and multilayers of these materials can be used for the gate dielectric. The thickness of the dielectric layer is, for example, from about 10 to 1000 nm, 5 with a more specific thickness being about 100 to 500 nm, providing a capacitance in the range of 0.1 – 100 nanofarads (nF).

The source electrode and drain electrode are separated from the gate electrode by the gate dielectric, while the organic semiconductor layer can be over or under the source electrode 10 and drain electrode. The source and drain electrodes can be any useful conductive material favourably providing a low resistance ohmic contact to the semiconductor layer. Useful materials include most of those materials described above for the gate electrode, for example, aluminum, barium, calcium, chromium, gold, silver, nickel, palladium, platinum, titanium, polyaniline, PEDOT:PSS, other conducting polymers, alloys thereof, combinations 15 thereof, and multilayers thereof. Some of these materials are appropriate for use with n-type semiconductor materials and others are appropriate for use with p-type semiconductor materials, as is known in the art.

The thin film electrodes (that is, the gate electrode, the source electrode, and the drain 20 electrode) can be provided by any useful means such as physical vapor deposition (for example, thermal evaporation or sputtering) or (ink jet) printing methods. The patterning of these electrodes can be accomplished by known methods such as shadow masking, additive photolithography, subtractive photolithography, printing, microcontact printing, and pattern coating.

25 The present invention further provides a thin film transistor device comprising a plurality of electrically conducting gate electrodes disposed on a substrate; a gate insulator layer disposed on said electrically conducting gate electrodes; a plurality of sets of electrically conductive source and drain electrodes disposed on said insulator layer such that each of said sets is in alignment with each of said gate electrodes; 30 an organic semiconductor layer disposed in the channel between source and drain electrodes on said insulator layer substantially overlapping said gate electrodes; wherein said organic semiconductor layer comprise a polymer of the formula I, or a mixture containing a polymer of formula I.

The present invention further provides a process for preparing a thin film transistor device comprising the steps of:

depositing a plurality of electrically conducting gate electrodes on a substrate;

depositing a gate insulator layer on said electrically conducting gate electrodes;

- 5 depositing a plurality of sets of electrically conductive source and drain electrodes on said layer such that each of said sets is in alignment with each of said gate electrodes;
- depositing a layer of a polymer of the formula I on said insulator layer such that said layer of the compound of formula I, or a mixture containing a polymer of formula I, substantially overlaps said gate electrodes; thereby producing the thin film transistor device.

10

A mixture containing a polymer of formula I results in a semi-conducting layer comprising a polymer of formula I (typically 5% to 99.9999% by weight, especially 20 to 85 % by weight) and at least another material. The other material can be, but is not restricted to a fraction of the same polymer of formula I with different molecular weight, another polymer of formula I, a semi-conducting polymer, organic small molecules, carbon nanotubes, a fullerene derivative, inorganic particles (quantum dots, quantum rods, quantum tripods, TiO₂, ZnO etc.), conductive particles (Au, Ag etc.), insulator materials like the ones described for the gate dielectric (PET, PS etc.).

20

For heterojunction solar cells the active layer comprises preferably a mixture of a polymer of formula I and a fullerene, such as [60]PCBM (= 6,6-phenyl-C61-butyric acid methyl ester), or [70]PCBM, in a weight ratio of 1:1 to 1:3.

25

Any suitable substrate can be used to prepare the thin films of the polymers of the present invention. Preferably, the substrate used to prepare the above thin films is a metal, silicon, plastic, paper, coated paper, fabric, glass or coated glass.

Alternatively, a TFT is fabricated by, for example, by solution deposition of a polymer on a highly doped silicon substrate covered with a thermally grown oxide layer followed by

30

vacuum deposition and patterning of source and drain electrodes.

In yet another approach, a TFT is fabricated by deposition of source and drain electrodes on a highly doped silicon substrate covered with a thermally grown oxide and then solution deposition of the polymer to form a thin film.

35

The gate electrode could also be a patterned metal gate electrode on a substrate or a conducting material such as, a conducting polymer, which is then coated with an insulator applied either by solution coating or by vacuum deposition on the patterned gate electrodes.

5 Any suitable solvent can be used to dissolve, and/or disperse the polymers of the present application, provided it is inert and can be removed partly, or completely from the substrate by conventional drying means (e.g. application of heat, reduced pressure, airflow etc.). Suitable organic solvents for processing the semiconductors of the invention include, but are not limited to, aromatic or aliphatic hydrocarbons, halogenated such as chlorinated or

10 fluorinated hydrocarbons, esters, ethers amides, such as chloroform, tetrachloroethane, , tetrahydrofuran, toluene, tetraline, anisole, xylene, ethyl acetate, methyl ethyl ketone, dimethyl formamide, dichlorobenzene, trichlorobenzene, propylene glycol monomethyl ether acetate (PGMEA) and mixtures thereof. The solution, and/or dispersion is then applied by a method, such as, spin-coating, dip-coating, screen printing, microcontact printing, doctor

15 blading or other solution application techniques known in the art on the substrate to obtain thin films of the semiconducting material.

The term "dispersion" covers any composition comprising the semiconductor material of the present invention, which is not fully dissolved in a solvent. The dispersion can be done

20 selecting a composition including at least a polymer of formula I, or a mixture containing a polymer of formula I, and a solvent, wherein the polymer exhibits lower solubility in the solvent at room temperature but exhibits greater solubility in the solvent at an elevated temperature, wherein the composition gels when the elevated temperature is lowered to a first lower temperature without agitation;

25 - dissolving at the elevated temperature at least a portion of the polymer in the solvent; lowering the temperature of the composition from the elevated temperature to the first lower temperature; agitating the composition to disrupt any gelling, wherein the agitating commences at any time prior to, simultaneous with, or subsequent to the lowering the elevated temperature of the composition to the first lower temperature; depositing a layer of

30 the composition wherein the composition is at a second lower temperature lower than the elevated temperature; and drying at least partially the layer.

The dispersion can also be constituted of (a) a continuous phase comprising a solvent, a binder resin, and optionally a dispersing agent, and (b) a disperse phase comprising a

35 polymer of formula I, or a mixture containing a polymer of formula I of the present invention.

The degree of solubility of the polymer of formula I in the solvent may vary for example from 0% to about 20% solubility, particularly from 0% to about 5% solubility.

Preferably, the thickness of the organic semiconductor layer is in the range of from about 5 to 5 about 1000 nm, especially the thickness is in the range of from about 10 to about 100 nm.

The polymers of the invention can be used alone or in combination as the organic semiconductor layer of the semiconductor device. The layer can be provided by any useful means, such as, for example, vapor deposition (for materials with relatively low molecular

10 weight) and printing techniques. The compounds of the invention may be sufficiently soluble in organic solvents and can be solution deposited and patterned (for example, by spin coating, dip coating, ink jet printing, gravure printing, flexo printing, offset printing, screen printing, microcontact (wave)-printing, drop or zone casting, or other known techniques).

15 The polymers of the invention can be used in integrated circuits comprising a plurality of OTFTs, as well as in various electronic articles. Such articles include, for example, radio-frequency identification (RFID) tags, backplanes for flexible displays (for use in, for example, personal computers, cell phones, or handheld devices), smart cards, memory devices, sensors (e.g. light-, image-, bio-, chemo-, mechanical- or temperature sensors), especially 20 photodiodes, or security devices and the like. Due to its ambi-polarity the material can also be used in Organic Light Emitting Transistors (OLET).

The invention provides organic photovoltaic (PV) devices (solar cells) comprising a polymer according to the present invention.

25 The PV device comprise in this order:

- (a) a cathode (electrode),
- (b) optionally a transition layer, such as an alkali halogenide, especially lithium fluoride,
- (c) a photoactive layer,
- 30 (d) optionally a smoothing layer,
- (e) an anode (electrode),
- (f) a substrate.

The photoactive layer comprises the polymers of the present invention. Preferably, the

35 photoactive layer is made of a conjugated polymer of the present invention, as an electron

donor and an acceptor material, like a fullerene, particularly a functionalized fullerene PCBM, as an electron acceptor.

The fullerenes useful in this invention may have a broad range of sizes (number of carbon

5 atoms per molecule). The term fullerene as used herein includes various cage-like molecules of pure carbon, including Buckminsterfullerene (C_{60}) and the related "spherical" fullerenes as well as carbon nanotubes. Fullerenes may be selected from those known in the art ranging from, for example, C_{20} - C_{1000} . Preferably, the fullerene is selected from the range of C_{60} to C_{96} . Most preferably the fullerene is C_{60} or C_{70} , such as [60]PCBM, or [70]PCBM. It is also
10 permissible to utilize chemically modified fullerenes, provided that the modified fullerene retains acceptor-type and electron mobility characteristics. The acceptor material can also be a material selected from the group consisting of another polymer of formula I or any semi-conducting polymer provided that the polymers retain acceptor-type and electron mobility characteristics, organic small molecules, carbon nanotubes, inorganic particles (quantum
15 dots, quantum rods, quantum tripods, TiO_2 , ZnO etc.).

The electrodes are preferably composed of metals or "metal substitutes". Herein the term

"metal" is used to embrace both materials composed of an elementally pure metal, e.g., Mg, and also metal alloys which are materials composed of two or more elementally pure metals,

20 e.g., Mg and Ag together, denoted Mg:Ag. Here, the term "metal substitute" refers to a material that is not a metal within the normal definition, but which has the metal-like properties that are desired in certain appropriate applications. Commonly used metal substitutes for electrodes and charge transfer layers would include doped wide-bandgap semiconductors, for example, transparent conducting oxides such as indium tin oxide (ITO),

25 gallium indium tin oxide (GITO), and zinc indium tin oxide (ZITO). Another suitable metal substitute is the transparent conductive polymer polyaniline (PANI) and its chemical relatives, or PEDOT:PSS. Metal substitutes may be further selected from a wide range of

non-metallic materials, wherein the term "non-metallic" is meant to embrace a wide range of materials provided that the material is free of metal in its chemically uncombined form. Highly
30 transparent, non-metallic, low resistance cathodes or highly efficient, low resistance

metallic/non-metallic compound cathodes are, for example, disclosed in US-B-6,420,031 and US-B-5,703,436.

The substrate can be, for example, a plastic (flexible substrate), or glass substrate.

In another preferred embodiment of the invention, a smoothing layer is situated between the anode and the photoactive layer. A preferred material for this smoothing layer comprises a film of 3,4-polyethylenedioxythiophene (PEDOT), or 3,4-polyethylenedioxythiophene:polystyrene-sulfonate (PEDOT:PSS).

5

In a preferred embodiment of the present invention, the photovoltaic cell comprises, as described for example, in US-B-6,933,436 a transparent glass carrier, onto which an electrode layer made of indium/tin oxide (ITO) is applied. This electrode layer generally has a comparatively rough surface structure, so that it is covered with a smoothing layer made of a polymer, typically PEDOT, which is made electrically conductive through doping. The photoactive layer is made of two components, has a layer thickness of, for example, 100 nm to a few μm depending on the application method, and is applied onto this smoothing layer. Photoactive layer is made of a conjugated polymer of the present invention, as an electron donor and a fullerene, particularly functionalized fullerene PCBM, as an electron acceptor.

10 These two components are mixed with a solvent and applied as a solution onto the smoothing layer by, for example, the spin-coating method, the casting method, the Langmuir-Blodgett ("LB") method, the ink jet printing method and the dripping method. A squeegee or printing method could also be used to coat larger surfaces with such a photoactive layer. Instead of toluene, which is typical, a dispersion agent such as chlorobenzene is preferably 15 used as a solvent. Among these methods, the vacuum deposition method, the spin-coating method, the ink jet printing method and the casting method are particularly preferred in view of ease of operation and cost.

20 In the case of forming the layer by using the spin-coating method, the casting method and ink jet printing method, the coating can be carried out using a solution and/or dispersion prepared by dissolving, or dispersing the composition in a concentration of from 0.01 to 90% by weight in an appropriate organic solvent such as benzene, toluene, xylene, tetrahydrofuran, methyltetrahydrofuran, N,N-dimethylformamide, acetone, acetonitrile, anisole, dichloromethane, dimethylsulfoxide, chlorobenzene, 1,2-dichlorobenzene and 25 mixtures thereof.

30 Before a counter electrode is applied, a thin transition layer, which must be electrically insulating, having a layer thickness of, for example, 0.6 nm, is applied to photoactive layer 4. In this exemplary embodiment, this transition layer is made of an alkali halogenide, namely a lithium fluoride, which is vapor deposited in a vacuum of $2 \cdot 10^{-6}$ torr at a rate of 0.2 35 nm/minute.

If ITO is used as a hole-collecting electrode, aluminum, which is vapor deposited onto the electrically insulating transition layer, is used as an electron-collecting electrode. The electric insulation properties of the transition layer obviously prevent influences which hinder the 5 crossing of the charge carrier from being effective, particularly in the transition region from the photoactive layer to the transition layer.

In a further embodiment on the invention, one or more of the layers may be treated with 10 plasma prior to depositing the next layer. It is particularly advantageous that the PEDOT:PSS layer be subject to a mild plasma treatment prior to deposition of the next layer.

The photovoltaic (PV) device can also consist of multiple junction solar cells that are processed on top of each other in order to absorb more of the solar spectrum. Such 15 structures are, for example, described in App. Phys. Let. **90**, 143512 (2007), Adv. Funct. Mater. **16**, 1897–1903 (2006) and WO2004/112161.

A so called 'tandem solar cell' comprise in this order:

- (a) a cathode (electrode),
- (b) optionally a transition layer, such as an alkali halogenide, especially lithium fluoride,
- 20 (c) a photoactive layer,
- (d) optionally a smoothing layer,
- (e) a middle electrode (such as Au, Al, ZnO, TiO₂ etc.)
- (f) optionally an extra electrode to match the energy level,
- (g) optionally a transition layer, such as an alkali halogenide, especially lithium fluoride,
- 25 (h) a photoactive layer,
- (i) optionally a smoothing layer,
- (j) an anode (electrode),
- (k) a substrate.

30 The PV device can also be processed on a fiber as described, for example, in US20070079867 and US 20060013549.

Due to their excellent self-organising properties the inventive compounds, materials or films 35 can also be used alone or together with other materials in or as alignment layers in LCD or OLED devices, as described for example in US2003/0021913.

The following examples are included for illustrative purposes only and do not limit the scope of the claims. Unless otherwise stated, all parts and percentages are by weight.

Weight-average molecular weight (M_w) and polydispersity ($M_w/M_n = PD$) are determined by Gel Permeation Chromatography (GPC) Apparatus: **GPC_{max} + TDA 302** from Viscotek

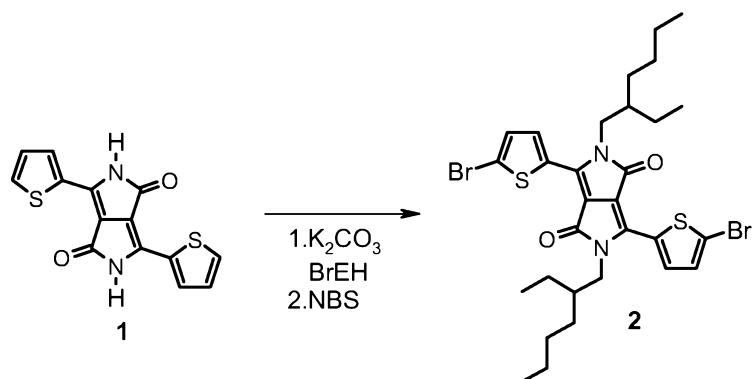
5 (Houston, TX, USA) yielding the responses form refractive index (RI), low angle light scattering (LALS), right angle light scattering (RALS) and differential viscosity (DP) measurements. Chromatographic conditions: Column: PL_{gel} mixed C (300 x 7.5 mm, 5 μ m particles) covering the molecular weight range from about 1×10^3 to about 2.5×10^6 Da from Polymer Laboratories (Church Stretton, UK); Mobile phase: tetrahydrofuran containing 5 g/l 10 of sodium trifluoroacetate; Mobile phase flow: either 0.5 or 0.7 ml/min; Solute concentration: about 1-2 mg/ml; Injection volume: 100 μ l; Detection: RI, LALS, RALS, DP. Procedure of 15 molecular weight calibration: **Relative calibration** is done by use of a set of 10 polystyrene calibration standards obtained from Polymer Laboratories (Church Stretton, UK) spanning the molecular weight range from 1'930'000 Da - 5'050 Da, i. e., PS 1'930'000, PS 1'460'000, PS 1'075'000, PS 560'000, PS 330'000, PS 96'000, PS 52'000, PS 30'300, PS 10'100, PS 20 5'050 Da. **Absolute calibration** is done on the base of the responses of LALS, RALS and DP. As experienced in a large number of investigations this combination provides optimum calculation of molecular weight data. Usually PS 96'000 is used as the molecular weight calibration standard, but in general every other PS standard lying in the molecular weight range to be determined can be chosen for this purpose.

All polymer structures given in the examples below are idealized representations of the polymer products obtained via the polymerization procedures described. If more than two components are copolymerized with each other sequences in the polymers can be either alternating or random depending on the polymerisation conditions.

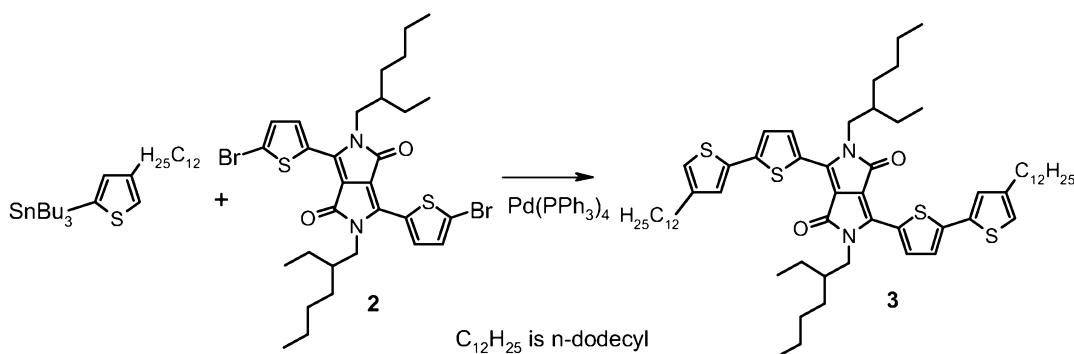
25

Examples

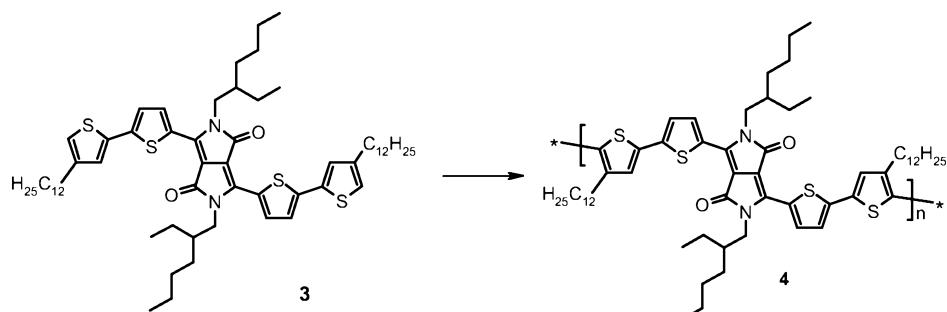
Example 1



a) A solution of 4.5 g of DPP **1**, 6.23 g of K_2CO_3 and 8.68 g of 1-bromo-2-ethyl-hexyl in 60 ml of N-methyl-pyrrolidone (NMP) is heated to 140°C for 6h. The mixture is washed with water and extracted with dichloromethane. The organic phase is then dried and filtered on a double layer of silica gel and Hyflo® (CAS 91053-39-3; Fluka 56678) before it is concentrated. The residue is dissolved in 100 ml of chloroform, cooled down to 0°C and 2 equivalents of N-bromosuccinimide are then added portion wise over a period of 1h. After the reaction has been completed, the mixture is washed with water. The organic phase is extracted, dried and concentrated. The compound is then purified over a silica gel column to give 1.90 g of a violet powder of DPP **2**.



10 b) A solution of 500 mg of the dibrominated DPP **2**, 990 mg of the tin derivative and 85 mg of Pd(PPh₃)₄ in 30 ml of dry toluene is refluxed overnight under inert conditions. After cooling down, the mixture is filtrated on a double layer silica gel/Hyflo®, concentrated and precipitated with methanol. The precipitate is filtrated and rinsed with methanol to give 530 mg of a blue solid of DPP **3**.



15 c) A solution of 2.55 g of the corresponding monomer **3** in chlorobenzene is degassed with argon over 15 min at 50°C. Then 1.6 g of FeCl_3 are added in nitromethane and the mixture is stirred while degassing for 4 hours at 50°C. The solution is then poured into methanol and the blue precipitate is then filtrated and washed with methanol. The solid is then purified by soxhlet extraction, using methanol and hexane to purify and chloroform to extract 2 g of the polymer fraction (**4**).

$$M_w = 13301$$

Fe content = 75 ppm

Photophysical properties:

UV spectra of spin coated films on glass substrates are made from hot chlorobenzene solutions and annealed at different temperatures:

Annealing Conditions	UV/Vis-absorption
Room temperature	680 nm
20 minutes at 100 °C	720 nm, 800 nm
20 minutes at 150 °C	720 nm, 800 nm

Growing of the band at 800 nm shows the appearance of strong aggregation behaviour while

5 annealing.

Application Example 1a - DPP-polymers based Field-Effect Transistors**a) Experimental:**

Bottom-gate thin-film transistor (TFT) structures with *p*-Si gate were used for all experiments.

10 A high-quality thermal SiO₂ layer served as gate-insulator of $C_i = 32.6 \text{ nF/cm}^2$ capacitance per unit area. Source and drain electrodes were patterned by photolithography directly on the gate-oxide (bottom-contact configuration). On each substrate 16 transistors are present with Au source/drain electrodes defining channels of different length. Prior to the deposition of the organic semiconductor the SiO₂ surface was derivatized with hexamethyldisilazane (HMDS)

15 or octadecyltrichlorosilane (OTS). The films are prepared either by spin casting or drop casting the polymer obtained in example 1 in different solvents. The transistor behaviour is measured on an automated tester elaborated by CSEM, Transistor Prober TP-10.

b) Transistor performance:

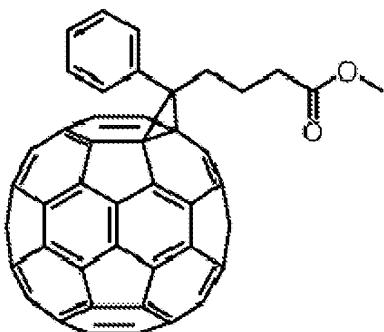
The thin-film transistors showed clear p-type transistor behavior. From a linear fit to the square root of the saturated transfer characteristics a field-effect mobility of $0.15 \text{ cm}^2/\text{Vs}$ could be determined. The transistors showed a threshold voltage of about 0 V to 5 V. The transistors showed good on/off current ratios of 10^4 to 10^7 .

Annealing of the sample results in a drastic increase of the performances (especially mobility), which can be correlated to a better aggregation of the polymer in the solid state.

25 Testing of a set of OFETs after 2 months exposed in air conditions shows remarkable stability as the mobility is almost constant. The on/off ratio, which usually suffers the most, is only reduced by a factor of 10.

Application Example 1b**30 DPP-polymer based bulk heterojunction solar cell****a) Experimental:**

The solar cell has the following structure: Al electrode/LiF layer/organic layer, including polymer of the invention/[poly(3,4-ethylenedioxy-thiophene) (PEDOT)/ poly(styrenesulfonic acid) (PSS)]/ITO electrode/glass substrate. The solar cells are made by spin-coating a layer of PEDOT-PSS on a pre-patterned ITO on glass substrate. Then a 1:4 mixture of the 5 polymer of example 1 (0.5 % by weight) : [60]PCBM (a substituted C₆₀ fullerene):

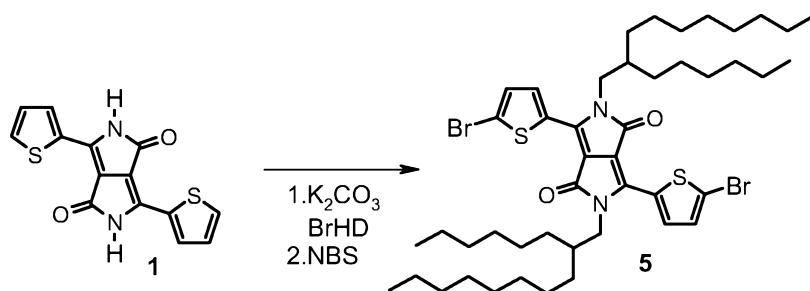


) is spin coated (organic layer). LiF and Al are sublimed under high vacuum through a shadow-mask.

b) Solar cell performance:

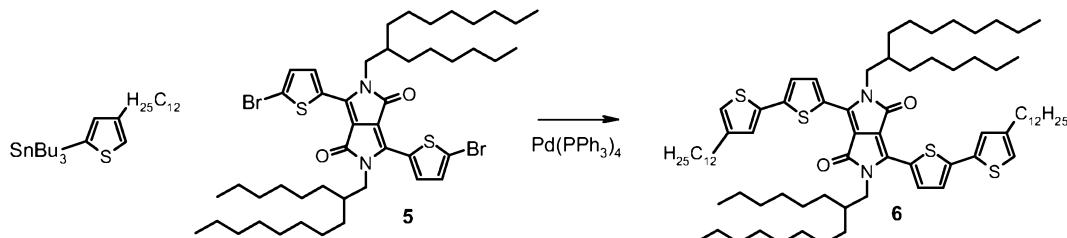
The solar cell is measured under a solar light simulator. Then with the External Quantum 10 Efficiency (EQE) graph the current is estimated under AM1.5 conditions. This leads to value of $J_{sc} = 4.1\text{mA/cm}^2$, FF = 0.539 and $V_{oc} = 0.733\text{ V}$ for an estimated overall efficiency of 1.62 % measured before annealing. After 10 min at 100°C the estimated efficiency grows to 2 %. After optimisation of the morphology of the active layer by varying the deposition solvent, the polymer/[60]PCBM ratio etc. the performance of the device can be 15 pushed up to 3.06 % ($J_{sc} = 9.5\text{mA/cm}^2$, FF = 0.46 and $V_{oc} = 0.7\text{ V}$).

Example 2

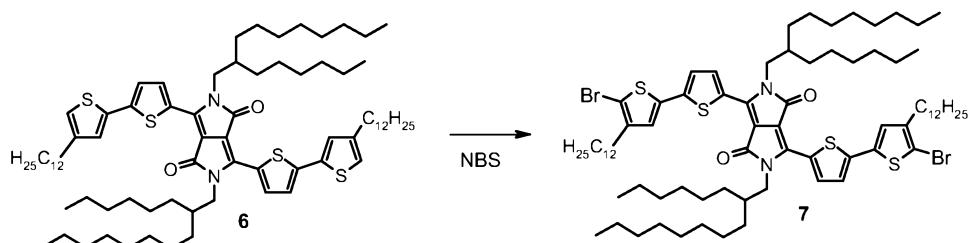


A solution of 25 g of DPP 1, 46.07 g of K_2CO_3 and 75 g of 1-bromo-2-hexyl-decyl in 300 ml of N-methyl-pyrrolidone (NMP) is heated to 140°C for 6h. The mixture is washed with water and 20 extracted with dichloromethane. The organic phase is then dried and filtered on a double layer of silica gel and Hyflo® before it is concentrated. The residue is dissolved in 100 ml of chloroform, cooled down to 0°C and 2 equivalents of N-bromosuccinimide are then added portion wise over a period of 1h. After the reaction has been completed, the mixture is washed with water. The

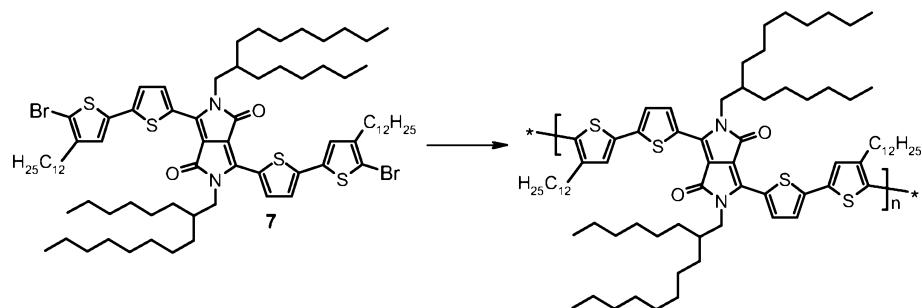
organic phase is extracted, dried and concentrated. The compound is then purified over a silica gel column to give 19 g of a violet powder of DPP **5**.



b) A solution of 18.5 g of the dibrominated DPP **5**, 27.47 g of the tin derivative and 2.36 g of 5 Pd(PPh₃)₄ in 250ml of dry toluene is refluxed overnight under inert conditions. After cooling down, the mixture is purified on a silica gel column (CHCl₃/hexane 3/7) to give 20.2 g of a blue solid of DPP **6**.



c) A solution of 10 g of the DPP derivative **6** is dissolved in 300 ml of chloroform, cooled down to 10 0°C and 2 equivalents of N-bromosuccinimide are then added portion wise over a period of 1h. After the reaction is completed, the mixture is washed with water. The organic phase is extracted, dried, concentrated and precipitated with methanol. The precipitate is filtrated and rinsed with methanol to give 10 g of a blue solid of DPP **7**.



15 In a shlenk tube, a solution of 240 mg of Ni(COD)₂ and 140 mg bipyridine in 10 ml of toluene is degassed for 15 min. 1 g of the corresponding dibrominated monomer **7** is added to this solution and then the mixture is heated to 80°C and stirred vigorously overnight. The solution is poured on 100 ml of a 1/1/1 methanol / HCl / acetone mixture and stirred for 1h. The precipitate is then filtrated, dissolved in CHCl₃ and stirred vigorously at 60°C with an aqueous 20 solution of ethylenediaminetetraacetic acid (EDTA) tetrasodium salt for one additional hour. The organic phase is washed with water, concentrated and precipitated in methanol. The

residue is purified by soxhlet extraction using methanol and hexane and the polymer is then extracted with CHCl_3 to give 250 mg of purple fibres.

$M_w = 77465$

Ni content = 65 ppm

5 Solubility > 10% by weight in toluene

Photophysical properties :

UV of spin coated film on glass substrate is made from a hot chlorobenzene solution and annealed at different temperatures:

Annealing Conditions	UV/Vis-absorption
Room temperature	680 nm
20 minutes at 100 °C	720 nm, 800 nm

Growing of the band at 800 nm shows the appearance of strong aggregation behaviour while

10 annealing.

Application Example 2a - DPP-polymers based Field-Effect Transistors

a) Experimental:

Application Example 1a is repeated, except that instead of the polymer obtained in example 1 the polymer obtained in example 2 is used.

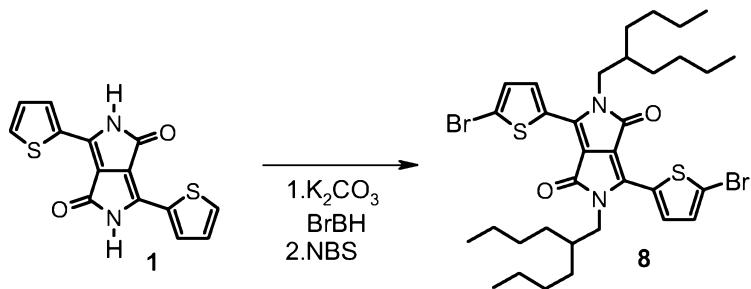
b) Transistor performance:

The thin-film transistors showed clear p-type transistor behavior. From a linear fit to the square root of the saturated transfer characteristics a field-effect mobility up to $0.013 \text{ cm}^2/\text{Vs}$ could be determined. The transistors showed a threshold voltage of about 0 V to 4 V. The

20 transistors showed good on/off current ratios of 10^5 to 10^7 . Testing of a set of OFETs after 7 days exposed in air conditions shows remarkable stability as the mobility is almost constant even better, on/off ratio which usually suffers the most is only reduced by a factor of 5.

This compound shows an electron mobility up to $10^{-3} \text{ cm}^2/\text{Vs}$ on the normal setup. After optimisation of this setup using top contact transistors, the ambi-polarity of this polymer is even more pronounced with similar mobilities for holes and electrons up to $0.1 \text{ cm}^2/\text{Vs}$.

Example 3



a) A solution of 25 g of DPP 1, 46.07 g of K_2CO_3 and 55 g of 1-bromo-2-butyl-hexyl in 300 ml of N-methyl-pyrrolidone (NMP) is heated to 140°C for 6h. The mixture is washed with water and extracted with dichloromethane. The organic phase is then dried and filtered on a double layer of silica gel and Hyflo® before it is concentrated. The residue is dissolved in 100 ml of chloroform, cooled down to 0°C and 2 equivalents of N-bromosuccinimide are then added portion wise over a period of 1h. After the reaction has been completed, the mixture is washed with water. The organic phase is extracted, dried and concentrated. The compound is then purified over a silica gel column to give 9.5 g of a violet powder of DPP 8.

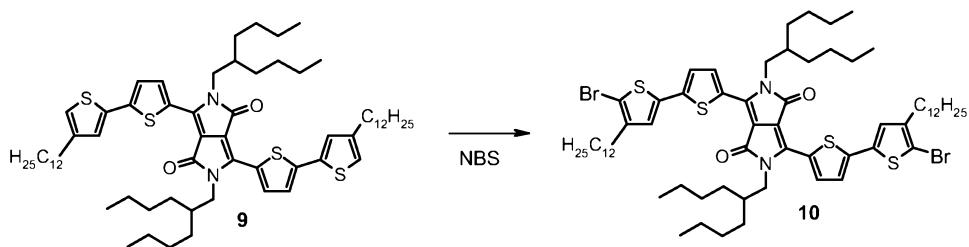
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10

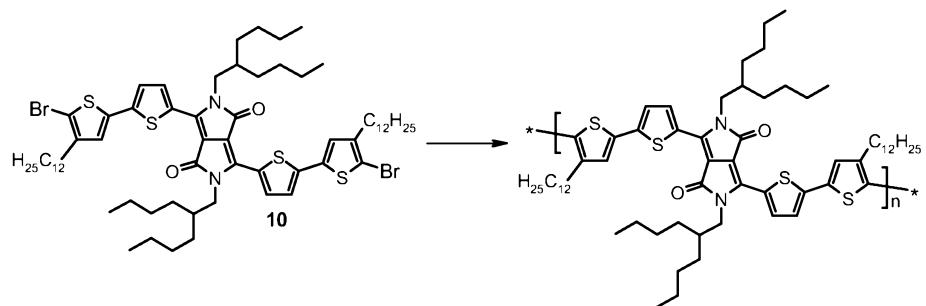
b) A solution of 2.24 g of the dibrominated DPP 8, 4.11 g of the tin derivative and 351 mg of $Pd(PPh_3)_4$ in 50ml of dry toluene is refluxed overnight under inert conditions. After cooling down, the mixture is purified on a silica gel column ($CHCl_3$ /hexane 3/7) to give 2.37 g of a blue solid of DPP 9.

15

20



c) A solution of 1.27 g of the DPP derivative 9 is dissolved in 60 ml of chloroform, cooled down to 0°C and 2 equivalents of N-bromosuccinimide are then added portion wise over a period of 1h. After the reaction is completed, the mixture is washed with water. The organic phase is extracted, dried, concentrated and precipitated with methanol. The precipitate is filtrated and rinsed with methanol to give 1.32 g of a blue solid of DPP 10.



d) In a Schlenk tube, a solution of 244 mg of Ni(COD)₂ and 142 mg bipyridine in 10 ml of toluene is degassed for 15 min. 1 g of the corresponding dibrominated monomer **10** is added to this solution and then the mixture is heated to 80°C and stirred vigorously overnight. The

5 solution is poured on 100 ml of a 1/1/1 methanol / HCl / acetone mixture and stirred for 1h. The precipitate is then filtrated, dissolved in CHCl₃ and stirred vigorously at 60°C with an aqueous solution of ethylenediaminetetraacetic acid (EDTA) tetrasodium salt for one additional hour. The organic phase is washed with water, concentrated and precipitated in methanol. The residue is purified by soxhlet extraction using methanol and hexane and the

10 polymer is then extracted with CHCl₃ to give 650 mg of purple fibres.

M_w = 30000

Ni content = 52 ppm

Solubility = 0.5% by weight in CHCl₃

Photophysical properties :

15 UV of spin coated film on glass substrate is made from a hot chlorobenzene solution and annealed at different temperatures:

Annealing Conditions	UV/Vis-absorption
Room temperature	720 nm, 810 nm

The band at 810 nm is attributed to the aggregation behaviour.

Application Example 3 - DPP-polymers based Field-Effect Transistors

20 **a) Experimental:**

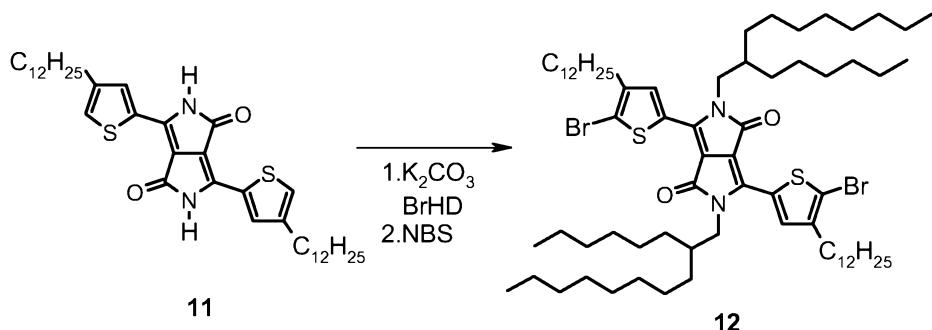
Application Example 1a is repeated, except that instead of the polymer obtained in example 1 the polymer obtained in example 3 is used.

b) Transistor performance:

The thin-film transistors showed clear p-type transistor behaviour. From a linear fit to the

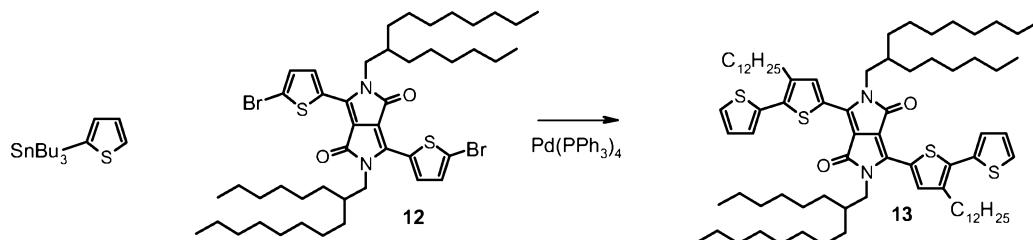
25 square root of the saturated transfer characteristics a field-effect mobility up to 0.1 cm²/Vs could be determined. The transistors showed a threshold voltage of about 6 V. The transistors showed good on/off current ratios of 10⁴ to 10⁵.

Example 4



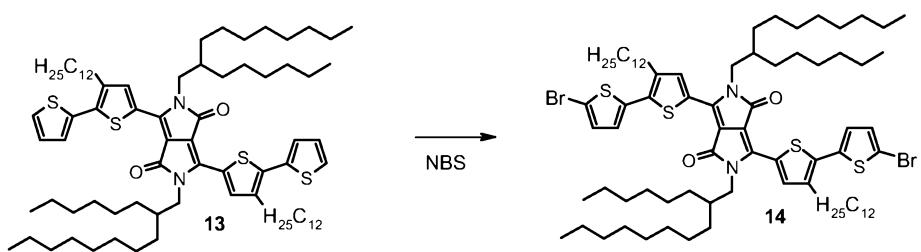
a) A solution of 3.5 g of DPP **11**, 3.04 g of K_2CO_3 and 4.13 g of 1-bromo-2-hexyl-decyl in 60 ml of N-methyl-pyrrolidone (NMP) is heated to 140°C for 6h. The mixture is washed with water and extracted with dichloromethane. The organic phase is then dried and filtered on a double layer of

5 silica gel and Hyflo® before it is concentrated. The residue is dissolved in 100 ml of chloroform, cooled down to 0°C and 2 equivalents of N-bromosuccinimide are then added portion wise over a period of 1h. After the reaction has been completed, the mixture is washed with water. The organic phase is extracted, dried and concentrated. The compound is then purified over a silica 10 gel column to give 1.7 g of a violet powder of DPP **12**.



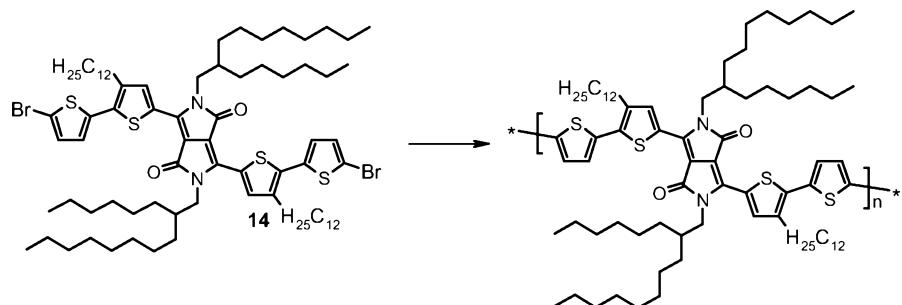
b) A solution of 1.6 g of the dibrominated DPP **12**, 0.65 g of the tin derivative and 150 mg of $Pd(PPh_3)_4$ in 60ml of dry toluene is refluxed overnight under inert conditions. After cooling down, the mixture is purified on a silica gel column ($CHCl_3$ /hexane 3/7) to give 1.27 g of a blue solid of

15 DPP **13**.



c) A solution of 1.27 g of the DPP derivative **13** is dissolved in 50 ml of chloroform, cooled down to 0°C and 2 equivalents of N-bromosuccinimide are then added portion wise over a period of 1h. After the reaction is completed, the mixture is washed with water. The organic phase is

extracted, dried, concentrated and precipitated with methanol. The precipitate is filtrated and rinsed with methanol to give 1.22 g of a blue solid of DPP **14**.



d) In a Schlenk tube, a solution of 292 mg of $\text{Ni}(\text{COD})_2$ and 170 mg bipyridine in 10 ml toluene is degassed for 15 min. 1.2 g of the corresponding dibrominated monomer **14** is added to this solution and then the mixture is heated to 65°C and stirred vigorously for 41h. The solution is poured on 100 ml of a 1/1/1 methanol / HCl / acetone mixture and stirred for 1h. The precipitate is then filtrated, dissolved in CHCl_3 and stirred vigorously at 60°C with an aqueous solution of ethylenediaminetetraacetic acid (EDTA) tetrasodium salt for one additional hour. The organic phase is washed with water, concentrated and precipitated in methanol. The residue is purified by soxhlet extraction using methanol and hexane and the polymer is then extracted with CHCl_3 to give 730 mg of purple fibres.

$$M_w = 30000$$

Ni content = 14 ppm

15 Solubility = 0.5% by weight in CHCl_3

Photophysical properties:

UV of spin coated film on glass substrate is made from a hot chlorobenzene solution and annealed at different temperatures:

Annealing Conditions	UV/Vis-absorption
Room temperature	720 nm, 800 nm

The band at 800 nm is attributed to the aggregation behaviour.

20

Application Example 4 - DPP-polymers based Field-Effect Transistors

a) Experimental:

Application Example 1a is repeated, except that instead of the polymer obtained in example 1 the polymer obtained in example 4 is used.

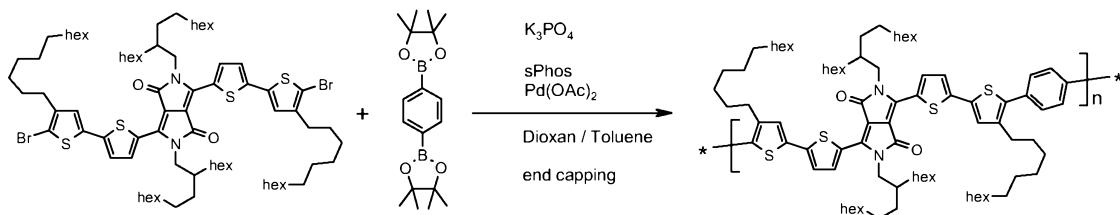
25 b) Transistor performance:

The thin-film transistors showed clear p-type transistor behaviour. From a linear fit to the square root of the saturated transfer characteristics a field-effect mobility up to $0.013 \text{ cm}^2/\text{Vs}$ could be determined. The transistors showed a threshold voltage of about 4 V to 8 V. The

transistors showed good on/off current ratios of 10^4 to 10^5 . Testing of a set of OFETs after 2 months exposed in air conditions shows remarkable stability as the mobility is even better (up to $0.028 \text{ cm}^2/\text{Vs}$), on/off ratio which usually suffer the most is also increased by a factor of 5 to 10 and threshold voltage in the range of 0 V to 4 V.

5

Example 5



In a three neck-flask, a degassed solution of 5 g of 7, 1.185 g of 1,4-benzenediboronic acid bis(pinacol) ester, 3.773 g of K_3PO_4 , 88.5 mg of sPhos (2-dicyclohexylphosphino-2',6'-dimethoxyphenylbiphenyl) and 80.6 mg of palladium acetate in 60 ml of toluene, 20 ml of dioxane and 10 ml of water are heated to 90°C and stirred vigorously overnight. An excess of bromobenzene is then added and after 2 hours at the same temperature an excess of phenylboronic acid pinacol ester is then added to end cap the polymer. After 2 hours to complete the end-capping, 100mL of NaCN (1% by weight) in water is added and the mixture is stirred at 90°C for 3 hours. The organic phase is extracted and precipitated in methanol. The residue is redissolved in toluene and resubmitted to NaCN treatment and the organic phase is precipitated in methanol. The residue is purified by soxhlet extraction using acetone and Et_2O and the polymer is then extracted with CHCl_3 to give 2.5 g of purple fibres.

$M_w = 27000$

20 Pd content = 30 ppm

Solubility = 1% by weight in CHCl_3

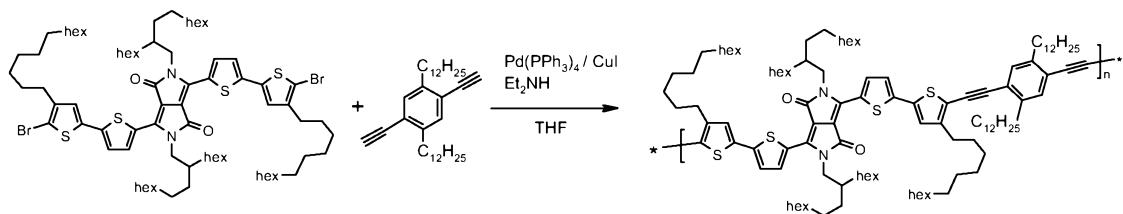
Photophysical properties:

UV of spin coated film on glass substrate is made from a hot chlorobenzene solution and annealed at different temperatures:

Annealing Conditions	UV/Vis-absorption
Room temperature	630 nm, 680 nm

25 The band at 680 nm is attributed to the aggregation behaviour.

Example 6



1g of **7**, 82 mg of $\text{Pd}(\text{PPh}_3)_4$ (10mol%) and 13.5 mg of copper iodide (10mol%) are dissolved in diethylamine, (0.85ml) and THF (2ml) in a dry, nitrogen flushed flask. The flask is then set under vacuum, flushed with nitrogen, this is repeated three times. 328 mg of the diacetylenique derivative is then added, the flask is sealed under nitrogen, heated up to 85°C and stirred over night. The reaction mixture is dissolved in 50 ml CHCl_3 , triturated in 500 ml MeOH, and filtrated. This action is repeated once. The solid is then purified via soxhlet extraction using MeOH, acetone and heptane and the polymer is then extracted with CHCl_3 to give 0.5 g of purple fibres.

10 $M_w = 38000$

Solubility = 0.5% by weight in CHCl_3

Photophysical properties:

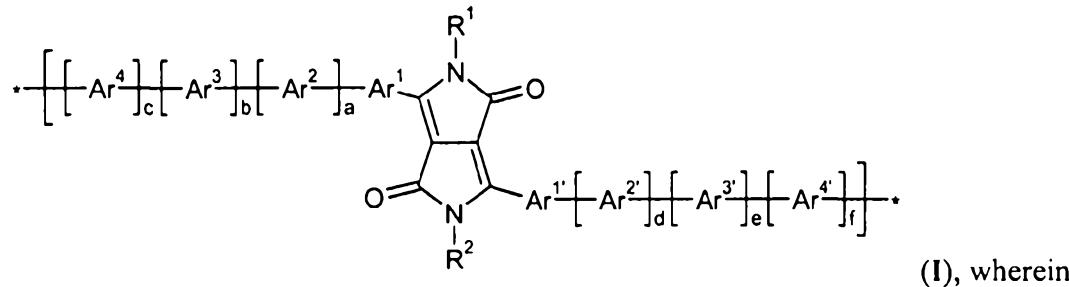
UV of spin coated film on glass substrate is made from a hot chlorobenzene solution and annealed at different temperatures:

Annealing Conditions	UV/Vis-absorption
Room temperature	650 nm, 700 nm

15 The band at 700 nm is attributed to the aggregation behaviour.

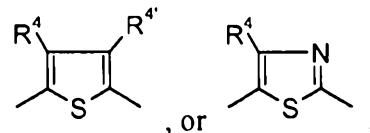
The claims defining the invention are as follows:

1. A polymer comprising (repeating) unit(s) of the formula

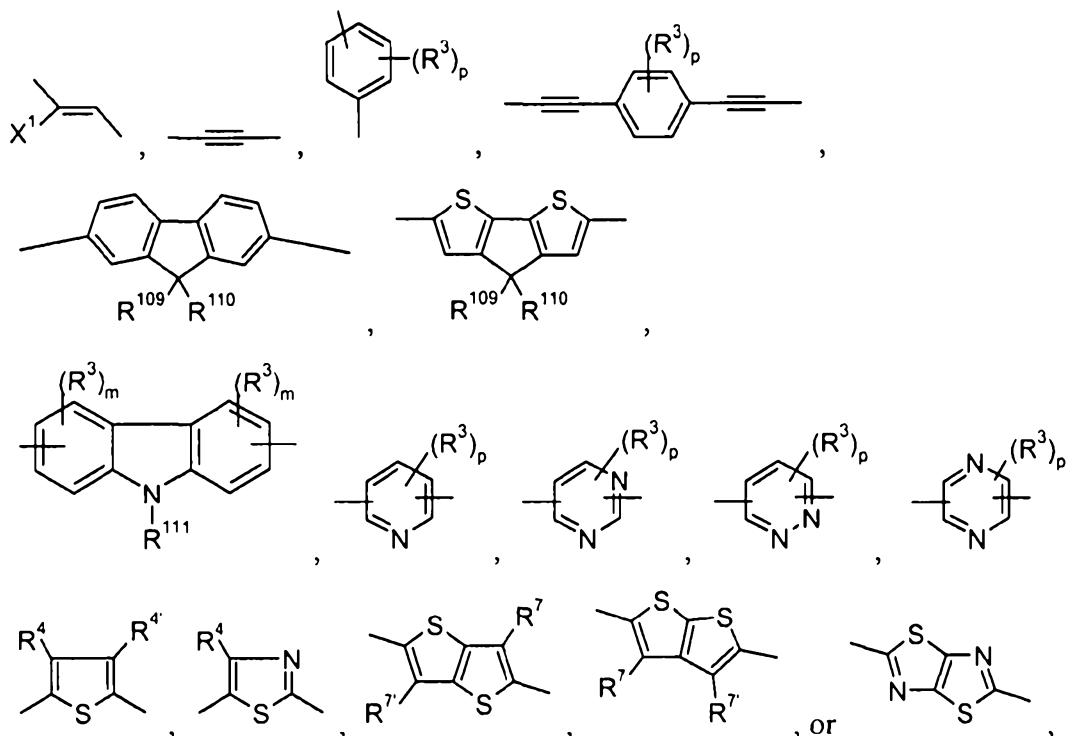


5 a, b, c, d, e and f are 0, 1, 2, or 3;

Ar^1 and Ar'^1 are independently of each other a group of formula



Ar^2 , Ar^2' , Ar^3 , Ar^3' , Ar^4 and Ar^4' are independently of each other a group of formula



p stands for 0, 1, 2, 3 or 4, if possible,

R^1 and R^2 may be the same or different and are selected from hydrogen, a C_1 - C_{25} alkyl

15 group, an alkenyl group, an alkynyl group, which may optionally be substituted by E and/or interrupted by D, an allyl group, which can be substituted one to three times with

5 C₁-C₄alkyl; a cycloalkyl group, which can be substituted one to three times with C₁-C₈alkyl, C₁-C₈thioalkoxy, or C₁-C₈alkoxy, or a cycloalkyl group, which can be condensed one or two times by phenyl, which can be substituted one to three times with C₁-C₄-alkyl, halogen, nitro or cyano; a cycloalkenyl group, a ketone or aldehyde group, an ester group, a carbamoyl group, a silyl group, a siloxanyl group, Ar¹⁰ or -CR⁵R⁶-(CH₂)_g-Ar¹⁰, wherein

10 R⁵ and R⁶ independently from each other stand for hydrogen, fluorine, cyano or C₁-C₄alkyl, which can be substituted by fluorine, chlorine or bromine, or phenyl, which can be substituted one to three times with C₁-C₄alkyl,

15 Ar¹⁰ stands for aryl or heteroaryl, which may optionally be substituted by G, in particular phenyl or 1- or 2-naphthyl which can be substituted one to three times with C₁-C₈alkyl, C₁-C₈thioalkoxy, and/or C₁-C₈alkoxy, and g stands for 0, 1, 2, 3 or 4, R³ may be the same or different within one group and is selected from C₁-C₂₅alkyl, which may optionally be substituted by E and/or interrupted by D, C₆-C₂₄aryl, which may optionally be substituted by G, C₂-C₂₀heteroaryl, which may optionally be substituted by G, C₁-C₁₈alkoxy, which may optionally be substituted by E and/or interrupted by D, C₇-C₂₅aralkyl, wherein ar (=aryl) of aralkyl may optionally be substituted by G, or -CO-R²⁸, or two or more groups R³ which are in the neighbourhood to each other, form a ring;

20 R⁴, R^{4'}, R⁷ and R^{7'} independently from each other stand for hydrogen, C₁-C₂₅alkyl, which may optionally be substituted by E and/or interrupted by D, C₆-C₂₄aryl, which may optionally be substituted by G, C₂-C₂₀heteroaryl, which may optionally be substituted by G, C₁-C₁₈alkoxy, which may optionally be substituted by E and/or interrupted by D, C₇-C₂₅aralkyl, wherein ar (=aryl) of aralkyl may optionally be substituted by G, or -CO-R²⁸; or R⁴ and R^{4'} form a ring;

25 D is -CO-; -COO-; -S-; -SO-; -SO₂-; -O-; -NR²⁵-; -CR²³=CR²⁴-; or -C≡C-; and E is -OR²⁹; -SR²⁹; -NR²⁵R²⁶; -COR²⁸; -COOR²⁷; -CONR²⁵R²⁶; -CN; or halogen; G is E, C₁-C₁₈alkyl, which may be interrupted by D, or C₁-C₁₈alkoxy which is substituted by E and/or interrupted by D, wherein

30 R²³, R²⁴, R²⁵ and R²⁶ are independently of each other H; C₆-C₁₈aryl; C₆-C₁₈aryl which is substituted by C₁-C₁₈alkyl, or C₁-C₁₈alkoxy; C₁-C₁₈alkyl; or C₁-C₁₈alkyl which is interrupted by -O-;

R^{27} and R^{28} are independently of each other H; $C_6\text{-}C_{18}\text{aryl}$; $C_6\text{-}C_{18}\text{aryl}$ which is substituted by $C_1\text{-}C_{18}\text{alkyl}$, or $C_1\text{-}C_{18}\text{alkoxy}$; $C_1\text{-}C_{18}\text{alkyl}$; or $C_1\text{-}C_{18}\text{alkyl}$ which is interrupted by $-\text{O}-$,

R^{29} is H; $C_6\text{-}C_{18}\text{aryl}$; $C_6\text{-}C_{18}\text{aryl}$, which is substituted by $C_1\text{-}C_{18}\text{alkyl}$, or $C_1\text{-}C_{18}\text{alkoxy}$; $C_1\text{-}C_{18}\text{alkyl}$; or $C_1\text{-}C_{18}\text{alkyl}$ which is interrupted by $-\text{O}-$,

R^{109} and R^{110} are independently of each other H, $C_1\text{-}C_{18}\text{alkyl}$, $C_1\text{-}C_{18}\text{alkyl}$ which is substituted by E and/or interrupted by D, $C_6\text{-}C_{24}\text{aryl}$, $C_6\text{-}C_{24}\text{aryl}$ which is substituted by G, $C_2\text{-}C_{20}\text{heteroaryl}$, $C_2\text{-}C_{20}\text{heteroaryl}$ which is substituted by G, $C_2\text{-}C_{18}\text{alkenyl}$, $C_2\text{-}C_{18}\text{alkynyl}$, $C_1\text{-}C_{18}\text{alkoxy}$, $C_1\text{-}C_{18}\text{alkoxy}$ which is substituted by E and/or interrupted by D, or $C_7\text{-}C_{25}\text{aralkyl}$, or

R^{109} and R^{110} together form a group of formula $=\text{CR}^{100}\text{R}^{101}$, wherein

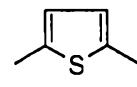
R^{100} and R^{101} are independently of each other H, $C_1\text{-}C_{18}\text{alkyl}$, $C_1\text{-}C_{18}\text{alkyl}$ which is substituted by E and/or interrupted by D, $C_6\text{-}C_{24}\text{aryl}$, $C_6\text{-}C_{24}\text{aryl}$ which is substituted by G, or $C_2\text{-}C_{20}\text{heteroaryl}$, or $C_2\text{-}C_{20}\text{heteroaryl}$ which is substituted by G, or

R^{109} and R^{110} together form a five or six membered ring, which optionally can be substituted by $C_1\text{-}C_{18}\text{alkyl}$, $C_1\text{-}C_{18}\text{alkyl}$ which is substituted by E and/or interrupted by D, $C_6\text{-}C_{24}\text{aryl}$, $C_6\text{-}C_{24}\text{aryl}$ which is substituted by G, $C_2\text{-}C_{20}\text{heteroaryl}$, $C_2\text{-}C_{20}\text{heteroaryl}$ which is substituted by G, $C_2\text{-}C_{18}\text{alkenyl}$, $C_2\text{-}C_{18}\text{alkynyl}$, $C_1\text{-}C_{18}\text{alkoxy}$, $C_1\text{-}C_{18}\text{alkoxy}$ which is substituted by E and/or interrupted by D, $C_7\text{-}C_{25}\text{aralkyl}$, or $-\text{C}(=\text{O})\text{-R}^{18}$,

R^{111} is H, a $C_1\text{-}C_{25}\text{alkyl}$ group, a $C_4\text{-}C_{18}\text{cycloalkyl}$ group, a $C_1\text{-}C_{25}\text{alkoxy}$ group, in which one or more carbon atoms which are not in neighbourhood to each other could be replaced by $-\text{O}-$, $-\text{S}-$, or $-\text{C}(=\text{O})\text{-O}-$, and/or wherein one or more hydrogen atoms can be replaced by F, a $C_6\text{-}C_{24}\text{aryl}$ group, or a $C_6\text{-}C_{24}\text{aryloxy}$ group, wherein one or more carbon atoms can be replaced by O, S, or N, and/or which can be substituted by one or more non-aromatic groups R^{111} ;

m can be the same or different at each occurrence and is 0, 1, 2, or 3, especially 0, 1, or 2, very especially 0 or 1;

X^1 is a hydrogen atom, or a cyano group,



with the proviso that, if Ar^1 and Ar^{11} are a group of formula

30 0.

5

10

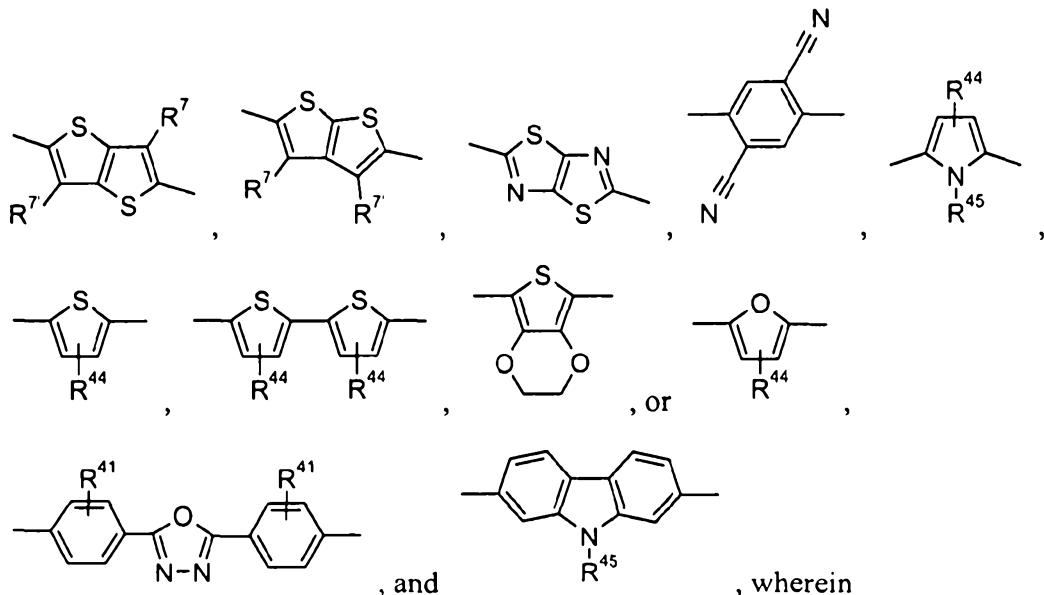
15

20

2. The polymer according to claim 1, wherein R¹ and R² are independently from each other hydrogen, C₁-C₂₅alkyl, which can optionally be interrupted by one or more oxygen atoms, C₅-C₁₂-cycloalkyl, especially cyclohexyl, which can be substituted one to three times with C₁-C₈alkyl and/or C₁-C₈alkoxy, or C₅-C₁₂cycloalkyl, especially cyclohexyl, which can be condensed one or two times by phenyl, which can be substituted one to three times with C₁-C₄alkyl, halogen, nitro or cyano, phenyl or 1- or 2-naphthyl which can be substituted one to three times with C₁-C₈alkyl and/or C₁-C₈alkoxy, or -CR⁵R⁶-(CH₂)_g-Ar¹⁰ wherein R⁵ and R⁶ stand for hydrogen, Ar¹⁰ stands for phenyl or 1- or 2-naphthyl, which can be substituted one to three times with C₁-C₈alkyl and/or C₁-C₈alkoxy, and g stands for 0 or 1.

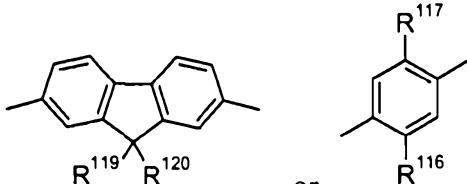
3. The polymer according to claim 1, wherein the polymer is a co-polymer comprising

repeating units of formula $\cdot -[A]_v -$ and $\cdot -[COM^1]_w -$; $\cdot -[A]_v -$ and
 $\cdot -[COM^2]_w -$; $\cdot -[A-COM^1]_v -$ or $\cdot -[A-COM^2]_v -$, wherein A is a repeating
 unit of formula I,
 v is 0.995 to 0.005, w is 0.005 to 0.995, and
 -COM¹- is selected from repeating units of formula:



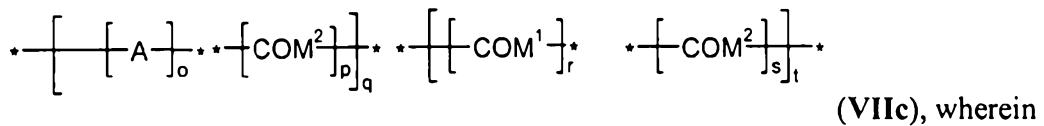
R⁷ and R^{7'} are as defined in claim 1,

R^{44} and R^{41} are hydrogen, C_1 - C_{18} alkyl, or C_1 - C_{18} alkoxy, and R^{45} is H, C_1 - C_{18} alkyl, or C_1 - C_{18} alkyl which is substituted by E and/or interrupted by D, especially C_1 - C_{18} alkyl which is interrupted by $-O-$, wherein D and E are as defined in claim 1, and



5 - COM^2 - is a group of formula , or , wherein
 R^{116} and R^{117} are independently of each other H, C_1 - C_{18} alkyl, which can optionally be interrupted by O, or C_1 - C_{18} alkoxy, which can optionally be interrupted by O,
 R^{119} and R^{120} are independently of each other H, C_1 - C_{18} alkyl, which can optionally be interrupted by O, or
10 R^{119} and R^{120} together form a group of formula $=CR^{100}R^{101}$, wherein
 R^{100} and R^{101} are independently of each other H, C_1 - C_{18} alkyl, or
 R^{119} and R^{120} together form a five or six membered ring, which optionally can be substituted by C_1 - C_{18} alkyl.

15 4. The polymer according to claim 3, wherein the polymer is a co-polymer of formula



A, COM^1 and COM^2 are as defined in claim 3,

o is 1,

p is 0, or 1,

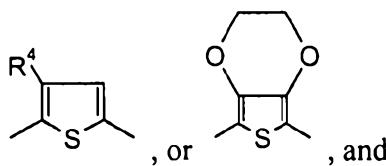
20 q is 0.005 to 1,

r is 0, or 1,

s is 0, or 1,

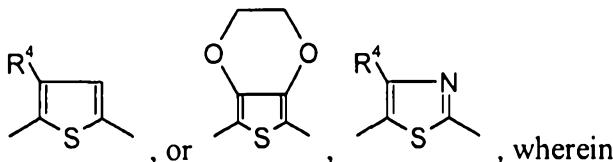
t is 0.995 to 0.

25 5. The polymer according to any of claims 1 to 4, wherein Ar^1 and $Ar^{1'}$ are the same and are a group of formula



, and

Ar², Ar^{2'}, Ar³, Ar^{3'}, Ar⁴ and Ar^{4'} are independently of each other a group of formula



, wherein

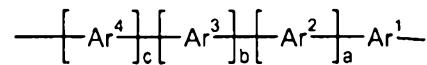
5 p stands for 0, 1, or 2, R³ may be the same or different within one group and is selected from C₁-C₂₅alkyl, which may optionally be substituted by E and/or interrupted by D, or C₁-C₁₈alkoxy, which may optionally be substituted by E and/or interrupted by D; R⁴ is C₆-C₂₅alkyl, which may optionally be substituted by E and/or interrupted by D, C₆-C₁₄aryl, such as phenyl, naphthyl, or biphenyl, which may optionally be substituted by G, C₁-C₂₅alkoxy, which may optionally be substituted by E and/or interrupted by D, or C₇-C₁₅aralkyl, wherein ar may optionally be substituted by G,

10 D is -CO-, -COO-, -S-, -SO-, -SO₂-, -O-, -NR²⁵-, wherein R²⁵ is C₁-C₁₂alkyl, such as methyl, ethyl, n-propyl, iso-propyl, n-butyl, isobutyl, or sec-butyl;

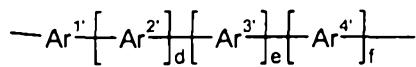
15 E is -OR²⁹; -SR²⁹; -NR²⁵R²⁵; -COR²⁸; -COOR²⁷; -CONR²⁵R²⁵; or -CN; wherein R²⁵, R²⁷, R²⁸ and R²⁹ are independently of each other C₁-C₁₂alkyl, such as methyl, ethyl, n-propyl, iso-propyl, n-butyl, isobutyl, sec-butyl, hexyl, octyl, or 2-ethyl-hexyl, or C₆-C₁₄ aryl, such as phenyl, naphthyl, or biphenyl,

G has the same preferences as E, or is C₁-C₁₈alkyl, especially C₁-C₁₂alkyl, such as methyl, ethyl, n-propyl, iso-propyl, n-butyl, isobutyl, sec-butyl, hexyl, octyl, or 2-ethyl-hexyl.

20



6. The polymer according to claim 5, wherein and

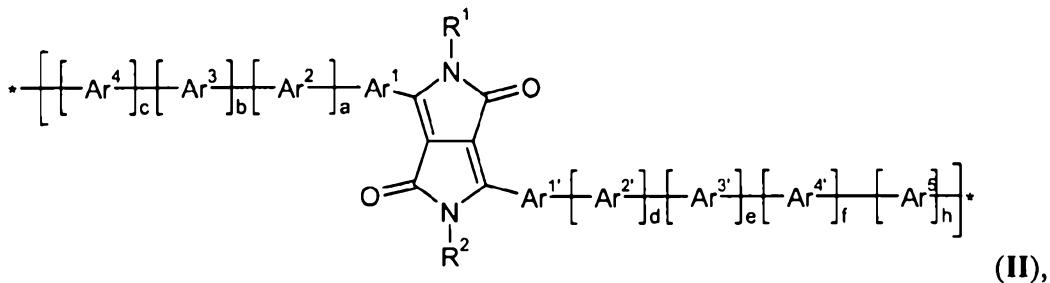


may be different, but are preferably the same and are

a group of formula

— indicates the bond to the diketopyrrolopyrrole skeleton, and R^4 is as defined in claim 5 and $R^{4'}$ has the meaning of R^4 .

7. The polymer according to any of claims 1 to 6, wherein the polymer comprise repeating units of the formula

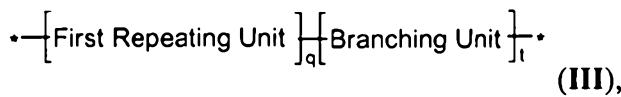


10 wherein a, b, c, d, e, f, R¹, R², Ar¹, Ar^{1'}, Ar², Ar^{2'}, Ar³, Ar^{3'}, Ar⁴ and Ar^{4'} are as defined in claim 1,
h is 1, and

Ar^5 is a group of formula $\text{R}^7\text{C}_6\text{H}_3\text{S}_2\text{C}_6\text{H}_3\text{R}^7$, $\text{R}^7\text{C}_6\text{H}_3\text{C}_6\text{H}_3\text{R}^7$, or $\text{R}^7\text{C}_6\text{H}_3\text{S}_2\text{N}_5$,

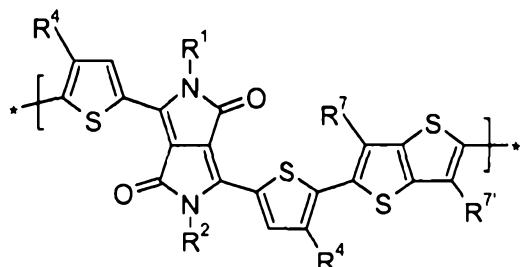
wherein R^7 and $R^{7'}$ are as defined in claim 1; or

15 the polymer has the structure of formula

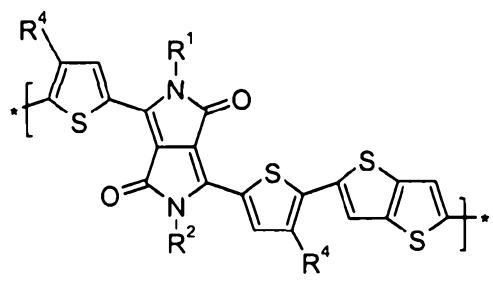


wherein the First Repeating Unit is a repeating unit of formula I according to claim 1, the Branching Unit is a unit having more than two linkage sites, and q and t are integers.

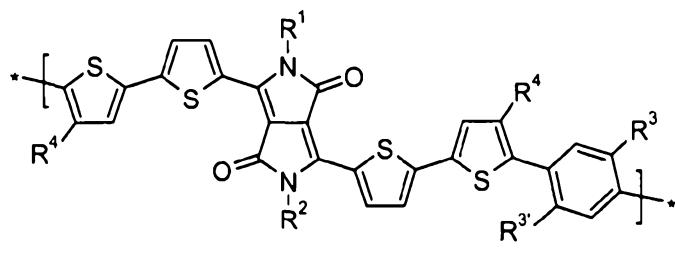
5 8. The polymer according to any of claims 1 to 7, comprising repeating units of the formula



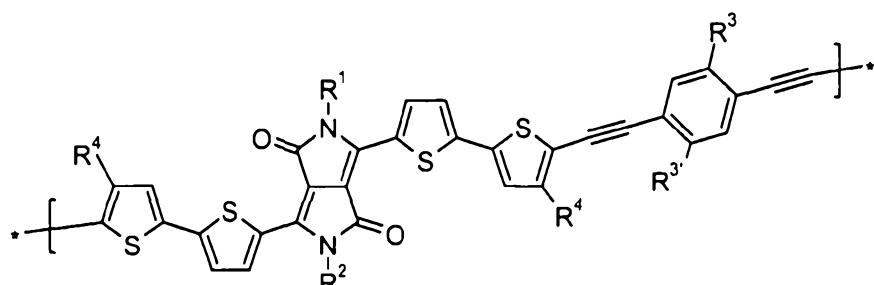
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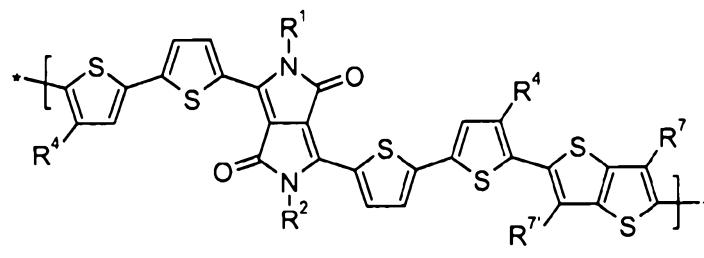
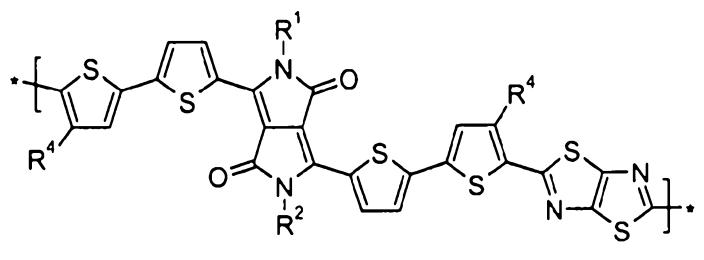


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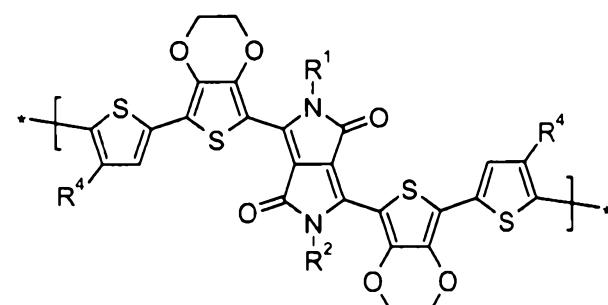
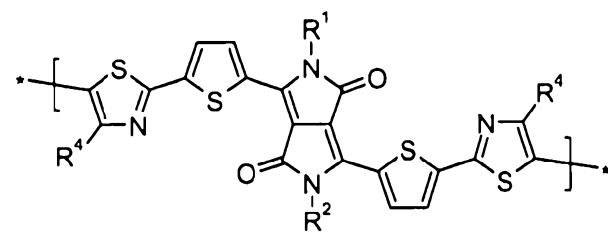
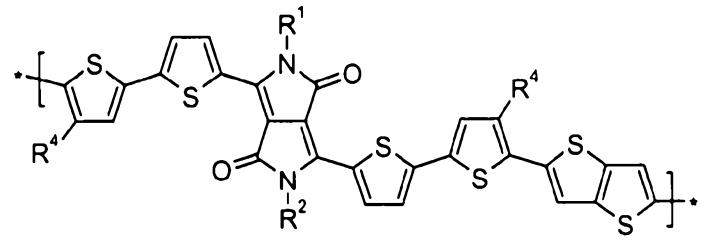


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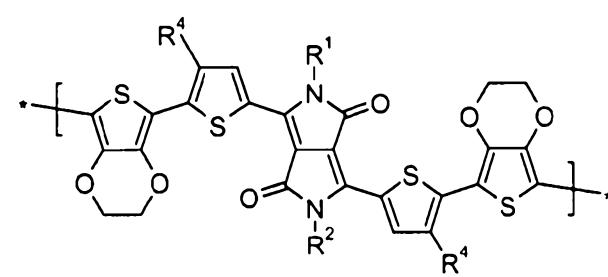
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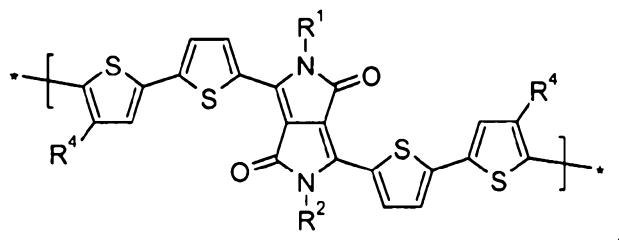


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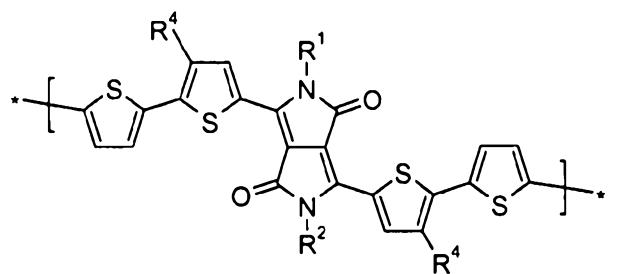


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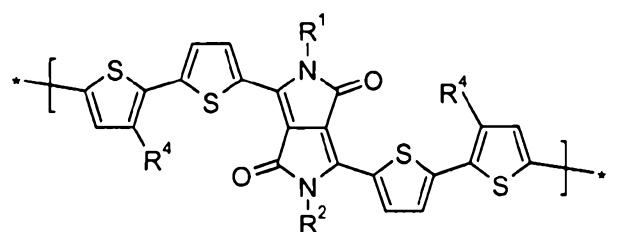




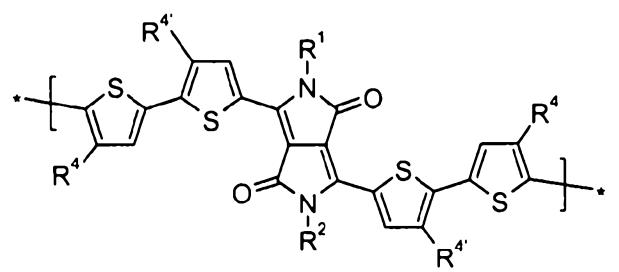
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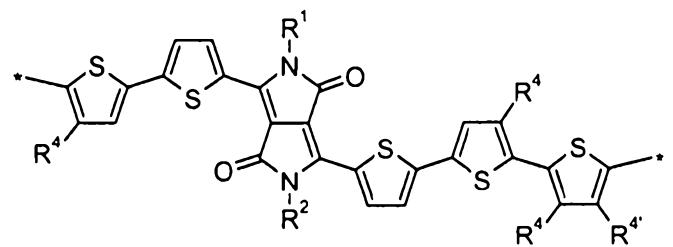
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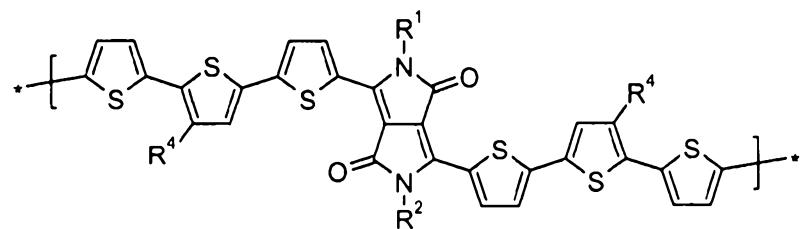
,



,



, or



, wherein

R¹ and R² are independently from each other C₁-C₂₅alkyl, and

R^3 and $R^{3'}$ are independently from each other C_6 - C_{25} alkyl, which may optionally be interrupted by one or more oxygen atoms,

R^4 and $R^{4'}$ are independently from each other C_6 - C_{25} alkyl, which may optionally be interrupted by one or more oxygen atoms, and

5 R^7 and $R^{7'}$ are independently from each other C_6 - C_{25} alkyl, which may optionally be interrupted by one or more oxygen atoms.

9. A semiconductor device, comprising a polymer of the formula I according to claim 1, especially a diode, a photodiode, an organic field effect transistor and/or a solar cell, or a 10 device containing a diode and/or a photodiode and/or an organic field effect transistor, and/or a solar cell.

10. The semiconductor device according to claim 9, which is a solar cell (photovoltaic device), comprising in this order:

15 (a) a cathode (electrode),
(b) optionally a transition layer, such as an alkali halogenide, especially lithium fluoride,
(c) a photoactive layer,
(d) optionally a smoothing layer,
(e) an anode (electrode),
20 (f) a substrate, wherein the photoactive layer comprises the polymer of the formula (I) according to claim 1.

11. The semiconductor device according to claim 9, which is a thin film transistor device comprising

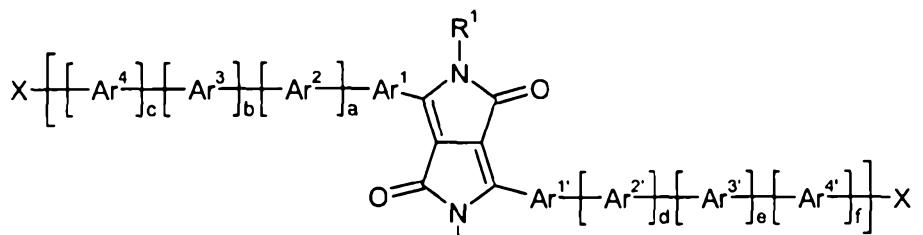
25 a plurality of electrically conducting gate electrodes disposed on a substrate; a gate insulator layer disposed on said electrically conducting gate electrodes; a plurality of sets of electrically conductive source and drain electrodes disposed on said insulator layer such that each of said sets is in alignment with each of said gate electrodes;

30 an organic semiconductor layer disposed in the channel between source and drain electrodes on said insulator layer substantially overlapping said gate electrodes; wherein

said organic semiconductor layer comprise a polymer of the formula I-according to claim 1, or a mixture containing a polymer of formula I according to claim 1.

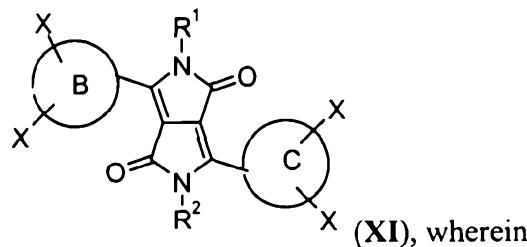
12. Process for the preparation of an organic semiconductor device, which
5 process comprises applying a solution and/or dispersion of a polymer of the formula I
according to claim 1 in an organic solvent to a suitable substrate and removing the
solvent.

13. A monomer of the formula



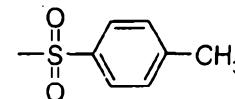
10

(X), or

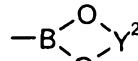


B and C are independently of each other an optionally condensed aromatic, or heteroaromatic ring,

15 a, b, c, d, e, f, R¹, R², Ar¹, Ar^{1'}, Ar², Ar^{2'}, Ar³, Ar^{3'}, Ar⁴ and Ar^{4'} are as defined in claim 1 and X is ZnX¹², -SnR²⁰⁷R²⁰⁸R²⁰⁹, wherein R²⁰⁷, R²⁰⁸ and R²⁰⁹ are identical or different and are H or C₁-C₆alkyl, wherein two radicals optionally form a common ring and these radicals are optionally branched or unbranched and X¹² is a halogen atom, very especially I, or Br;

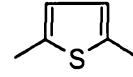


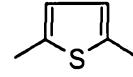
or where X is -OS(O)₂CF₃, -OS(O)₂-aryl, especially



20 -OS(O)₂CH₃, -B(OH)₂, -B(OY¹)₂, -BF₄Na, or -BF₄K, wherein Y¹ is independently in each occurrence a C₁-C₁₀alkyl group and Y² is independently in each occurrence a C₂-C₁₀alkylene group, such as -CY³Y⁴-CY⁵Y⁶-, or -CY⁷Y⁸-CY⁹Y¹⁰-CY¹¹Y¹²-, wherein Y³, Y⁴, Y⁵, Y⁶, Y⁷, Y⁸, Y⁹, Y¹⁰, Y¹¹ and Y¹² are

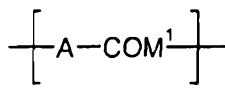
independently of each other hydrogen, or a C₁-C₁₀alkyl group, especially -C(CH₃)₂C(CH₃)₂-, or -C(CH₃)₂CH₂C(CH₃)₂-



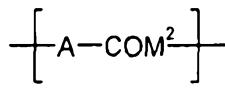
with the proviso that, if Ar¹ and Ar^{1'} are a group of formula  , a and d are not 0.

14. Use of the polymer of formula I according to any of claims 1 to 8 as charge-transport, semiconducting, el. conducting, photoconducting, light emitting material, surface-modifying material, electrode materials in batteries, alignment layers, or in OFETs, ICs, TFTs, displays, RFITD tags, electro- or photoluminescent devices, backlights of displays, photovoltaic or sensor devices, charge injection layers, Schottky diodes, memory devices (e.g. FeFET), planarising layers, antistatics, conductive substrates or patterns, photoconductors, or electrophotographic applications (recording).

15. 15. A process for preparing polymers of formula



(VIIId), or



(VIIe), which process comprises

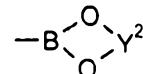
reacting a dihalogenide, such as a dibromide or dichloride, especially a dibromide corresponding to formula Br—A—Br with an equimolar amount of a diboronic acid or

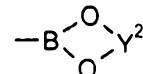


diboronate corresponding to formula , or under the

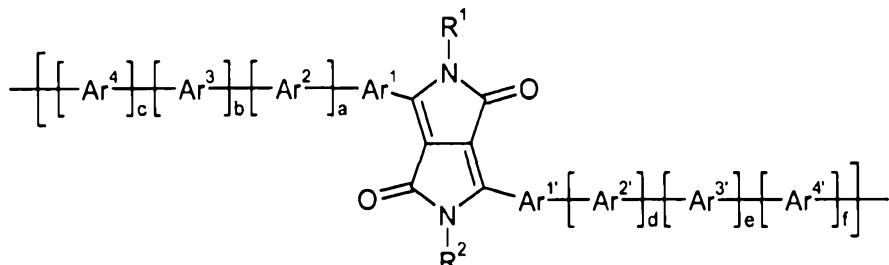
catalytic action of Pd and triphenylphosphine, wherein

A, COM¹ and COM² are as defined in claim 3,

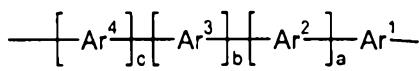


X¹¹ is independently in each occurrence -B(OH)₂, -B(OY¹)₂ or  , wherein Y¹ is independently in each occurrence a C₁-C₁₀alkyl group and Y² is independently in each occurrence a C₂-C₁₀alkylene group, such as -CY³Y⁴-CY⁵Y⁶-, or -CY⁷Y⁸-CY⁹Y¹⁰-CY¹¹Y¹²-, wherein Y³, Y⁴, Y⁵, Y⁶, Y⁷, Y⁸, Y⁹, Y¹⁰, Y¹¹ and Y¹² are independently of each other hydrogen, or a C₁-C₁₀alkyl group, especially -C(CH₃)₂C(CH₃)₂-, or -C(CH₃)₂CH₂C(CH₃)₂-.

16. A monomer of formula X-A-X, wherein A is a group of formula



and X is

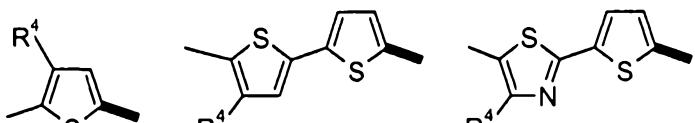


halogen, especially Br, wherein

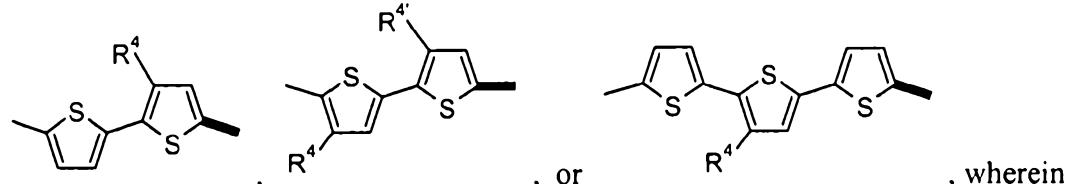
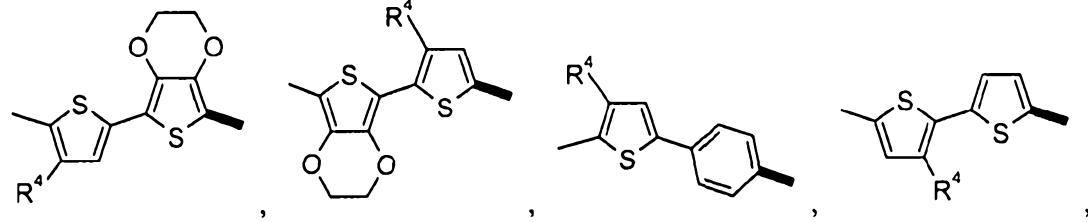
and



5 may be different, but are preferably the same and are



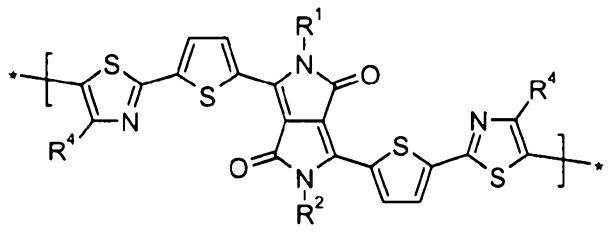
a group of formula

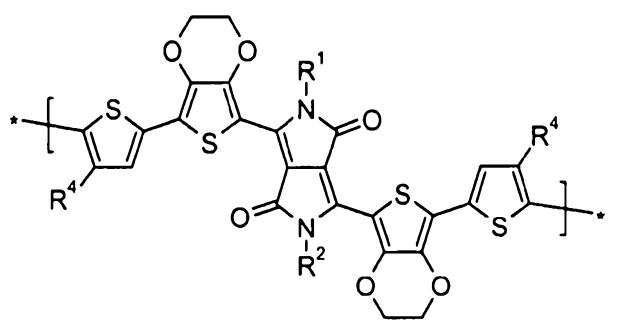


, wherein

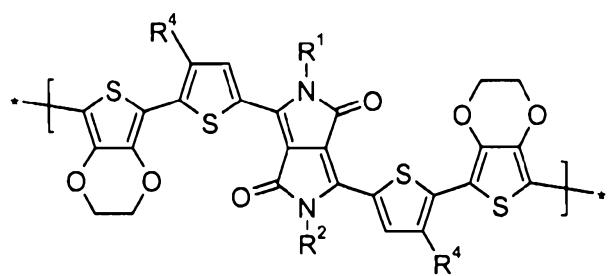
10 — indicates the bond to the diketopyrrolopyrrole skeleton, and R4 is as defined in claim 5 and R4' has the meaning of R4, and R1 and R2 are as defined in claim 1.

17. The monomer according to claim 16, wherein A is a group of formula

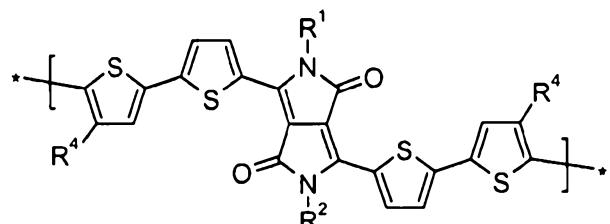




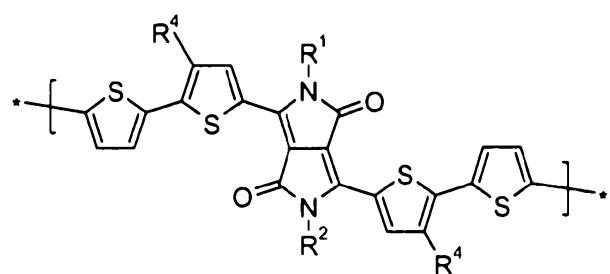
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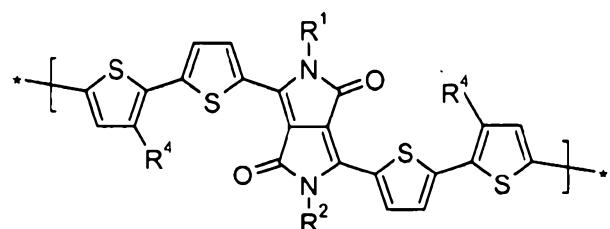
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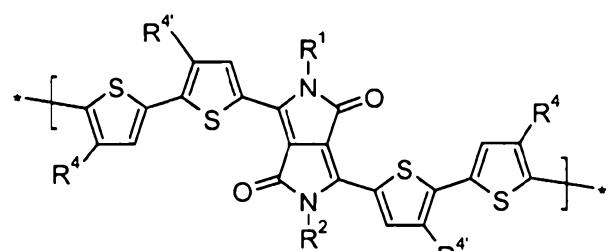


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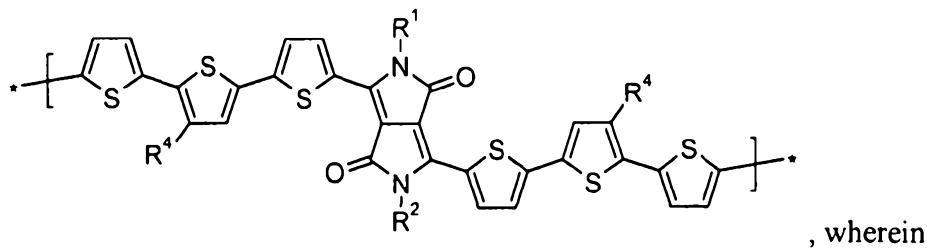
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, or

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, wherein

R¹ and R² are independently from each other C₁-C₂₅alkyl, and

R⁴ is C₆-C₂₅alkyl, which may optionally be interrupted by one or more oxygen atoms.

5 18. A method of making a device, comprising incorporating the polymer of claim 1 into the device.

19. The method of Claim 18, wherein the device is selected from the group consisting charge-transport material, semiconducting material, el. conducting material, photoconducting material, light emitting material, surface-modifying material, electrode materials in batteries, alignment layers, or in OFETs, ICs, TFTs, displays, RFITD tags, electro- or photoluminescent devices, backlights of displays, photovoltaic or sensor devices, charge injection layers, Schottky diodes, memory devices, planarising layers, antistatics, conductive substrates or patterns, photoconductors, and electrophotographic applications.

15 20. A polymer according to claim 1, monomer according to claim 13, or semiconductor device according to claim 9, substantially as hereinbefore described with reference to any one of the examples.

20 21. A process according to any one of claims 12 or 15 substantially as hereinbefore described with reference to any one of the examples.

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BASF SE

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